

TEST REPORT

FCC LTE Test for SM-S731U
Certification

APPLICANT
SAMSUNG Electronics Co., Ltd.

REPORT NO.
HCT-RF-2507-FC018

DATE OF ISSUE
July 14, 2025

Tested by
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TEST REPORT

REPORT NO.

HCT-RF-2507-FC018

DATE OF ISSUE

July 14, 2025

Additional Model

SM-S731U1

Applicant**SAMSUNG Electronics Co., Ltd.**

129, Samsung-ro, Yeongtong-gu, Suwon-si, Gyeonggi-do, 16677, Rep. of Korea

Product Name

Mobile Phone

Model Name

SM-S731U

Date of Test

May 13, 2025 ~ July 10, 2025

FCC ID

A3LSMS731U

Location of Test

☒ Permanent Testing Lab ☐ On Site Testing

(Address: 74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, Republic of Korea)

FCC Classification:

PCS Licensed Transmitter Held to Ear (PCE)

Test Standard Used

FCC Rule Part: § 24

Test Results

PASS

REVISION HISTORY

The revision history for this test report is shown in table.

Revision No.	Date of Issue	Description
0	July 14, 2025	Initial Release

Notice

Content

The measurements shown in this report were made in accordance with the procedures specified in CFR47 section § 2.947. I assume full responsibility for the accuracy and completeness of these measurements, and for the qualifications of all persons taking them.

HCT CO., LTD. Certifies that no party to this application has subject to a denial of Federal benefits that includes FCC benefits pursuant to section 5301 of the Anti-Drug Abuse Act of 1998, 21 U.S. C. 853(a)

The results shown in this test report only apply to the sample(s), as received, provided by the applicant, unless otherwise stated.

The test results have only been applied with the test methods required by the standard(s).

The laboratory is not accredited for the test results marked *.

Information provided by the applicant is marked **.

Test results provided by external providers are marked ***.

When confirmation of authenticity of this test report is required, please contact www.hct.co.kr

The test results in this test report are not associated with the ((KS Q) ISO/IEC 17025) accreditation by KOLAS (Korea Laboratory Accreditation Scheme) / A2LA (American Association for Laboratory Accreditation) that are under the ILAC (International Laboratory Accreditation Cooperation) Mutual Recognition Agreement (MRA).

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MEASUREMENT REPORT

1. GENERAL INFORMATION

Model(s):	SM-S731U
Additional Model(s)	SM-S731U1
Tx Frequency:	1850.7 MHz – 1914.3 MHz (LTE – Band25/2 (1.4 MHz)) 1851.5 MHz – 1913.5 MHz (LTE – Band25/2 (3 MHz)) 1852.5 MHz – 1912.5 MHz (LTE – Band25/2 (5 MHz)) 1855.0 MHz – 1910.0 MHz (LTE – Band25/2 (10 MHz)) 1857.5 MHz – 1907.5 MHz (LTE – Band25/2 (15 MHz)) 1860.0 MHz – 1905.0 MHz (LTE – Band25/2 (20 MHz))
Serial number:	Radiated : R3CY40DEG4K Conducted : R3CY40XC8LM
Antenna Information	Please refer to the Antenna Specification document.

1.1. MAXIMUM OUTPUT POWER

Main 1 ANT

Mode (MHz)	Tx Frequency (MHz)	Emission Designator	Modulation	EIRP	
				Max. Power (W)	Max. Power (dBm)
LTE – Band25/2 (1.4)	1850.7 - 1914.3	1M10G7D	QPSK	0.270	24.32
		1M09W7D	16QAM	0.231	23.64
		1M09W7D	64QAM	0.180	22.55
		1M10W7D	256QAM	0.089	19.47
LTE – Band25/2 (3)	1851.5 - 1913.5	2M72G7D	QPSK	0.277	24.42
		2M70W7D	16QAM	0.236	23.72
		2M70W7D	64QAM	0.187	22.72
		2M71W7D	256QAM	0.091	19.58
LTE – Band25/2 (5)	1852.5 - 1912.5	4M53G7D	QPSK	0.281	24.49
		4M50W7D	16QAM	0.250	23.98
		4M52W7D	64QAM	0.191	22.80
		4M55W7D	256QAM	0.089	19.51
LTE – Band25/2 (10)	1855.0 - 1910.0	9M00G7D	QPSK	0.279	24.46
		9M01W7D	16QAM	0.231	23.63
		9M03W7D	64QAM	0.179	22.54
		9M02W7D	256QAM	0.087	19.41
LTE – Band25/2 (15)	1857.5 - 1907.5	13M5G7D	QPSK	0.279	24.45
		13M5W7D	16QAM	0.236	23.72
		13M5W7D	64QAM	0.191	22.80
		13M5W7D	256QAM	0.096	19.82
LTE – Band25/2 (20)	1860.0 - 1905.0	18M0G7D	QPSK	0.288	24.60
		18M0W7D	16QAM	0.232	23.66
		17M9W7D	64QAM	0.193	22.86
		18M0W7D	256QAM	0.094	19.74

Sub 2 ANT

Mode (MHz)	Tx Frequency (MHz)	Emission Designator	Modulation	EIRP	
				Max. Power (W)	Max. Power (dBm)
LTE – Band25/2 (1.4)	1850.7 - 1914.3	1M10G7D	QPSK	0.156	21.93
		1M10W7D	16QAM	0.134	21.28
		1M10W7D	64QAM	0.106	20.25
		1M10W7D	256QAM	0.054	17.35
LTE – Band25/2 (3)	1851.5 - 1913.5	2M72G7D	QPSK	0.157	21.96
		2M70W7D	16QAM	0.136	21.35
		2M70W7D	64QAM	0.107	20.28
		2M72W7D	256QAM	0.055	17.37
LTE – Band25/2 (5)	1852.5 - 1912.5	4M53G7D	QPSK	0.160	22.03
		4M51W7D	16QAM	0.137	21.38
		4M53W7D	64QAM	0.106	20.27
		4M55W7D	256QAM	0.052	17.17
LTE – Band25/2 (10)	1855.0 - 1910.0	9M01G7D	QPSK	0.167	22.23
		9M01W7D	16QAM	0.135	21.29
		9M02W7D	64QAM	0.108	20.32
		9M03W7D	256QAM	0.057	17.55
LTE – Band25/2 (15)	1857.5 - 1907.5	13M5G7D	QPSK	0.159	22.01
		13M4W7D	16QAM	0.136	21.32
		13M5W7D	64QAM	0.110	20.42
		13M5W7D	256QAM	0.055	17.37
LTE – Band25/2 (20)	1860.0 - 1905.0	18M0G7D	QPSK	0.174	22.40
		17M9W7D	16QAM	0.145	21.60
		17M9W7D	64QAM	0.119	20.76
		17M9W7D	256QAM	0.061	17.87

2. INTRODUCTION

2.1. DESCRIPTION OF EUT

Please refer to the [2G3G] Test Report.

2.2. MEASURING INSTRUMENT CALIBRATION

The measuring equipment, which was utilized in performing the tests documented herein, has been calibrated in accordance with the manufacturer's recommendations for utilizing calibration equipment, which is traceable to recognized national standards.

2.3. TEST FACILITY

The Fully-anechoic chamber and conducted measurement facility used to collect the radiated data are located at the **74, Seoicheon-ro 578beon-gil, Majang-myeon, Icheon-si, Gyeonggi-do, Republic of Korea**

3. DESCRIPTION OF TESTS

3.1 TEST PROCEDURE

Test Description	Test Procedure Used
Occupied Bandwidth	- KDB 971168 D01 v03r01 – Section 4.3 - ANSI C63.26-2015 – Section 5.4.4
Band Edge	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Spurious and Harmonic Emissions at Antenna Terminal	- KDB 971168 D01 v03r01 – Section 6.0 - ANSI C63.26-2015 – Section 5.7
Conducted Output Power	- N/A (See SAR Report)
Peak- to- Average Ratio	- KDB 971168 D01 v03r01 – Section 5.7 - ANSI C63.26-2015 – Section 5.2.3.4
Frequency stability	- ANSI C63.26-2015 – Section 5.6
Radiated Power	- ANSI C63.26-2015 – Section 5.2.4.4 - KDB 971168 D01 v03r01 – Section 5.8
Radiated Spurious and Harmonic Emissions	- ANSI C63.26-2015 – Section 5.5.3 - KDB 971168 D01 v03r01 – Section 5.8

3.2 RADIATED POWER

Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

The equipment under test is placed on a non-conductive table 3-meters away from the receive antenna.

Test Settings

1. Radiated power measurements are performed using the signal analyzer's "channel power" measurement capability for signals with continuous operation.
2. RBW = 1 – 5 % of the expected OBW, not to exceed 1 MHz
3. VBW $\geq$ 3 x RBW
4. Span = 1.5 times the OBW
5. No. of sweep points > 2 x span / RBW
6. Detector = RMS
7. Trigger is set to "free run" for signals with continuous operation with the sweep times set to "auto".
8. The integration bandwidth was roughly set equal to the measured OBW of the signal for signals with continuous operation.
9. Trace mode = trace averaging (RMS) over 100 sweeps
10. The trace was allowed to stabilize

Test Note

1. The turntable is rotated through 360 degrees, and the receiving antenna scans in order to determine the level of the maximized emission.
2. A half wave dipole is then substituted in place of the EUT. For emissions above 1 GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator and the previously recorded signal was duplicated.

The power is calculated by the following formula;

$$P_d \text{ (dBm)} = P_g \text{ (dBm)} - \text{cable loss (dB)} + \text{antenna gain (dB)}$$

Where: P_d is the dipole equivalent power and P_g is the generator output power into the substitution antenna.

3. The maximum value is calculated by adding the forward power to the calibrated source plus its appropriate gain value.

These steps are repeated with the receiving antenna in both vertical and horizontal polarization. the difference between the gain of the horn and an isotropic antenna are taken into consideration

4. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
5. All measurements are performed as RMS average measurements while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies.

3.3 RADIATED SPURIOUS EMISSIONS

Test Overview

Radiated tests are performed in the Fully-anechoic chamber.

Radiated Spurious Emission Measurements at 3 meters by Substitution Method.

Test Settings

1. RBW = 100 kHz for emissions below 1 GHz and 1 MHz for emissions above 1 GHz
2. VBW $\geq 3 \times$ RBW
3. Span = 1.5 times the OBW
4. No. of sweep points $> 2 \times$ span / RBW
5. Detector = Peak
6. Trace mode = Max Hold
7. The trace was allowed to stabilize
8. Test channel : Low/ Middle/ High
9. Frequency range : We are performed all frequency to 10th harmonics from 9 kHz.

Test Note

1. Measurements value show only up to 3 maximum emissions noted, or would be lesser if no specific emissions from the EUT are recorded (ie: margin > 20 dB from the applicable limit) and considered that's already beyond the background noise floor.
2. The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning. The worst case emissions are reported with the EUT positioning, modulations, RB sizes and offsets, and channel bandwidth configurations shown in the test data
3. For spurious emissions above 1 GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator and the previously recorded signal was duplicated. The spurious emissions is calculated by the following formula;

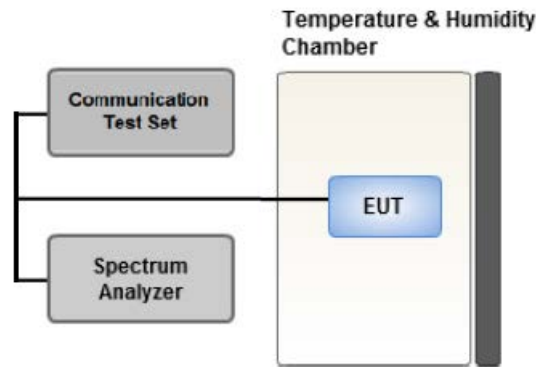
$$\text{Result}_{(\text{dBm})} = P_g_{(\text{dBm})} - \text{cable loss}_{(\text{dB})} + \text{antenna gain}_{(\text{dBi})}$$

Where: P_g is the generator output power into the substitution antenna.

If the fundamental frequency is below 1 GHz, RF output power has been converted to EIRP.

$$\text{EIRP}_{(\text{dBm})} = \text{ERP}_{(\text{dBm})} + 2.15$$

3.4 PEAK- TO- AVERAGE RATIO



Test setup

① CCDF Procedure for PAPR

Test Settings

1. Set resolution/measurement bandwidth $\geq$ signal's occupied bandwidth;
2. Set the number of counts to a value that stabilizes the measured CCDF curve;
3. Set the measurement interval as follows:
 - .- for continuous transmissions, set to 1 ms,
 - .- or burst transmissions, employ an external trigger that is synchronized with the EUT burst timing sequence, or use the internal burst trigger with a trigger level that allows the burst to stabilize and set the measurement interval to a time that is less than or equal to the burst duration.
4. Record the maximum PAPR level associated with a probability of 0.1 %.

② Alternate Procedure for PAPR

Use one of the procedures presented in 5.2(ANSI C63.26-2015) to measure the total peak power and record as P_{Pk} .

Use one of the applicable procedures presented 5.2(ANSI C63.26-2015) to measure the total average power and record as P_{Avg} . Determine the P.A.R. from:

$$P.A.R. (dB) = P_{Pk} (dBm) - P_{Avg} (dBm) \quad (P_{Avg} = \text{Average Power} + \text{Duty cycle Factor})$$

Test Settings(Peak Power)

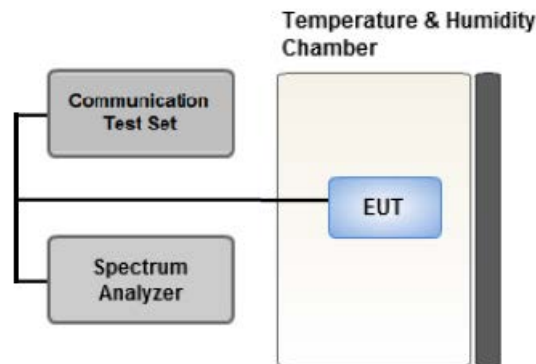
The measurement instrument must have a RBW that is greater than or equal to the OBW of the signal to be measured and a VBW $\geq 3 \times$ RBW.

1. Set the RBW $\geq$ OBW.
2. Set VBW $\geq 3 \times$ RBW.
3. Set span $\geq 2 \times$ OBW.
4. Sweep time $\geq 10 \times$ (number of points in sweep) $\times$ (transmission symbol period).
5. Detector = peak.
6. Trace mode = max hold.
7. Allow trace to fully stabilize.
8. Use the peak marker function to determine the peak amplitude level.

Test Settings(Average Power)

1. Set span to $2 \times$ to $3 \times$ the OBW.
2. Set RBW $\geq$ OBW.
3. Set VBW $\geq 3 \times$ RBW.
4. Set number of measurement points in sweep $\geq 2 \times$ span / RBW.
5. Sweep time:
Set $\geq [10 \times (\text{number of points in sweep}) \times (\text{transmission period})]$ for single sweep (automation-compatible) measurement. The transmission period is the (on + off) time.
6. Detector = power averaging (rms).
7. Set sweep trigger to "free run."
8. Trace average at least 100 traces in power averaging (rms) mode if sweep is set to auto-couple. (To accurately determine the average power over the on and off period of the transmitter, it can be necessary to increase the number of traces to be averaged above 100 or, if using a manually configured sweep time, increase the sweep time.)
9. Use the peak marker function to determine the maximum amplitude level.
10. Add $[10 \log (1/\text{duty cycle})]$ to the measured maximum power level to compute the average power during continuous transmission. For example, add $[10 \log (1/0.25)] = 6 \text{ dB}$ if the duty cycle is a constant 25 %.

3.5 OCCUPIED BANDWIDTH.



Test setup

The width of a frequency band such that, below the lower and above the upper frequency limits, the mean powers emitted are each equal to a specified percentage 0.5 % of the total mean power of a given emission.

The EUT makes a call to the communication simulator.

The conducted occupied bandwidth used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

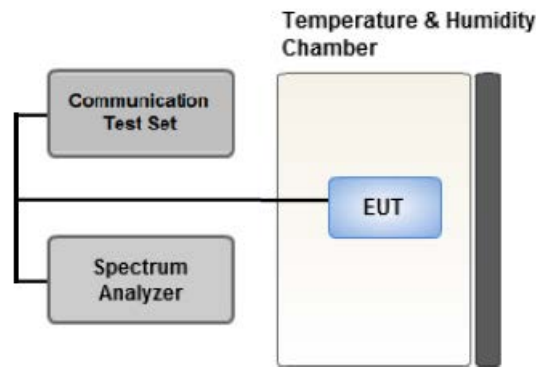
The communication simulator station system controlled a EUT to export maximum output power under transmission mode and specific channel frequency.

Use OBW measurement function of Spectrum analyzer to measure 99 % occupied bandwidth

Test Settings

1. The signal analyzer's automatic bandwidth measurement capability was used to perform the 99 % occupied bandwidth and the 26 dB bandwidth. The bandwidth measurement was not influenced by any intermediate power nulls in the fundamental emission.
2. RBW = 1 – 5 % of the expected OBW
3. VBW $\geq$ 3 x RBW
4. Detector = Peak
5. Trace mode = max hold
6. Sweep = auto couple
7. The trace was allowed to stabilize
8. If necessary, steps 2 – 7 were repeated after changing the RBW such that it would be within 1 – 5 % of the 99 % occupied bandwidth observed in Step 7

3.6 SPURIOUS AND HARMONIC EMISSIONS AT ANTENNA TERMINAL



Test setup

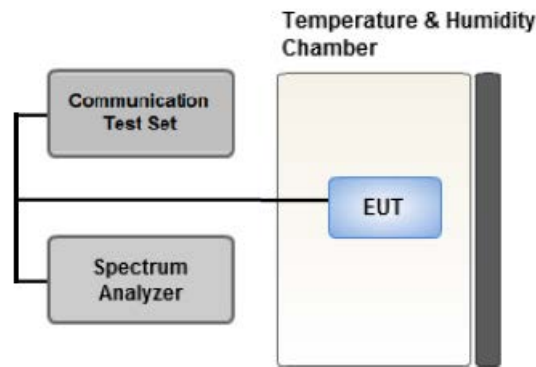
Test Overview

The level of the carrier and the various conducted spurious and harmonic frequencies is measured by means of a calibrated spectrum analyzer. The spectrum is scanned from the lowest frequency generated in the equipment up to a frequency including its 10th harmonic. All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

Test Settings

1. RBW = 1 MHz
2. VBW $\geq$ 3 MHz
3. Detector = Peak
4. Trace Mode = max hold
5. Sweep time = auto
6. Number of points in sweep $\geq$ 2 x Span / RBW

3.7 BAND EDGE



Test setup

Test Overview

All out of band emissions are measured with a spectrum analyzer connected to the antenna terminal of the EUT while the EUT is operating at its maximum duty cycle, at maximum power, and at the appropriate frequencies. All data rates were investigated to determine the worst case configuration. All modes of operation were investigated and the worst case configuration results are reported in this section.

Test Settings

1. Start and stop frequency were set such that the band edge would be placed in the center of the plot
2. Span was set large enough so as to capture all out of band emissions near the band edge
3. RBW > 1 % of the emission bandwidth
4. VBW > 3 x RBW
5. Detector = RMS
6. Number of sweep points $\geq 2 \times \text{Span/RBW}$
7. Trace mode = trace average
8. Sweep Time > (Number of Points) $\times$ (Symbol Period)
9. The trace was allowed to stabilize

Test Notes

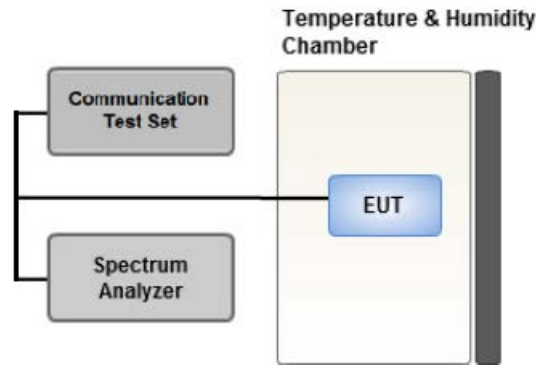
According to FCC 22.917, 24.238, 27.53 specified that power of any emission outside of The authorized operating frequency ranges must be attenuated below the transmitting power (P) by a factor of at least $43 + 10 \log(P)$ dB. In the 1 MHz bands immediately outside and adjacent to the frequency block a resolution bandwidth of at least one percent of the emission bandwidth of the fundamental emission of the transmitter may be employed.

All measurements were done at 2 channels(low and high operational frequency range.)

The band edge measurement used the power splitter via EUT RF power connector between simulation base station and spectrum analyzer.

Where $\text{Margin} < 1 \text{ dB}$ the emission level is either corrected by $10 \log(1 \text{ MHz} / \text{RB})$ or the emission is integrated over a 1 MHz bandwidth to determine the final result. When using the integration method the integration window is either centered on the emission or, for emissions at the band edge, centered by an offset of 500 kHz from the block edge so that the integration window is the 1 MHz adjacent to the block edge.

3.8 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE



Test setup

Test Overview

Frequency stability testing is performed in accordance with the guidelines of ANSI C63.26-2015.

The frequency stability of the transmitter is measured by:

1. Temperature:

The temperature is varied from -30 °C to +50 °C in 10 °C increments using an environmental chamber.

2. Primary Supply Voltage:

- .- Unless otherwise specified, vary primary supply voltage from 85 % to 115 % of the nominal value for other than hand carried battery equipment.
- .- For hand carried, battery powered equipment, reduce the primary ac or dc supply voltage to the battery operating end point, which shall be specified by the manufacturer.

Test Settings

1. The carrier frequency of the transmitter is measured at room temperature (20 °C to provide a reference).
2. The equipment is turned on in a “standby” condition for fifteen minutes before applying power to the transmitter.
Measurement of the carrier frequency of the transmitter is made within one minute after applying power to the transmitter.
3. Frequency measurements are made at 10 °C intervals ranging from -30 °C to +50 °C. A period of at least one half-hour is provided to allow stabilization of the equipment at each temperature level.

3.9 WORST CASE(RADIATED TEST)

- The EUT was tested in three orthogonal planes(X, Y, Z) and in all possible test configurations and positioning.
- In the case of radiated spurious emissions, all bandwidth of operation were investigated and the worst case bandwidth results are reported. (Worst case : 20 MHz)
- LTE BAND 25 (1850 – 1915 MHz) overlaps the entire frequency range of LTE BAND 2 (1850 - 1910 MHz) and they have the same Tune-up power.
Therefore, test data provided in this report covers BAND 2 as well as BAND 25.
- All modes of operation were investigated and the worst case configuration results are reported.
Mode : Stand alone, Stand alone + External accessories (Earphone, AC adapter, etc)
Worst case : Stand alone
- All simultaneous transmission scenarios of operation were investigated, and the test results showed no additional significant emissions relative to the least restrictive limit were observed.
Therefore, only the worst case(stand-alone) results were reported.
- The worst case is reported with the EUT positioning, modulations, and paging service configurations shown in the test data.
- Please refer to the table below.
- SM-S731U & additional models were tested and the worst case results are reported.
(Worst case : SM-S731U)

[Main 1 ANT Worst case]

Test Description	Modulation	RB size	RB offset	Axis
Effective Isotropic Radiated Power	QPSK, 16QAM, 64QAM, 256QAM	See Section 8.1		Z
Radiated Spurious and Harmonic Emissions	QPSK	See Section 8.2		Z

[Sub 2 ANT Worst case]

Test Description	Modulation	RB size	RB offset	Axis
Effective Isotropic Radiated Power	QPSK, 16QAM, 64QAM, 256QAM	See Section 9.1		Z
Radiated Spurious and Harmonic Emissions	QPSK	See Section 9.2		Y

3.10 WORST CASE(CONDUCTED TEST)

- All modes of operation were investigated and the worst case configuration results are reported.
- LTE BAND 25 (1850 – 1915 MHz) overlaps the entire frequency range of LTE BAND 2 (1850 - 1910 MHz) and they have the same Tune-up power.
Therefore, test data provided in this report covers BAND 2 as well as BAND 25.
- SM-S731U & additional models were tested and the worst case results are reported.
(Worst case : SM-S731U)

[Worst case]

Test Description	Modulation	Bandwidth (MHz)	Frequency	RB size	RB offset
Occupied Bandwidth	QPSK, 16QAM, 64QAM, 256QAM	1.4, 3, 5, 10, 15, 20	Mid	Full RB	0
Peak-To-Average Ratio	QPSK, 16QAM, 64QAM, 256QAM	1.4, 3, 5, 10, 15, 20	Mid	Full RB	0
Band Edge	QPSK	1.4	Low	1	0
			High	1	5
		3	Low	1	0
			High	1	14
		5	Low	1	0
			High	1	24
		10	Low	1	0
			High	1	49
		15	Low	1	0
			High	1	74
		20	Low	1	0
			High	1	99
		1.4, 3, 5, 10, 15, 20	Low, High	Full RB	0
Spurious and Harmonic Emissions at Antenna Terminal	QPSK	1.4, 3, 5, 10, 15, 20	Low, Mid, High	1	0

4. LIST OF TEST EQUIPMENT

Equipment	Model	Manufacture	Serial No.	Due to Calibration	Calibration Interval
RF Switching System	Switch box(1.2 G HPF+LNA)	HCT CO., LTD.	F1L1	11/11/2025	Annual
RF Switching System	Switch box(3.3 G HPF+LNA)	HCT CO., LTD.	F1L2	11/11/2025	Annual
RF Switching System	Switch box(LNA)	HCT CO., LTD.	F1L4	11/11/2025	Annual
RF Switching System	Switch box(6 G HPF+LNA)	HCT CO., LTD.	F1L7	11/11/2025	Annual
Power Amplifier	CBL18265035	CERNEX	22966	11/07/2025	Annual
Power Amplifier	CBL26405040	CERNEX	25956	02/19/2026	Annual
Power Splitter(DC ~ 26.5 GHz)	11667B	Hewlett Packard	5001	04/10/2026	Annual
DC Power Supply	E3632A	Agilent	MY40010147	08/06/2025	Annual
Dipole Antenna	UHAP	Schwarzbeck	01274	03/10/2026	Biennial
Dipole Antenna	UHAP	Schwarzbeck	01288	08/07/2026	Biennial
Chamber	SU-642	ESPEC	93008124	02/11/2026	Annual
Horn Antenna(1 ~ 18 GHz)	BBHA 9120D	Schwarzbeck	147	08/17/2025	Biennial
Horn Antenna(1 ~ 18 GHz)	BBHA 9120D	Schwarzbeck	9120D-1298	09/11/2025	Biennial
Horn Antenna(15 ~ 40 GHz)	BBHA 9170	Schwarzbeck	BBHA9170342	09/20/2026	Biennial
Horn Antenna(15 ~ 40 GHz)	BBHA 9170	Schwarzbeck	BBHA9170124	03/23/2027	Biennial
Signal Analyzer(10 Hz ~ 26.5 GHz)	N9020A	Agilent	MY52090906	04/14/2026	Annual
ATTENUATOR(20 dB)	8493C	Hewlett Packard	17280	04/10/2026	Annual
Spectrum Analyzer(10 Hz ~ 40 GHz)	FSV40	REOHDE & SCHWARZ	100931	08/06/2025	Annual
Base Station	8960 (E5515C)	Agilent	MY48360800	08/05/2025	Annual
Loop Antenna(9 kHz ~ 30 MHz)	FMZB1513	Schwarzbeck	1513-333	03/07/2026	Biennial
Trilog Broadband Antenna	VULB9168	Schwarzbeck	895	08/28/2026	Biennial
Trilog Broadband Antenna	VULB9168	Schwarzbeck	1135	08/19/2026	Biennial
Wideband Radio Communication Tester	MT8821C	Anritsu Corp.	6262094331	11/13/2025	Annual
Radio Communication Test Station	MT8000A	Anritsu Corp.	6272613402	08/28/2025	Annual
SIGNAL GENERATOR (100 kHz ~ 40 GHz)	SMB100A	REOHDE & SCHWARZ	177633	07/26/2025	Annual
Signal Analyzer(5 Hz ~ 40.0 GHz)	N9030B	KEYSIGHT	MY55480167	05/14/2026	Annual
Signal Analyzer(2 Hz ~ 50.0 GHz)	N9040B	KEYSIGHT	US55230216	12/09/2025	Annual
Signal & Spectrum Analyzer (2 Hz~67 GHz)	FSW67	REOHDE & SCHWARZ	101736	05/27/2026	Annual
Automation Software	FCC 2G/3G/4G Conducted	HCT CO., LTD	-	-	-
Automation Software	FCC NR Conducted	HCT CO., LTD	-	-	-
Automation Software	FCC LTE Radiated	HCT CO., LTD	-	-	-
Automation Software	FCC NR Radiated	HCT CO., LTD	-	-	-

Note:

- Equipment listed above that has a calibration due date during the testing period, the testing is completed before equipment expiration date.
- Especially, all antenna for measurement is calibrated in accordance with the requirements of C63.5 (Version : 2017).

5. MEASUREMENT UNCERTAINTY

The measurement uncertainties shown below were calculated in accordance with the requirements of ANSI C63.4:2014.

All measurement uncertainty values are shown with a coverage factor of $k=2$ to indicate a 95 % level of confidence. The measurement data shown herein meets or exceeds the U_{CISPR} measurement uncertainty values specified in CISPR 16-4-2 and, thus, can be compared directly to specified limits to determine compliance.

Parameter	Expanded Uncertainty ($\pm$ kHz)
Occupied Bandwidth	95 (Confidence level about 95 %, $k=2$)
Frequency stability	28 (Confidence level about 95 %, $k=2$)

Parameter	Expanded Uncertainty ($\pm$ dB)
Block Edge	0.70 (Confidence level about 95 %, $k=2$)
Conducted Spurious Emissions	1.18 (Confidence level about 95 %, $k=2$)
Peak- to- Average Ratio	0.68 (Confidence level about 95 %, $k=2$)
Radiated Power	4.74 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (9 kHz ~ 30 MHz)	4.36 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (30 MHz ~ 1 GHz)	5.68 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (1 GHz ~ 18 GHz)	5.75 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (18 GHz ~ 40 GHz)	5.82 (Confidence level about 95 %, $k=2$)
Radiated Disturbance (Above 40 GHz)	5.58 (Confidence level about 95 %, $k=2$)

6. SUMMARY OF TEST RESULTS

-. The decision rule applies 'simple acceptance'

6.1 Test Condition: Conducted Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Occupied Bandwidth	§ 2.1049	N/A	PASS
Band Edge / Spurious and Harmonic Emissions at Antenna Terminal.	§ 2.1051, § 24.238(a)	< 43 + 10log10 (P[Watts]) at Band Edge and for all out-of-band emissions	PASS
Conducted Output Power	§ 2.1046	N/A	Note1
Peak- to- Average Ratio	§ 24.232(d)	< 13 dB	PASS
Frequency stability / variation of ambient temperature	§ 24.235	Emission must remain in band	PASS

Note:

1. Refer to the SAR report.

6.2 Test Condition: Radiated Test

Test Description	FCC Part Section(s)	Test Limit	Test Result
Equivalent Isotropic Radiated Power	§ 24.232(c)	< 2 Watts max. EIRP	PASS
Radiated Spurious and Harmonic Emissions	§ 2.1053, § 24.238(a)	< 43 + 10log10 (P[Watts]) for all out-of band emissions	PASS

7. SAMPLE CALCULATION

7.1 ERP Sample Calculation

Ch./ Freq.		Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBd)	C.L	Pol.	ERP	
channel	Freq.(MHz)						W	dBm
128	824.20	-21.37	38.40	-10.61	0.95	H	0.483	26.84

$$\text{ERP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test, the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of effective radiated power.

7.2 EIRP Sample Calculation

Ch./ Freq.		Measured Level (dBm)	Substitute Level (dBm)	Ant. Gain (dBi)	C.L	Pol.	EIRP	
channel	Freq.(MHz)						W	dBm
20175	1,732.50	-15.75	18.45	9.90	1.76	H	0.456	26.59

$$\text{EIRP} = \text{Substitute LEVEL(dBm)} + \text{Ant. Gain} - \text{CL(Cable Loss)}$$

- 1) The EUT mounted on a non-conductive turntable is 2.5 meter above test site ground level.
- 2) During the test, the turn table is rotated until the maximum signal is found.
- 3) Record the field strength meter's level.
- 4) Replace the EUT with dipole/Horn antenna that is connected to a calibrated signal generator.
- 5) Increase the signal generator output till the field strength meter's level is equal to the item (3).
- 6) The signal generator output level with Ant. Gain and cable loss are the rating of equivalent isotropic radiated power.

7.3. Emission Designator

GSM Emission Designator

Emission Designator = 249KGXW
GSM BW = 249 kHz
G = Phase Modulation
X = Cases not otherwise covered
W = Combination (Audio/Data)

EDGE Emission Designator

Emission Designator = 249KG7W
GSM BW = 249 kHz
G = Phase Modulation
7 = Quantized/Digital Info
W = Combination (Audio/Data)

WCDMA Emission Designator

Emission Designator = 4M17F9W
WCDMA BW = 4.17 MHz
F = Frequency Modulation
9 = Composite Digital Info
W = Combination (Audio/Data)

QPSK Modulation

Emission Designator = 4M48G7D
LTE BW = 4.48 MHz
G = Phase Modulation
7 = Quantized/Digital Info
D = Data transmission; telemetry; telecommand

QAM Modulation

Emission Designator = 4M48W7D
LTE BW = 4.48 MHz
W = Amplitude/Angle Modulated
7 = Quantized/Digital Info
D = Data transmission; telemetry; telecommand

8. TEST DATA(Main 1 ANT)

8.1 EQUIVALENT ISOTROPIC RADIATED POWER

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1850.7	LTE B25/B2 1.4 MHz	QPSK	-18.59	15.93	10.40	2.07	V	< 2.00	0.267	24.26	1	0
		16-QAM	-19.21	15.31	10.40	2.07	V		0.231	23.64		
		64-QAM	-20.30	14.22	10.40	2.07	V		0.180	22.55		
		256-QAM	-23.46	11.06	10.40	2.07	V		0.087	19.39		
1882.5		QPSK	-18.85	16.13	10.40	2.21	V		0.270	24.32	1	0
		16-QAM	-19.56	15.42	10.40	2.21	V		0.229	23.61		
		64-QAM	-20.66	14.32	10.40	2.21	V		0.178	22.51		
		256-QAM	-23.70	11.28	10.40	2.21	V		0.089	19.47		
1914.3		QPSK	-19.81	15.20	10.40	2.17	V		0.220	23.43	1	0
		16-QAM	-20.42	14.59	10.40	2.17	V		0.191	22.82		
		64-QAM	-21.33	13.68	10.40	2.17	V		0.155	21.91		
		256-QAM	-24.47	10.54	10.40	2.17	V		0.075	18.77		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1851.5	LTE B25/B2 3 MHz	QPSK	-18.67	15.85	10.40	2.07	V	< 2.00	0.262	24.18	1	0
		16-QAM	-19.22	15.30	10.40	2.07	V		0.231	23.63		
		64-QAM	-20.22	14.30	10.40	2.07	V		0.183	22.63		
		256-QAM	-23.27	11.25	10.40	2.07	V		0.091	19.58		
1882.5		QPSK	-18.75	16.23	10.40	2.21	V		0.277	24.42	1	0
		16-QAM	-19.45	15.53	10.40	2.21	V		0.236	23.72		
		64-QAM	-20.45	14.53	10.40	2.21	V		0.187	22.72		
		256-QAM	-23.63	11.35	10.40	2.21	V		0.090	19.54		
1913.5		QPSK	-19.38	15.63	10.40	2.17	V		0.243	23.86	1	0
		16-QAM	-20.01	15.00	10.40	2.17	V		0.211	23.23		
		64-QAM	-21.11	13.90	10.40	2.17	V		0.163	22.13		
		256-QAM	-24.24	10.77	10.40	2.17	V		0.079	19.00		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1852.5	LTE B25/B2 5 MHz	QPSK	-18.52	16.05	10.40	2.08	V	< 2.00	0.274	24.37	1	0
		16-QAM	-19.19	15.38	10.40	2.08	V		0.235	23.70		
		64-QAM	-20.30	14.27	10.40	2.08	V		0.181	22.59		
		256-QAM	-23.45	11.12	10.40	2.08	V		0.088	19.44		
1882.5		QPSK	-18.68	16.30	10.40	2.21	V		0.281	24.49	1	0
		16-QAM	-19.19	15.79	10.40	2.21	V		0.250	23.98		
		64-QAM	-20.37	14.61	10.40	2.21	V		0.191	22.80		
		256-QAM	-23.66	11.32	10.40	2.21	V		0.089	19.51		
1912.5		QPSK	-19.50	15.51	10.40	2.17	V		0.236	23.74	1	0
		16-QAM	-20.18	14.83	10.40	2.17	V		0.202	23.06		
		64-QAM	-21.16	13.85	10.40	2.17	V		0.161	22.08		
		256-QAM	-24.17	10.84	10.40	2.17	V		0.081	19.07		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1855.0	LTE B25/B2 10 MHz	QPSK	-18.43	16.14	10.40	2.08	V	< 2.00	0.279	24.46	1	0
		16-QAM	-19.26	15.31	10.40	2.08	V		0.231	23.63		
		64-QAM	-20.41	14.16	10.40	2.08	V		0.177	22.48		
		256-QAM	-23.48	11.09	10.40	2.08	V		0.087	19.41		
1882.5		QPSK	-18.79	16.19	10.40	2.21	V		0.274	24.38	1	0
		16-QAM	-19.84	15.14	10.40	2.21	V		0.215	23.33		
		64-QAM	-20.63	14.35	10.40	2.21	V		0.179	22.54		
		256-QAM	-23.80	11.18	10.40	2.21	V		0.086	19.37		
1910.0		QPSK	-19.47	15.47	10.40	2.17	V		0.234	23.70	1	0
		16-QAM	-20.06	14.88	10.40	2.17	V		0.205	23.11		
		64-QAM	-21.12	13.82	10.40	2.17	V		0.160	22.05		
		256-QAM	-24.18	10.76	10.40	2.17	V		0.079	18.99		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1857.5	LTE B25/B2 15 MHz	QPSK	-18.53	16.11	10.40	2.10	V	< 2.00	0.276	24.41	1	74
		16-QAM	-19.31	15.33	10.40	2.10	V		0.231	23.63		
		64-QAM	-20.33	14.31	10.40	2.10	V		0.182	22.61		
		256-QAM	-23.33	11.31	10.40	2.10	V		0.091	19.61		
1882.5		QPSK	-18.72	16.26	10.40	2.21	V		0.279	24.45	1	0
		16-QAM	-19.45	15.53	10.40	2.21	V		0.236	23.72		
		64-QAM	-20.37	14.61	10.40	2.21	V		0.191	22.80		
		256-QAM	-23.35	11.63	10.40	2.21	V		0.096	19.82		
1907.5		QPSK	-19.12	15.82	10.40	2.17	V		0.254	24.05	1	0
		16-QAM	-19.89	15.05	10.40	2.17	V		0.213	23.28		
		64-QAM	-20.82	14.12	10.40	2.17	V		0.172	22.35		
		256-QAM	-23.98	10.96	10.40	2.17	V		0.083	19.19		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1860.0	LTE B25/B2 20 MHz	QPSK	-18.44	16.20	10.40	2.10	V	< 2.00	0.282	24.50	1	0
		16-QAM	-19.45	15.19	10.40	2.10	V		0.223	23.49		
		64-QAM	-20.16	14.48	10.40	2.10	V		0.189	22.78		
		256-QAM	-23.32	11.32	10.40	2.10	V		0.092	19.62		
1882.5		QPSK	-18.57	16.41	10.40	2.21	V		0.288	24.60	1	0
		16-QAM	-19.51	15.47	10.40	2.21	V		0.232	23.66		
		64-QAM	-20.31	14.67	10.40	2.21	V		0.193	22.86		
		256-QAM	-23.43	11.55	10.40	2.21	V		0.094	19.74		
1905.0		QPSK	-19.12	15.80	10.40	2.19	V		0.252	24.01	1	0
		16-QAM	-19.91	15.01	10.40	2.19	V		0.210	23.22		
		64-QAM	-20.95	13.97	10.40	2.19	V		0.165	22.18		
		256-QAM	-23.68	11.24	10.40	2.19	V		0.088	19.45		

8.2 RADIATED SPURIOUS EMISSIONS

MOD:	<u>LTE B25/B2</u>
MODULATION SIGNAL:	<u>20 MHz QPSK</u>
DISTANCE:	<u>3 meters</u>
LIMIT:	<u>-13 dBm</u>

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBi)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	RB	
								Size	Offset
26140 (1860.0)	3 720.00	-44.03	12.28	-61.04	3.13	H	-51.89	1	0
	5 580.00	-44.11	13.07	-56.39	3.91	V	-47.23		
	7 440.00	-44.05	10.78	-46.46	4.58	H	-40.26		
26365 (1882.5)	3 765.00	-42.74	12.22	-58.58	3.11	V	-49.47	1	0
	5 647.50	-40.57	13.12	-52.74	3.96	H	-43.58		
	7 530.00	-45.19	10.85	-47.83	4.60	V	-41.58		
26590 (1905.0)	3 810.00	-44.44	12.15	-60.68	3.20	H	-51.73	1	0
	5 715.00	-40.35	13.08	-52.78	4.01	V	-43.71		
	7 620.00	-44.09	11.14	-46.88	4.65	H	-40.39		

8.3 PEAK-TO-AVERAGE RATIO

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (dB)	Limit (dB)
25/2	1.4 MHz	1882.5	QPSK	6	0	5.71	13.00
			16-QAM			6.48	
			64-QAM			6.58	
			256-QAM			6.41	
	3 MHz		QPSK	15		5.77	
			16-QAM			6.37	
			64-QAM			6.67	
			256-QAM			6.32	
	5 MHz		QPSK	25		5.74	
			16-QAM			6.48	
			64-QAM			6.62	
			256-QAM			6.36	
	10 MHz		QPSK	50		5.84	
			16-QAM			6.44	
			64-QAM			6.74	
			256-QAM			6.36	
	15 MHz		QPSK	75		5.70	
			16-QAM			6.41	
			64-QAM			6.67	
			256-QAM			6.32	
	20 MHz		QPSK	100		5.65	
			16-QAM			6.41	
			64-QAM			6.64	
			256-QAM			6.35	

Note:

1. Plots of the EUT's Peak- to- Average Ratio are shown Page 77 ~ 100.

8.4 OCCUPIED BANDWIDTH

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (MHz)
25/2	1.4 MHz	1882.5	QPSK	6	0	1.0971
			16-QAM			1.0942
			64-QAM			1.0881
			256-QAM			1.0978
	3 MHz		QPSK	15		2.7164
			16-QAM			2.7016
			64-QAM			2.7028
			256-QAM			2.7078
	5 MHz		QPSK	25		4.5262
			16-QAM			4.5035
			64-QAM			4.5169
			256-QAM			4.5455
	10 MHz		QPSK	50		8.9952
			16-QAM			9.0087
			64-QAM			9.0338
			256-QAM			9.0152
	15 MHz		QPSK	75		13.455
			16-QAM			13.485
			64-QAM			13.517
			256-QAM			13.461
	20 MHz		QPSK	100		17.997
			16-QAM			17.954
			64-QAM			17.925
			256-QAM			17.960

Note:

1. Plots of the EUT's Occupied Bandwidth are shown Page 101 ~ 124.

8.5 CONDUCTED SPURIOUS EMISSIONS

Band	Band Width (MHz)	Frequency (MHz)	Frequency of Maximum Harmonic (GHz)	Factor (dB)	Measurement Maximum Data (dBm)	Result (dBm)	Limit (dBm)
25/2	1.4	1850.7	9.8405	28.591	-68.193	-39.602	-13.00
		1882.5	8.6740	28.591	-67.816	-39.225	
		1914.3	3.7987	27.976	-67.489	-39.513	
	3	1851.5	6.2712	28.591	-67.811	-39.220	
		1882.5	9.9801	28.591	-67.729	-39.138	
		1913.5	9.9900	28.591	-68.210	-39.619	
	5	1852.5	3.8286	27.976	-67.648	-39.672	
		1882.5	4.0479	27.976	-67.890	-39.914	
		1912.5	4.0280	27.976	-65.875	-37.899	
	10	1855.0	8.2752	28.591	-67.627	-39.036	
		1882.5	5.4537	28.591	-66.785	-38.194	
		1910.0	9.4616	28.591	-67.826	-39.235	
	15	1857.5	9.9701	28.591	-67.814	-39.223	
		1882.5	3.7787	27.976	-66.228	-38.252	
		1907.5	5.4337	28.591	-67.424	-38.833	
	20	1860.0	4.8256	27.976	-67.109	-39.133	
		1882.5	7.9960	28.591	-67.516	-38.925	
		1905.0	9.7009	28.591	-67.212	-38.621	

Note:

1. Plots of the EUT's Conducted Spurious Emissions are shown Page 125 ~ 160.
2. Conducted Spurious Emissions was Tested QPSK Modulation, Resource Block Size 1 and Resource Block Offset 0
3. Result (dBm) = Measurement Maximum Data (dBm) + Factor (dB)
4. Factor(dB) = Cable Loss + Ext. Attenuator + Power Splitter

Frequency Range (GHz)	Factor [dB]
0.03 – 1	25.270
1 – 5	27.976
5 – 10	28.591
10 – 15	29.116
15 – 20	29.489
Above 20(26.5)	30.131

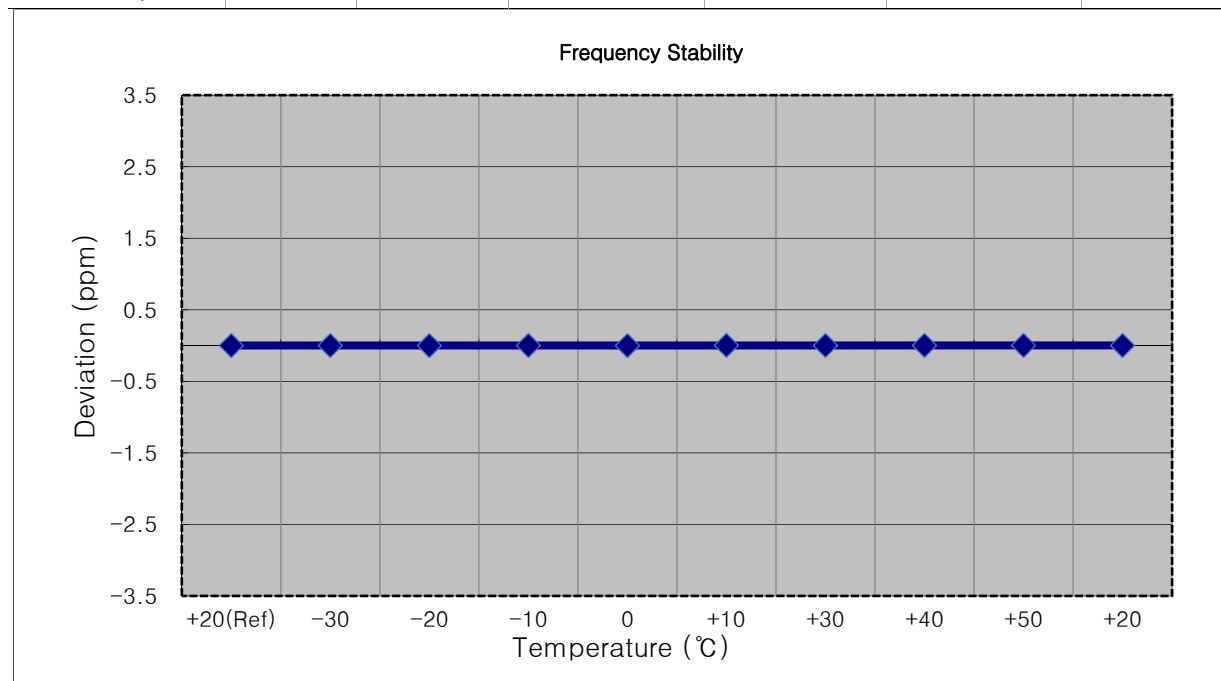
8.6 BAND EDGE

- Plots of the EUT's Band Edge are shown Page 161 ~ 196.

8.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE

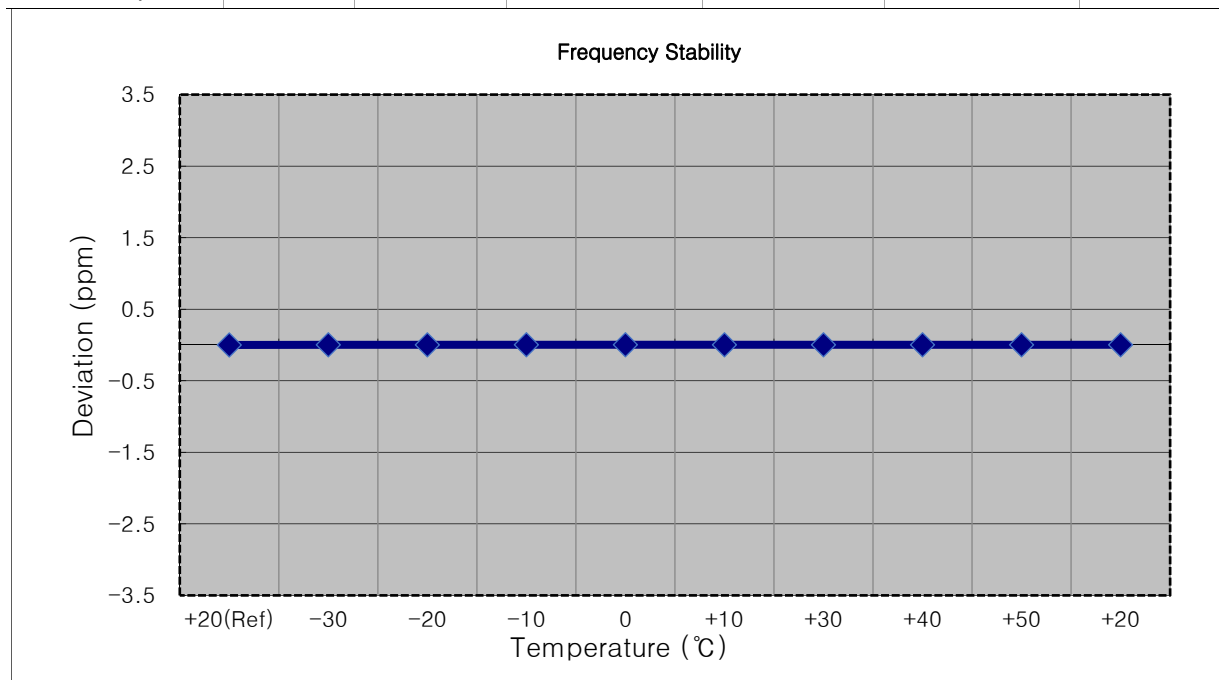
MODE:	<u>LTE B25/B2</u>
OPERATING FREQUENCY:	<u>1850,700,000 Hz</u>
CHANNEL:	<u>26047 (1.4 MHz)</u>
REFERENCE VOLTAGE:	<u>3.880 VDC</u>
DEVIATION LIMIT:	<u>Emission must remain in band</u>

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1850 700 004	0.0	0.000 000	0.000
100 %		-30	1850 700 005	1.3	0.000 000	0.001
100 %		-20	1850 700 002	-2.1	0.000 000	-0.001
100 %		-10	1850 700 007	2.8	0.000 000	0.002
100 %		0	1850 700 002	-2.4	0.000 000	-0.001
100 %		+10	1850 700 009	4.9	0.000 000	0.003
100 %		+30	1850 700 006	2.0	0.000 000	0.001
100 %		+40	1850 700 008	3.6	0.000 000	0.002
100 %		+50	1850 700 008	3.6	0.000 000	0.002
Batt. Endpoint	3.300	+20	1850 700 007	2.9	0.000 000	0.002



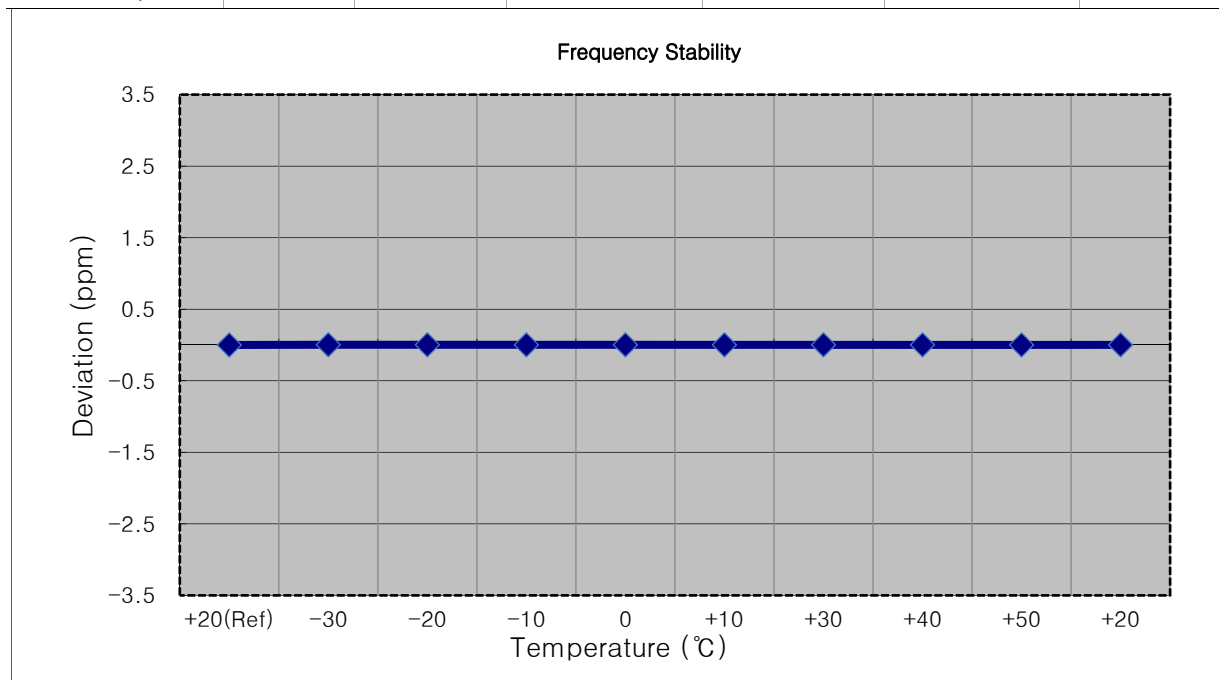
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1851,500,000 Hz
- ▣ CHANNEL: 26055 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1851 500 005	0.0	0.000 000	0.000
100 %		-30	1851 500 009	4.2	0.000 000	0.002
100 %		-20	1851 500 009	4.0	0.000 000	0.002
100 %		-10	1851 500 011	5.9	0.000 000	0.003
100 %		0	1851 500 011	6.0	0.000 000	0.003
100 %		+10	1851 500 010	4.9	0.000 000	0.003
100 %		+30	1851 500 010	5.1	0.000 000	0.003
100 %		+40	1851 500 009	4.6	0.000 000	0.002
100 %		+50	1851 500 010	4.7	0.000 000	0.003
Batt. Endpoint	3.300	+20	1851 500 010	5.1	0.000 000	0.003



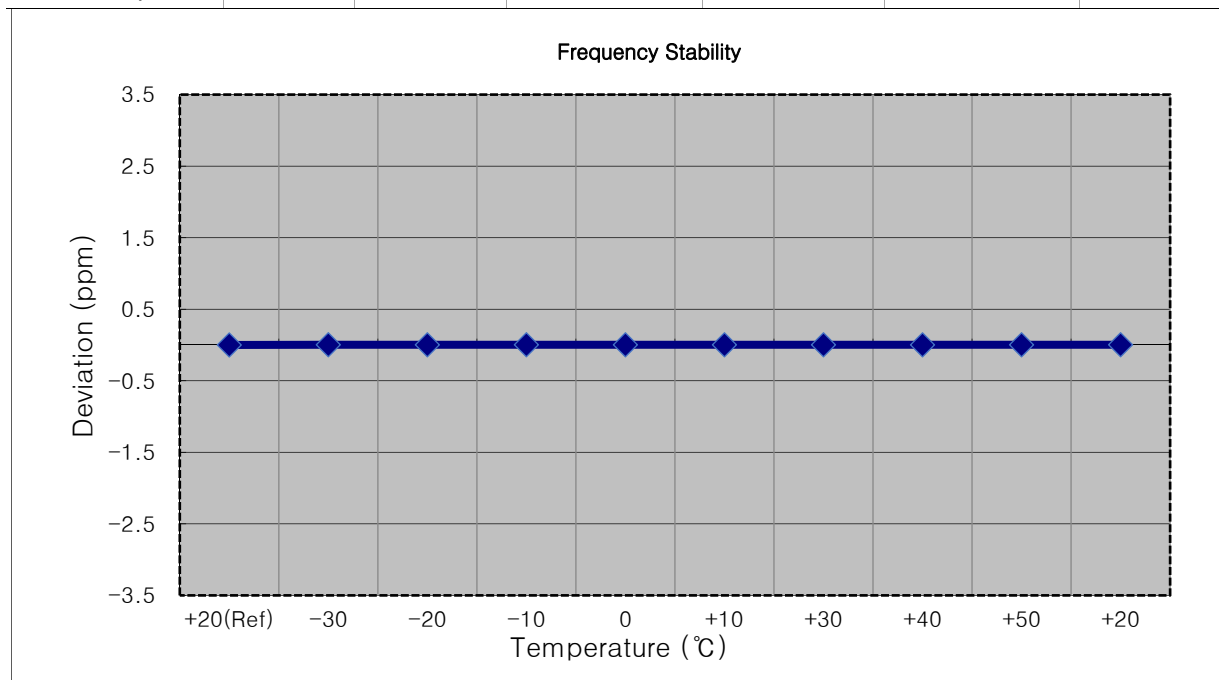
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1852,500,000 Hz
- ▣ CHANNEL: 26065 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1852 500 003	0.0	0.000 000	0.000
100 %		-30	1852 500 009	5.7	0.000 000	0.003
100 %		-20	1852 500 008	4.7	0.000 000	0.003
100 %		-10	1852 500 006	3.1	0.000 000	0.002
100 %		0	1852 500 007	4.1	0.000 000	0.002
100 %		+10	1852 500 006	3.6	0.000 000	0.002
100 %		+30	1852 500 006	3.6	0.000 000	0.002
100 %		+40	1852 500 006	3.4	0.000 000	0.002
100 %		+50	1852 500 005	1.9	0.000 000	0.001
Batt. Endpoint	3.300	+20	1852 500 006	2.8	0.000 000	0.002



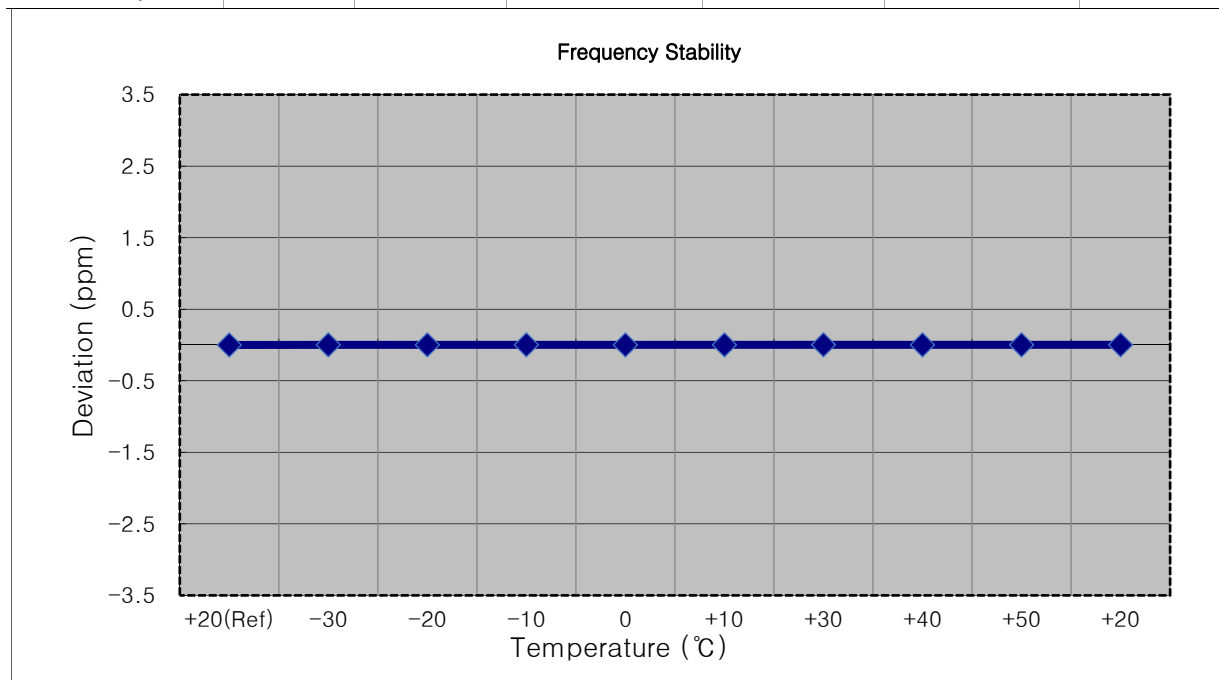
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1855,000,000 Hz
- ▣ CHANNEL: 26090 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1855 000 005	0.0	0.000 000	0.000
100 %		-30	1855 000 011	5.7	0.000 000	0.003
100 %		-20	1855 000 010	5.1	0.000 000	0.003
100 %		-10	1855 000 011	6.0	0.000 000	0.003
100 %		0	1855 000 010	5.1	0.000 000	0.003
100 %		+10	1855 000 010	5.0	0.000 000	0.003
100 %		+30	1855 000 010	5.0	0.000 000	0.003
100 %		+40	1855 000 009	4.0	0.000 000	0.002
100 %		+50	1855 000 010	4.9	0.000 000	0.003
Batt. Endpoint	3.300	+20	1855 000 011	5.8	0.000 000	0.003



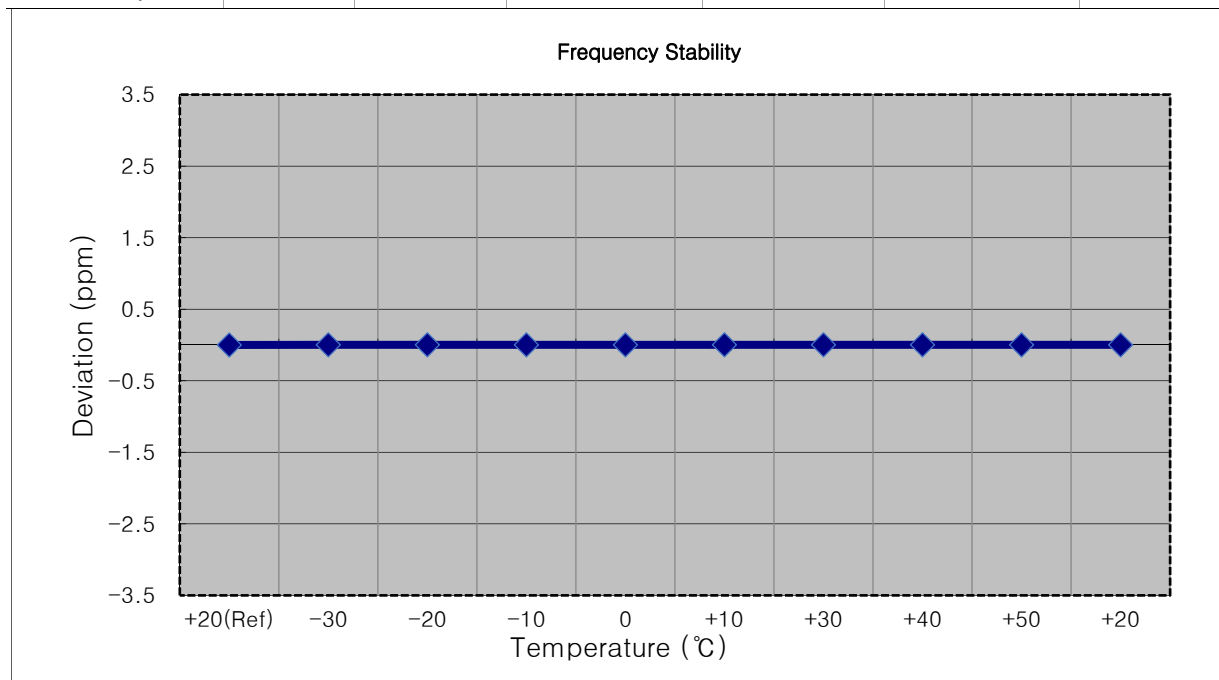
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1857,500,000 Hz
- ▣ CHANNEL: 26115 (15 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1857 500 005	0.0	0.000 000	0.000
100 %		-30	1857 500 008	3.2	0.000 000	0.002
100 %		-20	1857 500 008	3.4	0.000 000	0.002
100 %		-10	1857 500 009	4.2	0.000 000	0.002
100 %		0	1857 500 007	2.3	0.000 000	0.001
100 %		+10	1857 500 009	4.0	0.000 000	0.002
100 %		+30	1857 500 010	5.1	0.000 000	0.003
100 %		+40	1857 500 009	3.7	0.000 000	0.002
100 %		+50	1857 500 009	4.1	0.000 000	0.002
Batt. Endpoint	3.300	+20	1857 500 010	4.7	0.000 000	0.003



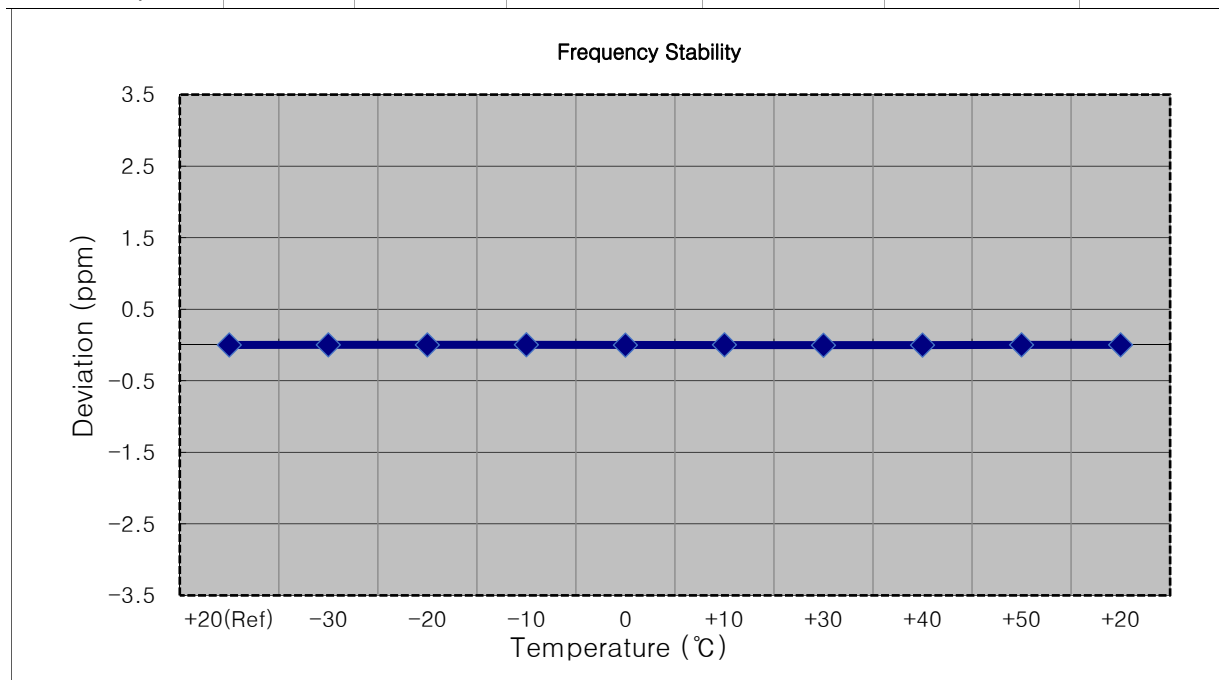
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1860,000,000 Hz
- ▣ CHANNEL: 26140 (20 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1860 000 004	0.0	0.000 000	0.000
100 %		-30	1860 000 009	4.9	0.000 000	0.003
100 %		-20	1860 000 009	4.9	0.000 000	0.003
100 %		-10	1860 000 008	3.8	0.000 000	0.002
100 %		0	1860 000 007	3.1	0.000 000	0.002
100 %		+10	1860 000 008	4.2	0.000 000	0.002
100 %		+30	1860 000 009	4.7	0.000 000	0.003
100 %		+40	1860 000 009	4.4	0.000 000	0.002
100 %		+50	1860 000 008	3.8	0.000 000	0.002
Batt. Endpoint	3.300	+20	1860 000 008	3.7	0.000 000	0.002



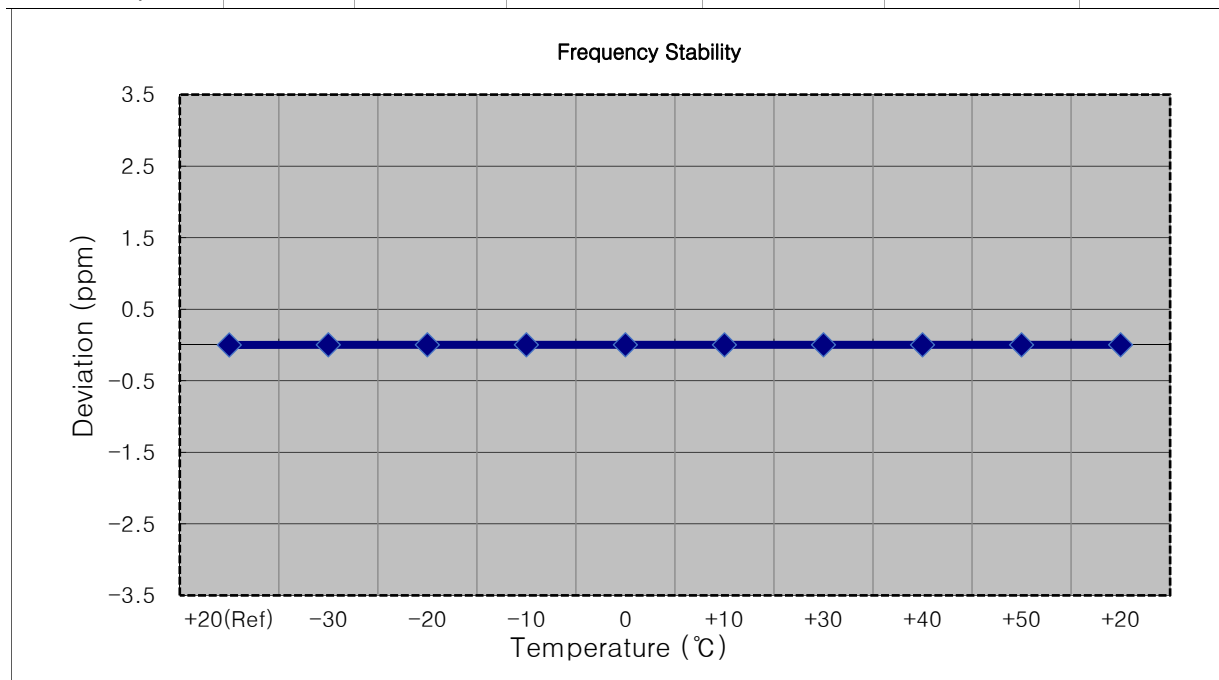
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 008	0.0	0.000 000	0.000
100 %		-30	1882 500 011	3.9	0.000 000	0.002
100 %		-20	1882 500 010	2.5	0.000 000	0.001
100 %		-10	1882 500 013	5.7	0.000 000	0.003
100 %		0	1882 500 004	-3.9	0.000 000	-0.002
100 %		+10	1882 500 012	4.5	0.000 000	0.002
100 %		+30	1882 500 000	-7.6	0.000 000	-0.004
100 %		+40	1882 500 004	-3.7	0.000 000	-0.002
100 %		+50	1882 500 011	3.3	0.000 000	0.002
Batt. Endpoint	3.300	+20	1882 500 011	3.3	0.000 000	0.002



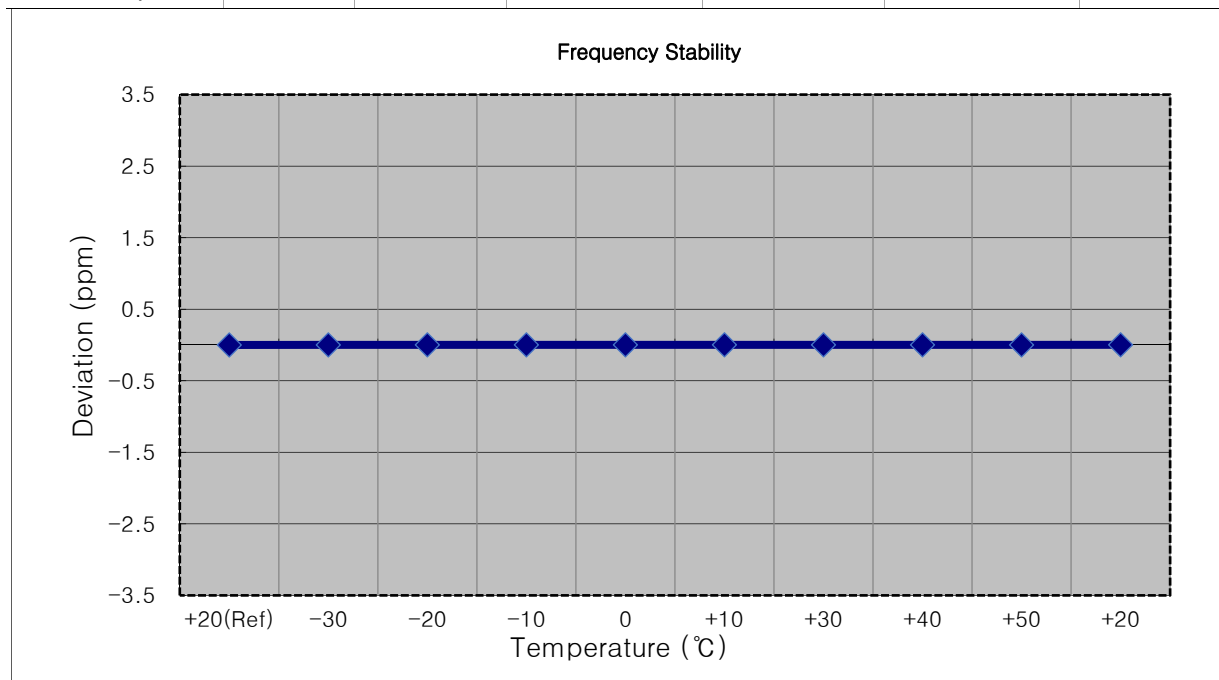
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 005	0.0	0.000 000	0.000
100 %		-30	1882 500 010	5.2	0.000 000	0.003
100 %		-20	1882 500 009	4.3	0.000 000	0.002
100 %		-10	1882 500 010	5.1	0.000 000	0.003
100 %		0	1882 500 009	4.8	0.000 000	0.003
100 %		+10	1882 500 008	3.8	0.000 000	0.002
100 %		+30	1882 500 009	4.8	0.000 000	0.003
100 %		+40	1882 500 009	4.0	0.000 000	0.002
100 %		+50	1882 500 008	3.7	0.000 000	0.002
Batt. Endpoint	3.300	+20	1882 500 009	4.7	0.000 000	0.002



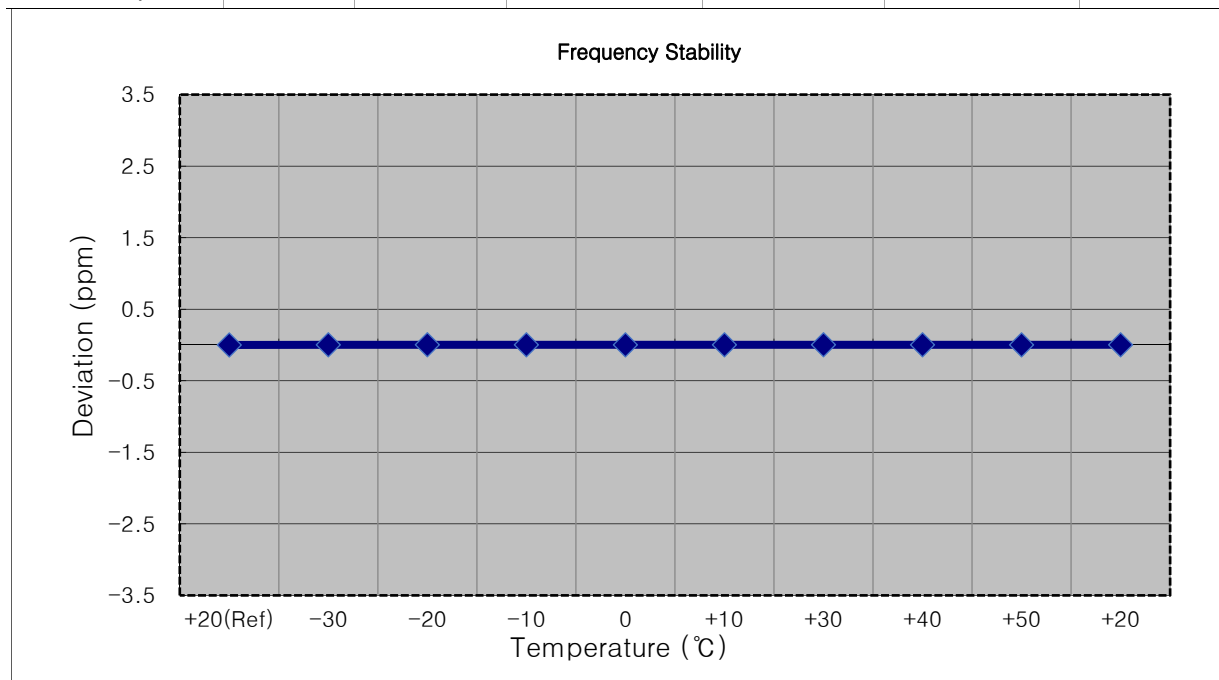
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 003	0.0	0.000 000	0.000
100 %		-30	1882 500 005	2.1	0.000 000	0.001
100 %		-20	1882 500 007	3.5	0.000 000	0.002
100 %		-10	1882 500 006	3.0	0.000 000	0.002
100 %		0	1882 500 006	2.9	0.000 000	0.002
100 %		+10	1882 500 008	4.9	0.000 000	0.003
100 %		+30	1882 500 006	3.1	0.000 000	0.002
100 %		+40	1882 500 007	3.4	0.000 000	0.002
100 %		+50	1882 500 006	2.7	0.000 000	0.001
Batt. Endpoint	3.300	+20	1882 500 008	4.4	0.000 000	0.002



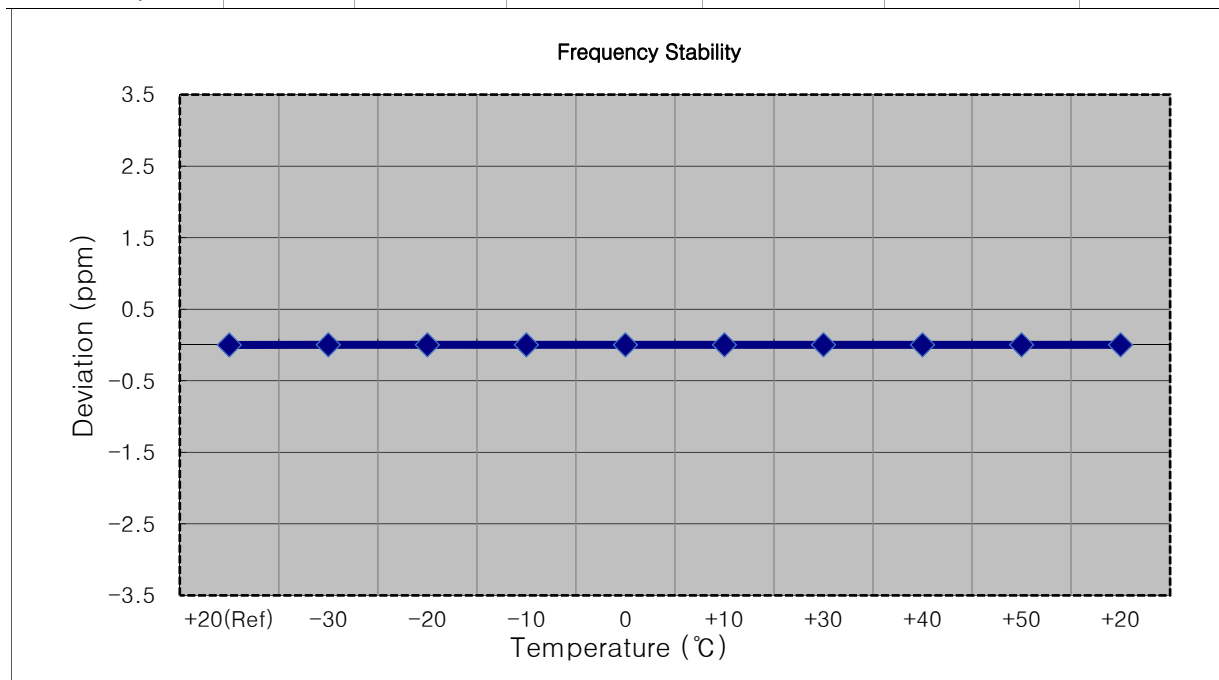
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 004	0.0	0.000 000	0.000
100 %		-30	1882 500 008	4.4	0.000 000	0.002
100 %		-20	1882 500 010	5.9	0.000 000	0.003
100 %		-10	1882 500 008	4.6	0.000 000	0.002
100 %		0	1882 500 008	4.1	0.000 000	0.002
100 %		+10	1882 500 008	4.6	0.000 000	0.002
100 %		+30	1882 500 010	6.0	0.000 000	0.003
100 %		+40	1882 500 008	4.7	0.000 000	0.002
100 %		+50	1882 500 008	3.9	0.000 000	0.002
Batt. Endpoint	3.300	+20	1882 500 009	5.5	0.000 000	0.003



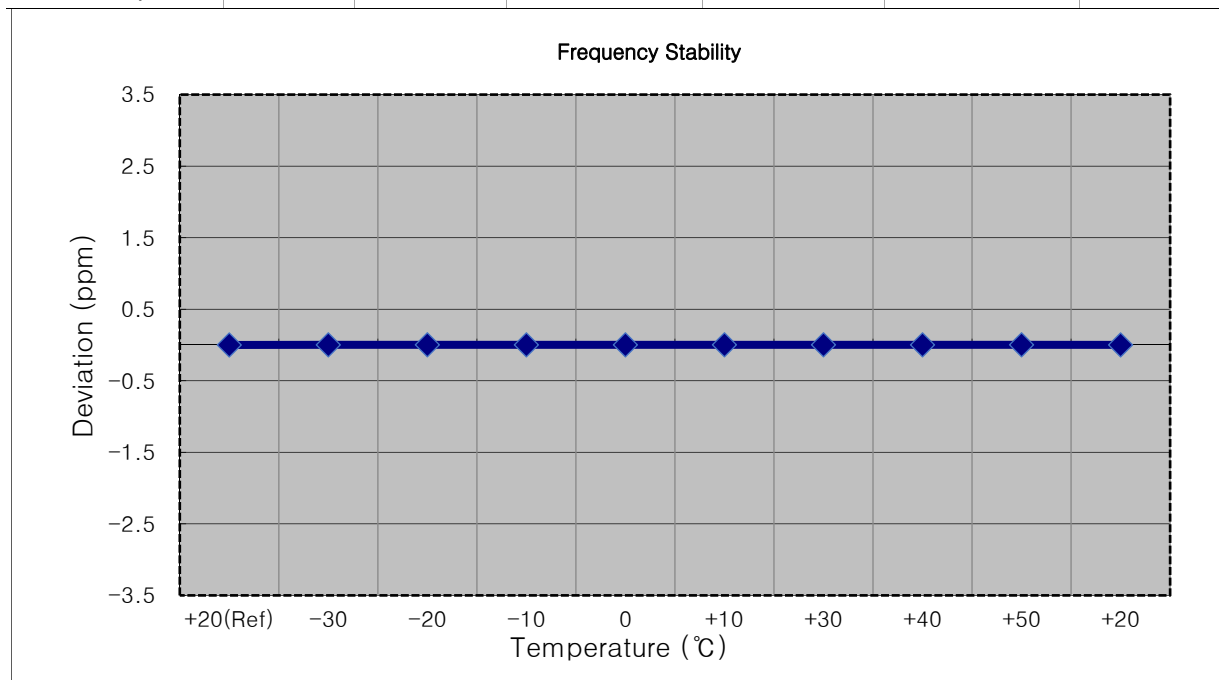
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (15 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 003	0.0	0.000 000	0.000
100 %		-30	1882 500 008	4.8	0.000 000	0.003
100 %		-20	1882 500 006	3.2	0.000 000	0.002
100 %		-10	1882 500 007	3.8	0.000 000	0.002
100 %		0	1882 500 007	3.7	0.000 000	0.002
100 %		+10	1882 500 006	3.4	0.000 000	0.002
100 %		+30	1882 500 008	4.9	0.000 000	0.003
100 %		+40	1882 500 006	2.8	0.000 000	0.001
100 %		+50	1882 500 006	3.4	0.000 000	0.002
Batt. Endpoint	3.300	+20	1882 500 007	3.9	0.000 000	0.002



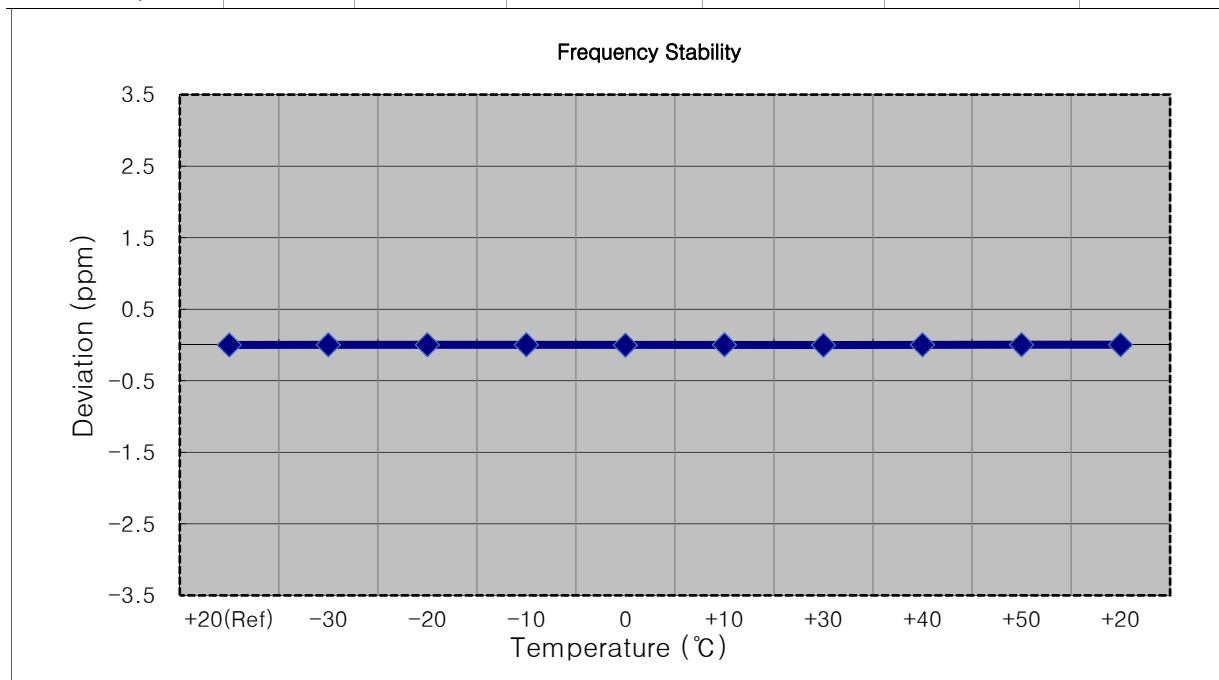
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (20 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 003	0.0	0.000 000	0.000
100 %		-30	1882 500 007	4.1	0.000 000	0.002
100 %		-20	1882 500 008	4.2	0.000 000	0.002
100 %		-10	1882 500 007	3.3	0.000 000	0.002
100 %		0	1882 500 007	4.0	0.000 000	0.002
100 %		+10	1882 500 008	4.3	0.000 000	0.002
100 %		+30	1882 500 009	5.3	0.000 000	0.003
100 %		+40	1882 500 007	4.1	0.000 000	0.002
100 %		+50	1882 500 008	4.5	0.000 000	0.002
Batt. Endpoint	3.300	+20	1882 500 006	2.5	0.000 000	0.001



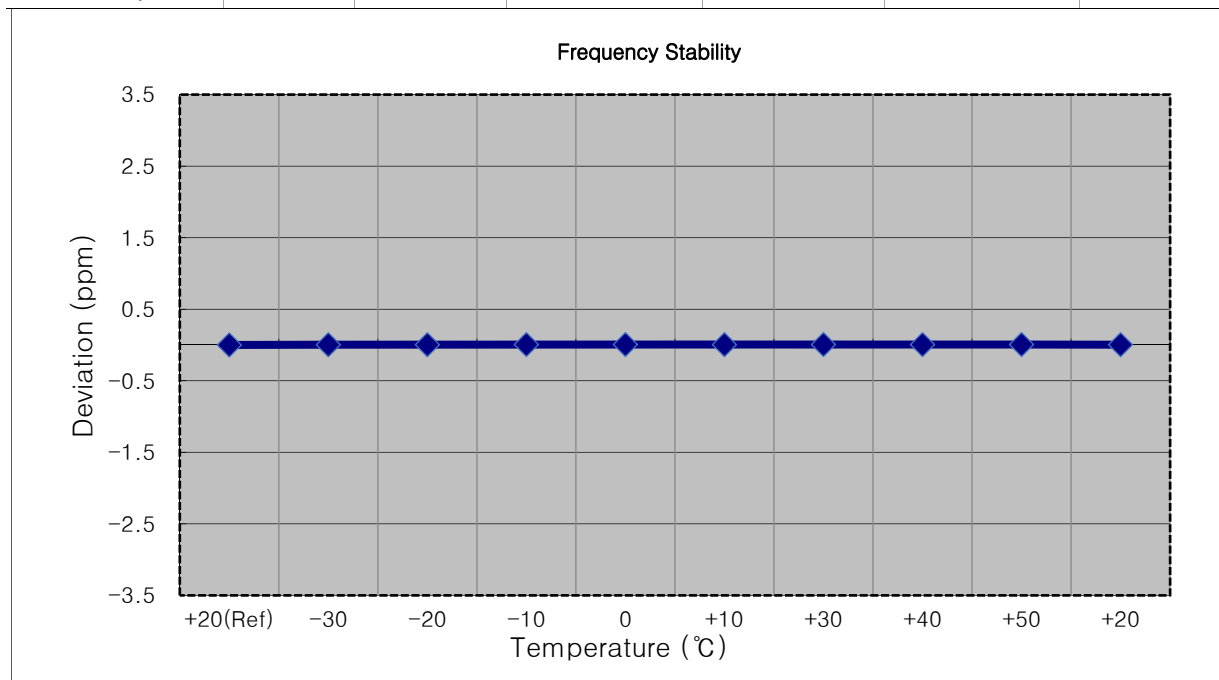
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1914,300,000 Hz
- ▣ CHANNEL: 26683 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1914 299 992	0.0	0.000 000	0.000
100 %		-30	1914 299 997	4.5	0.000 000	0.002
100 %		-20	1914 299 999	6.4	0.000 000	0.003
100 %		-10	1914 299 999	6.2	0.000 000	0.003
100 %		0	1914 299 988	-4.8	0.000 000	-0.003
100 %		+10	1914 299 999	6.3	0.000 000	0.003
100 %		+30	1914 299 988	-4.5	0.000 000	-0.002
100 %		+40	1914 299 998	5.5	0.000 000	0.003
100 %		+50	1914 300 000	7.6	0.000 000	0.004
Batt. Endpoint	3.300	+20	1914 299 999	6.7	0.000 000	0.003



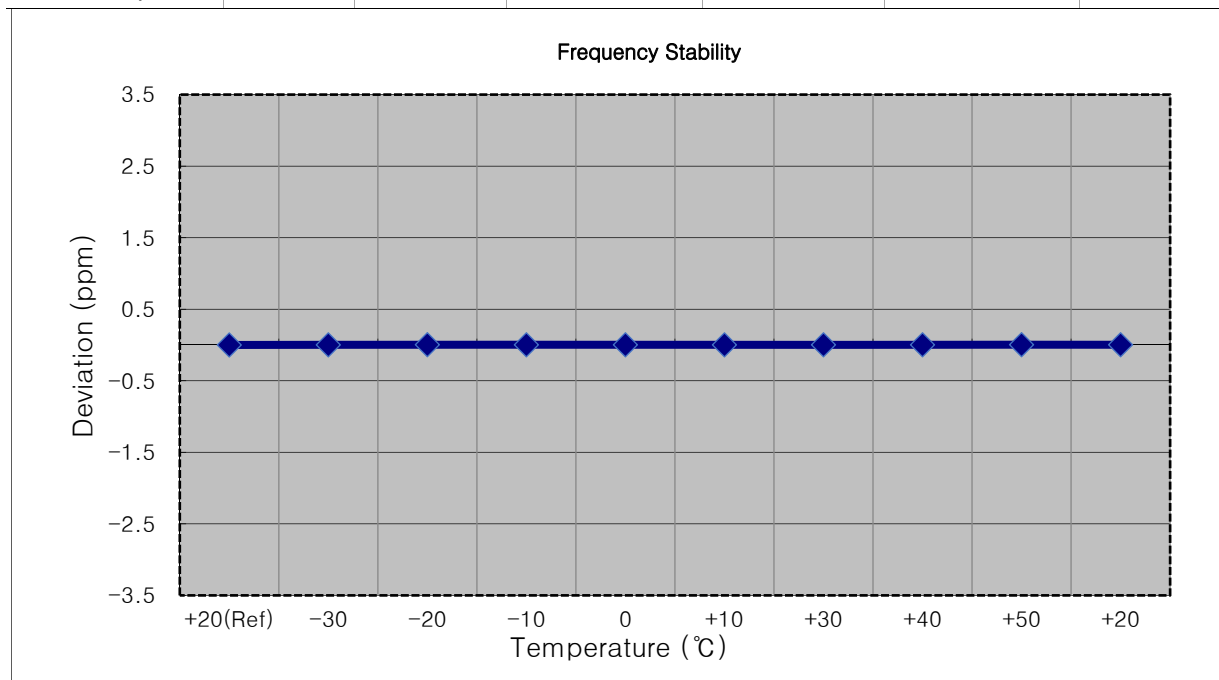
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1913,500,000 Hz
- ▣ CHANNEL: 26675 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1913 500 007	0.0	0.000 000	0.000
100 %		-30	1913 500 013	6.4	0.000 000	0.003
100 %		-20	1913 500 015	7.9	0.000 000	0.004
100 %		-10	1913 500 019	11.6	0.000 001	0.006
100 %		0	1913 500 019	12.1	0.000 001	0.006
100 %		+10	1913 500 016	9.0	0.000 000	0.005
100 %		+30	1913 500 019	11.7	0.000 001	0.006
100 %		+40	1913 500 018	11.0	0.000 001	0.006
100 %		+50	1913 500 020	12.7	0.000 001	0.007
Batt. Endpoint	3.300	+20	1913 500 015	7.6	0.000 000	0.004



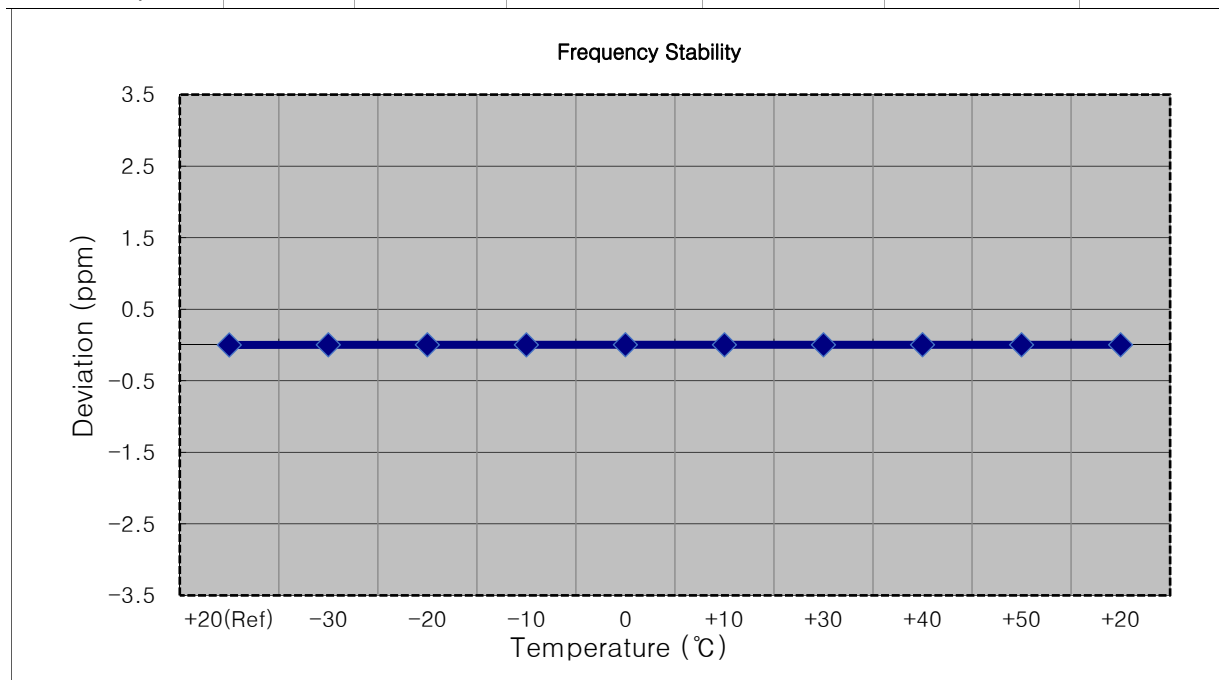
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1912,500,000 Hz
- ▣ CHANNEL: 26665 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1912 500 005	0.0	0.000 000	0.000
100 %		-30	1912 500 009	4.0	0.000 000	0.002
100 %		-20	1912 500 013	7.6	0.000 000	0.004
100 %		-10	1912 500 010	5.1	0.000 000	0.003
100 %		0	1912 500 009	4.5	0.000 000	0.002
100 %		+10	1912 500 009	3.7	0.000 000	0.002
100 %		+30	1912 500 009	4.3	0.000 000	0.002
100 %		+40	1912 500 010	4.9	0.000 000	0.003
100 %		+50	1912 500 012	7.3	0.000 000	0.004
Batt. Endpoint	3.300	+20	1912 500 011	5.9	0.000 000	0.003



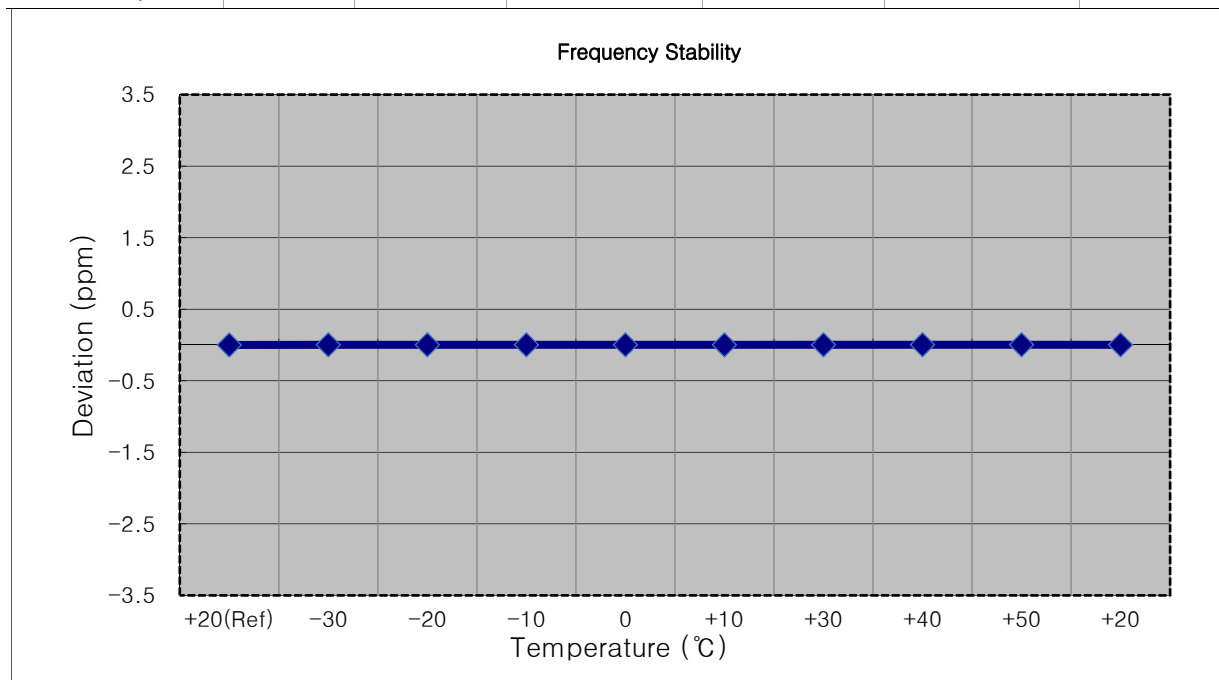
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1910,000,000 Hz
- ▣ CHANNEL: 26640 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1910 000 005	0.0	0.000 000	0.000
100 %		-30	1910 000 009	4.7	0.000 000	0.002
100 %		-20	1910 000 010	5.5	0.000 000	0.003
100 %		-10	1910 000 009	4.1	0.000 000	0.002
100 %		0	1910 000 010	5.8	0.000 000	0.003
100 %		+10	1910 000 010	5.2	0.000 000	0.003
100 %		+30	1910 000 009	4.9	0.000 000	0.003
100 %		+40	1910 000 011	6.2	0.000 000	0.003
100 %		+50	1910 000 009	4.3	0.000 000	0.002
Batt. Endpoint	3.300	+20	1910 000 010	5.4	0.000 000	0.003



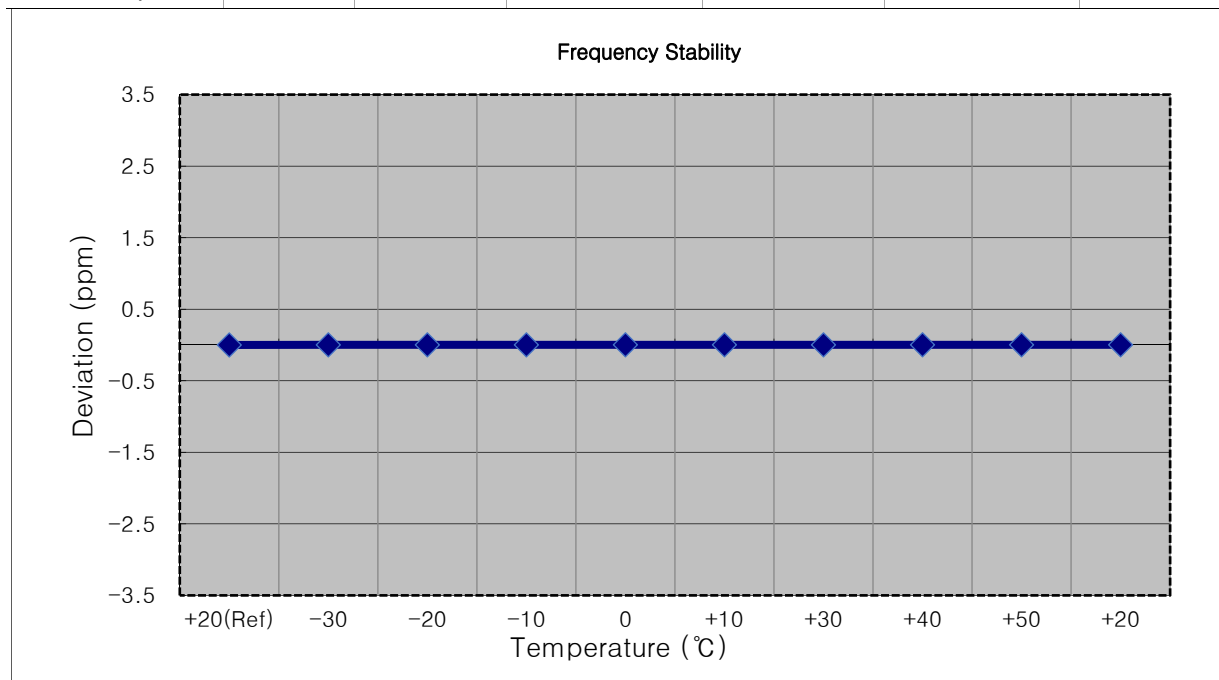
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1907,500,000 Hz
- ▣ CHANNEL: 26615 (15 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1907 500 006	0.0	0.000 000	0.000
100 %		-30	1907 500 010	4.4	0.000 000	0.002
100 %		-20	1907 500 011	5.0	0.000 000	0.003
100 %		-10	1907 500 010	4.5	0.000 000	0.002
100 %		0	1907 500 011	4.9	0.000 000	0.003
100 %		+10	1907 500 009	3.7	0.000 000	0.002
100 %		+30	1907 500 010	4.4	0.000 000	0.002
100 %		+40	1907 500 012	6.0	0.000 000	0.003
100 %		+50	1907 500 012	6.7	0.000 000	0.004
Batt. Endpoint	3.300	+20	1907 500 010	4.6	0.000 000	0.002



- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1905,000,000 Hz
- ▣ CHANNEL: 26590 (20 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1905 000 005	0.0	0.000 000	0.000
100 %		-30	1905 000 009	4.1	0.000 000	0.002
100 %		-20	1905 000 009	3.9	0.000 000	0.002
100 %		-10	1905 000 008	3.1	0.000 000	0.002
100 %		0	1905 000 010	4.6	0.000 000	0.002
100 %		+10	1905 000 010	5.4	0.000 000	0.003
100 %		+30	1905 000 009	4.2	0.000 000	0.002
100 %		+40	1905 000 009	4.3	0.000 000	0.002
100 %		+50	1905 000 010	4.9	0.000 000	0.003
Batt. Endpoint	3.300	+20	1905 000 010	4.7	0.000 000	0.002



9. TEST DATA(Sub 2 ANT)

9.1 EQUIVALENT ISOTROPIC RADIATED POWER

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1850.7	LTE B25/B2 1.4 MHz	QPSK	-20.92	13.60	10.40	2.07	V	< 2.00	0.156	21.93	1	5
		16-QAM	-21.57	12.95	10.40	2.07	V		0.134	21.28		
		64-QAM	-22.60	11.92	10.40	2.07	V		0.106	20.25		
		256-QAM	-25.50	9.02	10.40	2.07	V		0.054	17.35		
1882.5		QPSK	-21.38	13.60	10.40	2.21	V		0.151	21.79	1	0
		16-QAM	-21.98	13.00	10.40	2.21	V		0.132	21.19		
		64-QAM	-23.11	11.87	10.40	2.21	V		0.101	20.06		
		256-QAM	-26.09	8.89	10.40	2.21	V		0.051	17.08		
1914.3		QPSK	-21.90	13.11	10.40	2.17	V		0.136	21.34	1	0
		16-QAM	-22.50	12.51	10.40	2.17	V		0.118	20.74		
		64-QAM	-23.62	11.39	10.40	2.17	V		0.092	19.62		
		256-QAM	-26.75	8.26	10.40	2.17	V		0.045	16.49		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1851.5	LTE B25/B2 3 MHz	QPSK	-20.89	13.63	10.40	2.07	V	< 2.00	0.157	21.96	1	8
		16-QAM	-21.55	12.97	10.40	2.07	V		0.135	21.30		
		64-QAM	-22.57	11.95	10.40	2.07	V		0.107	20.28		
		256-QAM	-25.48	9.04	10.40	2.07	V		0.055	17.37		
1882.5		QPSK	-21.21	13.77	10.40	2.21	V		0.157	21.96	1	0
		16-QAM	-21.82	13.16	10.40	2.21	V		0.136	21.35		
		64-QAM	-22.89	12.09	10.40	2.21	V		0.107	20.28		
		256-QAM	-25.93	9.05	10.40	2.21	V		0.053	17.24		
1913.5		QPSK	-21.60	13.41	10.40	2.17	V		0.146	21.64	1	0
		16-QAM	-22.32	12.69	10.40	2.17	V		0.124	20.92		
		64-QAM	-23.30	11.71	10.40	2.17	V		0.099	19.94		
		256-QAM	-26.35	8.66	10.40	2.17	V		0.049	16.89		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1852.5	LTE B25/B2 5 MHz	QPSK	-20.86	13.71	10.40	2.08	V	< 2.00	0.160	22.03	1	13
		16-QAM	-21.51	13.06	10.40	2.08	V		0.137	21.38		
		64-QAM	-22.82	11.75	10.40	2.08	V		0.102	20.07		
		256-QAM	-25.86	8.71	10.40	2.08	V		0.050	17.03		
1882.5		QPSK	-21.30	13.68	10.40	2.21	V		0.154	21.87	1	0
		16-QAM	-21.87	13.11	10.40	2.21	V		0.135	21.30		
		64-QAM	-22.90	12.08	10.40	2.21	V		0.106	20.27		
		256-QAM	-26.00	8.98	10.40	2.21	V		0.052	17.17		
1912.5		QPSK	-21.46	13.55	10.40	2.17	V		0.151	21.78	1	0
		16-QAM	-22.11	12.90	10.40	2.17	V		0.130	21.13		
		64-QAM	-23.16	11.85	10.40	2.17	V		0.102	20.08		
		256-QAM	-26.10	8.91	10.40	2.17	V		0.052	17.14		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1855.0	LTE B25/B2 10 MHz	QPSK	-20.82	13.75	10.40	2.08	V	< 2.00	0.161	22.07	1	0
		16-QAM	-21.60	12.97	10.40	2.08	V		0.135	21.29		
		64-QAM	-22.69	11.88	10.40	2.08	V		0.105	20.20		
		256-QAM	-25.58	8.99	10.40	2.08	V		0.054	17.31		
QPSK		-20.94	14.04	10.40	2.21	V	0.167		22.23	1	0	
16-QAM		-21.89	13.09	10.40	2.21	V	0.134		21.28			
64-QAM		-22.85	12.13	10.40	2.21	V	0.108		20.32			
256-QAM		-25.62	9.36	10.40	2.21	V	0.057		17.55			
1910.0		QPSK	-21.35	13.59	10.40	2.17	V		0.152	21.82	1	0
		16-QAM	-21.97	12.97	10.40	2.17	V		0.132	21.20		
		64-QAM	-23.03	11.91	10.40	2.17	V		0.103	20.14		
		256-QAM	-25.97	8.97	10.40	2.17	V		0.052	17.20		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1857.5	LTE B25/B2 15 MHz	QPSK	-20.97	13.67	10.40	2.10	V	< 2.00	0.157	21.97	1	0
		16-QAM	-21.67	12.97	10.40	2.10	V		0.134	21.27		
		64-QAM	-22.85	11.79	10.40	2.10	V		0.102	20.09		
		256-QAM	-25.57	9.07	10.40	2.10	V		0.055	17.37		
1882.5		QPSK	-21.16	13.82	10.40	2.21	V		0.159	22.01	1	0
		16-QAM	-21.85	13.13	10.40	2.21	V		0.136	21.32		
		64-QAM	-22.75	12.23	10.40	2.21	V		0.110	20.42		
		256-QAM	-25.84	9.14	10.40	2.21	V		0.054	17.33		
1907.5		QPSK	-21.64	13.30	10.40	2.17	V		0.142	21.53	1	38
		16-QAM	-22.33	12.61	10.40	2.17	V		0.121	20.84		
		64-QAM	-23.23	11.71	10.40	2.17	V		0.099	19.94		
		256-QAM	-26.27	8.67	10.40	2.17	V		0.049	16.90		

Freq (MHz)	Mod/ Bandwidth	Modulation	Measured	Substitute	Ant. Gain(dBi)	C.L	Pol	Limit	EIRP		RB	
			Level (dBm)	Level (dBm)				W	W	dBm	Size	Offset
1860.0	LTE B25/B2 20 MHz	QPSK	-20.65	13.99	10.40	2.10	V	< 2.00	0.169	22.29	1	99
		16-QAM	-21.55	13.09	10.40	2.10	V		0.138	21.39		
		64-QAM	-22.44	12.20	10.40	2.10	V		0.112	20.50		
		256-QAM	-25.35	9.29	10.40	2.10	V		0.057	17.59		
1882.5		QPSK	-20.77	14.21	10.40	2.21	V		0.174	22.40	1	0
		16-QAM	-21.57	13.41	10.40	2.21	V		0.145	21.60		
		64-QAM	-22.41	12.57	10.40	2.21	V		0.119	20.76		
		256-QAM	-25.30	9.68	10.40	2.21	V		0.061	17.87		
1905.0		QPSK	-21.38	13.54	10.40	2.19	V		0.150	21.75	1	0
		16-QAM	-22.08	12.84	10.40	2.19	V		0.127	21.05		
		64-QAM	-23.22	11.70	10.40	2.19	V		0.098	19.91		
		256-QAM	-25.89	9.03	10.40	2.19	V		0.053	17.24		

9.2 RADIATED SPURIOUS EMISSIONS

▣ MOD:	<u>LTE B25/B2</u>
▣ MODULATION SIGNAL:	<u>20 MHz QPSK</u>
▣ DISTANCE:	<u>3 meters</u>
▣ LIMIT:	<u>-13 dBm</u>

Ch	Freq (MHz)	Measured Level (dBm)	Ant. Gain (dBi)	Substitute Level (dBm)	C.L	Pol	Result (dBm)	RB	
								Size	Offset
26140 (1860.0)	3 720.00	-41.36	12.28	-58.37	3.13	H	-49.22	1	99
	5 580.00	-22.15	13.07	-34.43	3.91	H	-25.27		
	7 440.00	-45.15	10.78	-47.56	4.58	H	-41.36		
26365 (1882.5)	3 765.00	-39.88	12.22	-55.72	3.11	H	-46.61	1	0
	5 647.50	-20.74	13.12	-32.91	3.96	H	-23.75		
	7 530.00	-44.11	10.85	-46.75	4.60	V	-40.50		
26590 (1905.0)	3 810.00	-40.33	12.15	-56.57	3.20	H	-47.62	1	0
	5 715.00	-23.96	13.08	-36.39	4.01	H	-27.32		
	7 620.00	-44.21	11.14	-47.00	4.65	V	-40.51		

9.3 PEAK-TO-AVERAGE RATIO

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (dB)	Limit (dB)
25/2	1.4 MHz	1882.5	QPSK	6	0	5.66	13.00
			16-QAM			6.34	
			64-QAM			6.56	
			256-QAM			6.14	
	3 MHz		QPSK	15		5.72	
			16-QAM			6.30	
			64-QAM			6.53	
			256-QAM			6.25	
	5 MHz		QPSK	25		5.68	
			16-QAM			6.34	
			64-QAM			6.55	
			256-QAM			6.28	
	10 MHz		QPSK	50		5.81	
			16-QAM			6.38	
			64-QAM			6.59	
			256-QAM			6.31	
	15 MHz		QPSK	75		5.71	
			16-QAM			6.35	
			64-QAM			6.54	
			256-QAM			6.32	
	20 MHz		QPSK	100		5.69	
			16-QAM			6.39	
			64-QAM			6.58	
			256-QAM			6.41	

Note:

1. Plots of the EUT's Peak- to- Average Ratio are shown Page 198 ~ 221.

9.4 OCCUPIED BANDWIDTH

Band	Band Width	Frequency (MHz)	Modulation	Resource Block Size	Resource Block Offset	Data (MHz)
25/2	1.4 MHz	1882.5	QPSK	6	0	1.0975
			16-QAM			1.0965
			64-QAM			1.0958
			256-QAM			1.0964
	3 MHz		QPSK	15		2.7197
			16-QAM			2.7025
			64-QAM			2.7025
			256-QAM			2.7153
	5 MHz		QPSK	25		4.5255
			16-QAM			4.5140
			64-QAM			4.5287
			256-QAM			4.5529
	10 MHz		QPSK	50		9.0084
			16-QAM			9.0137
			64-QAM			9.0197
			256-QAM			9.0318
	15 MHz		QPSK	75		13.473
			16-QAM			13.443
			64-QAM			13.508
			256-QAM			13.498
	20 MHz		QPSK	100		17.973
			16-QAM			17.903
			64-QAM			17.930
			256-QAM			17.911

Note:

1. Plots of the EUT's Occupied Bandwidth are shown Page 222 ~ 245.

9.5 CONDUCTED SPURIOUS EMISSIONS

Band	Band Width (MHz)	Frequency (MHz)	Frequency of Maximum Harmonic (GHz)	Factor (dB)	Measurement Maximum Data (dBm)	Result (dBm)	Limit (dBm)
25/2	1.4	1850.7	3.0808	27.976	-67.856	-39.880	-13.00
		1882.5	6.5304	28.591	-67.989	-39.398	
		1914.3	3.7189	27.976	-67.962	-39.986	
	3	1851.5	3.6990	27.976	-67.924	-39.948	
		1882.5	3.1805	27.976	-68.502	-40.526	
		1913.5	6.9492	28.591	-67.765	-39.174	
	5	1852.5	3.0509	27.976	-67.683	-39.707	
		1882.5	2.6920	27.976	-68.478	-40.502	
		1912.5	3.3400	27.976	-68.126	-40.150	
	10	1855.0	6.2214	28.591	-68.255	-39.664	
		1882.5	3.6890	27.976	-67.136	-39.160	
		1910.0	2.8116	27.976	-67.572	-39.596	
	15	1857.5	3.6591	27.976	-68.068	-40.092	
		1882.5	3.7189	27.976	-68.546	-40.570	
		1907.5	3.5295	27.976	-67.437	-39.461	
	20	1860.0	3.6990	27.976	-67.141	-39.165	
		1882.5	2.6820	27.976	-66.934	-38.958	
		1905.0	3.3999	27.976	-68.166	-40.190	

Note:

1. Plots of the EUT's Conducted Spurious Emissions are shown Page 246 ~ 281.
2. Conducted Spurious Emissions was Tested QPSK Modulation, Resource Block Size 1 and Resource Block Offset 0
3. Result (dBm) = Measurement Maximum Data (dBm) + Factor (dB)
4. Factor(dB) = Cable Loss + Ext. Attenuator + Power Splitter

Frequency Range (GHz)	Factor [dB]
0.03 – 1	25.270
1 – 5	27.976
5 – 10	28.591
10 – 15	29.116
15 – 20	29.489
Above 20(26.5)	30.131

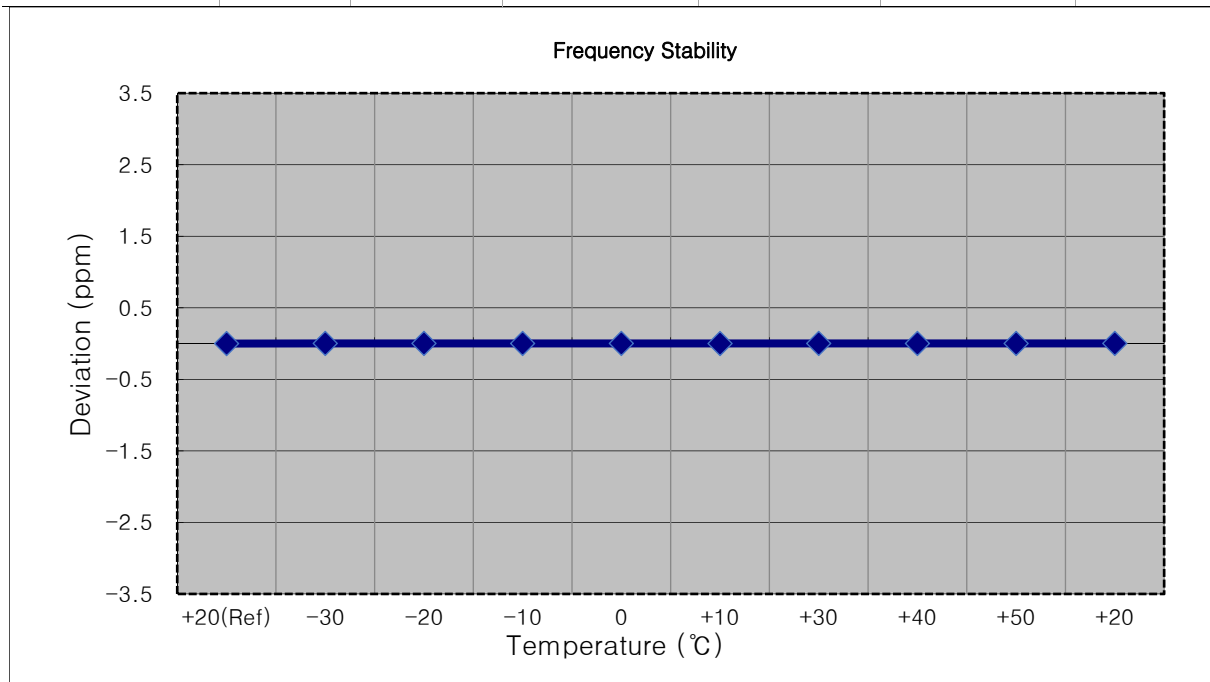
9.6 BAND EDGE

- Plots of the EUT's Band Edge are shown Page 282 ~ 317.

9.7 FREQUENCY STABILITY / VARIATION OF AMBIENT TEMPERATURE

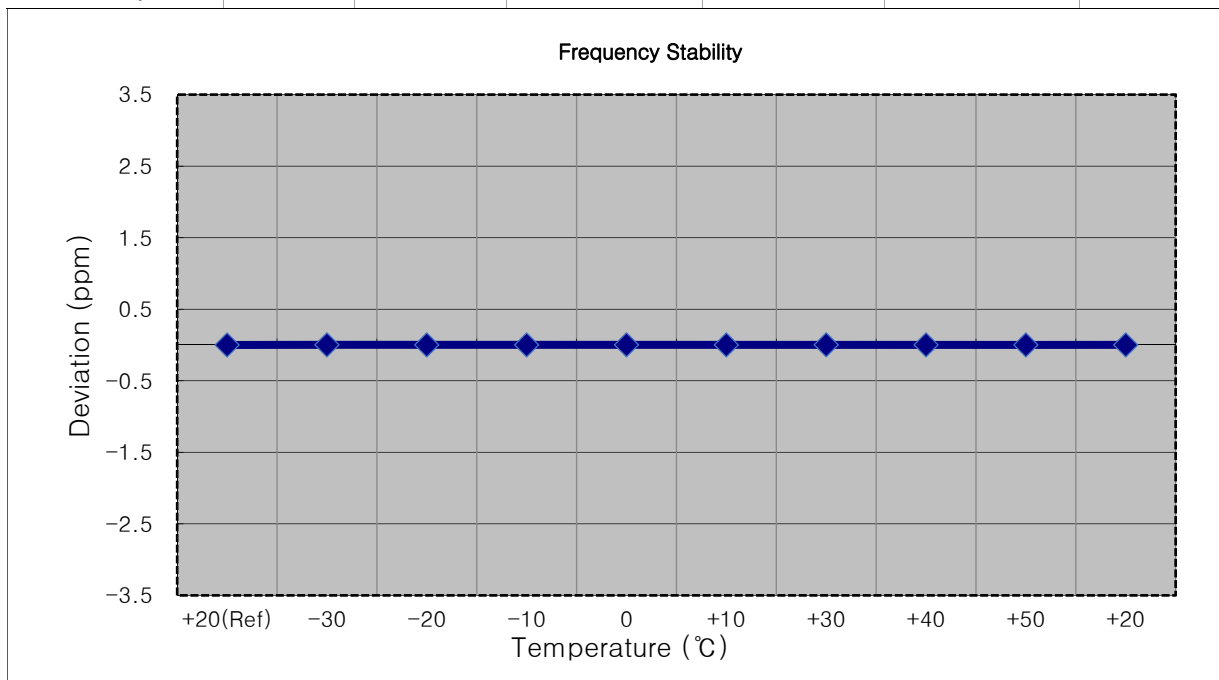
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1850,700,000 Hz
- ▣ CHANNEL: 26047 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage	Power	Temp.	Frequency	Frequency	Deviation	ppm
(%)	(VDC)	(°C)	(Hz)	Error (Hz)	(%)	
100 %	3.880	+20(Ref)	1850 700 003	0.0	0.000 000	0.000
100 %		-30	1850 700 006	3.2	0.000 000	0.002
100 %		-20	1850 700 006	3.2	0.000 000	0.002
100 %		-10	1850 700 006	2.5	0.000 000	0.001
100 %		0	1850 700 006	3.1	0.000 000	0.002
100 %		+10	1850 700 005	1.3	0.000 000	0.001
100 %		+30	1850 700 007	3.6	0.000 000	0.002
100 %		+40	1850 700 005	1.9	0.000 000	0.001
100 %		+50	1850 700 006	2.8	0.000 000	0.002
Batt. Endpoint	3.300	+20	1850 700 007	3.5	0.000 000	0.002



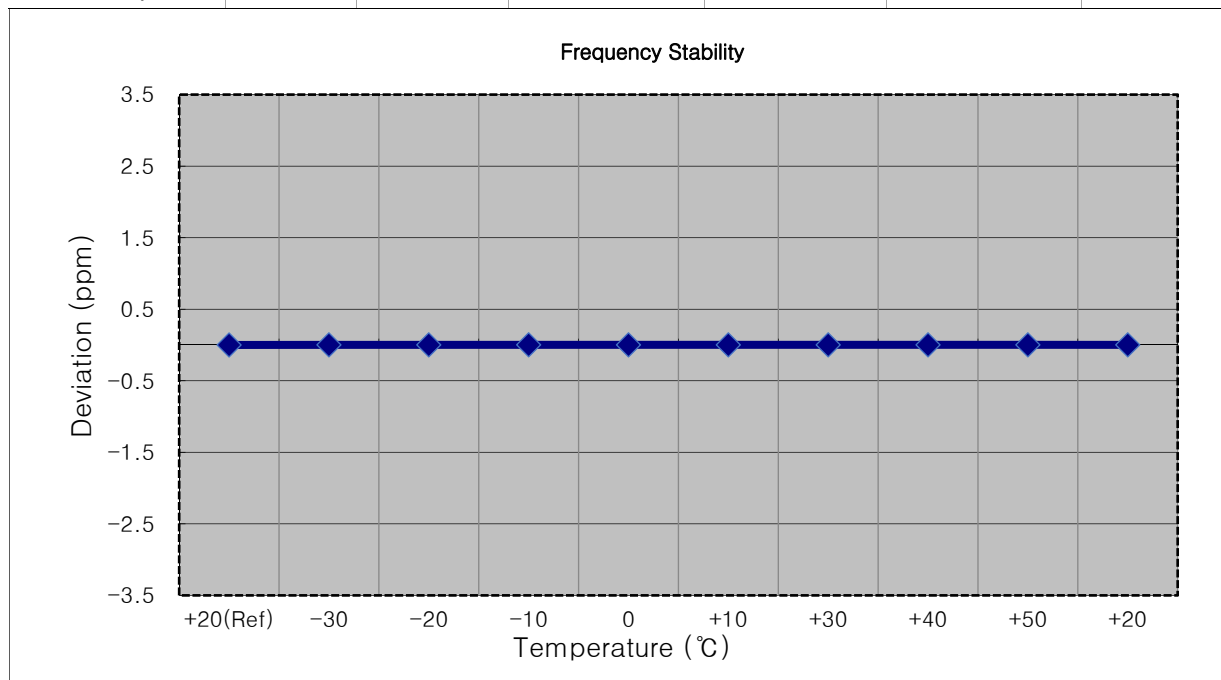
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1851,500,000 Hz
- ▣ CHANNEL: 26055 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1851 500 004	0.0	0.000 000	0.000
100 %		-30	1851 500 008	4.0	0.000 000	0.002
100 %		-20	1851 500 007	2.7	0.000 000	0.001
100 %		-10	1851 500 006	1.8	0.000 000	0.001
100 %		0	1851 500 009	4.6	0.000 000	0.002
100 %		+10	1851 500 006	2.3	0.000 000	0.001
100 %		+30	1851 500 008	4.1	0.000 000	0.002
100 %		+40	1851 500 007	3.3	0.000 000	0.002
100 %		+50	1851 500 006	1.8	0.000 000	0.001
Batt. Endpoint	3.300	+20	1851 500 007	2.6	0.000 000	0.001



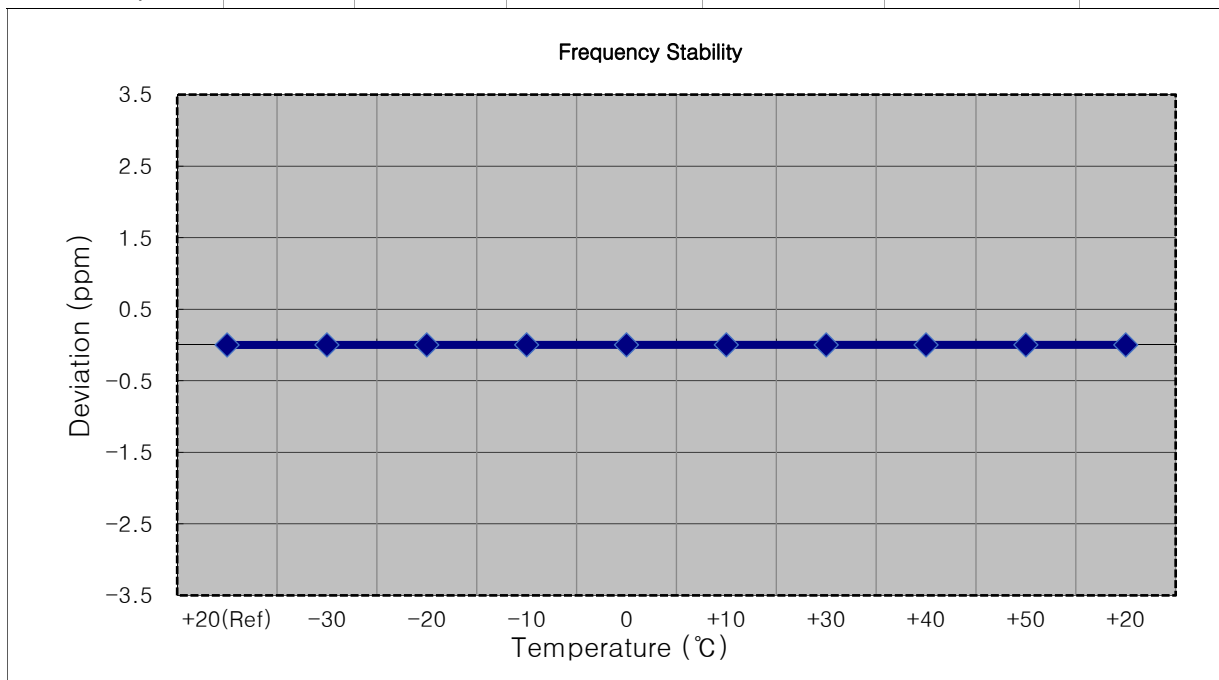
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1852,500,000 Hz
- ▣ CHANNEL: 26065 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1852 500 003	0.0	0.000 000	0.000
100 %		-30	1852 500 006	3.3	0.000 000	0.002
100 %		-20	1852 500 006	3.2	0.000 000	0.002
100 %		-10	1852 500 008	5.1	0.000 000	0.003
100 %		0	1852 500 006	3.8	0.000 000	0.002
100 %		+10	1852 500 006	3.5	0.000 000	0.002
100 %		+30	1852 500 006	3.4	0.000 000	0.002
100 %		+40	1852 500 006	3.6	0.000 000	0.002
100 %		+50	1852 500 006	3.8	0.000 000	0.002
Batt. Endpoint	3.300	+20	1852 500 005	2.8	0.000 000	0.002



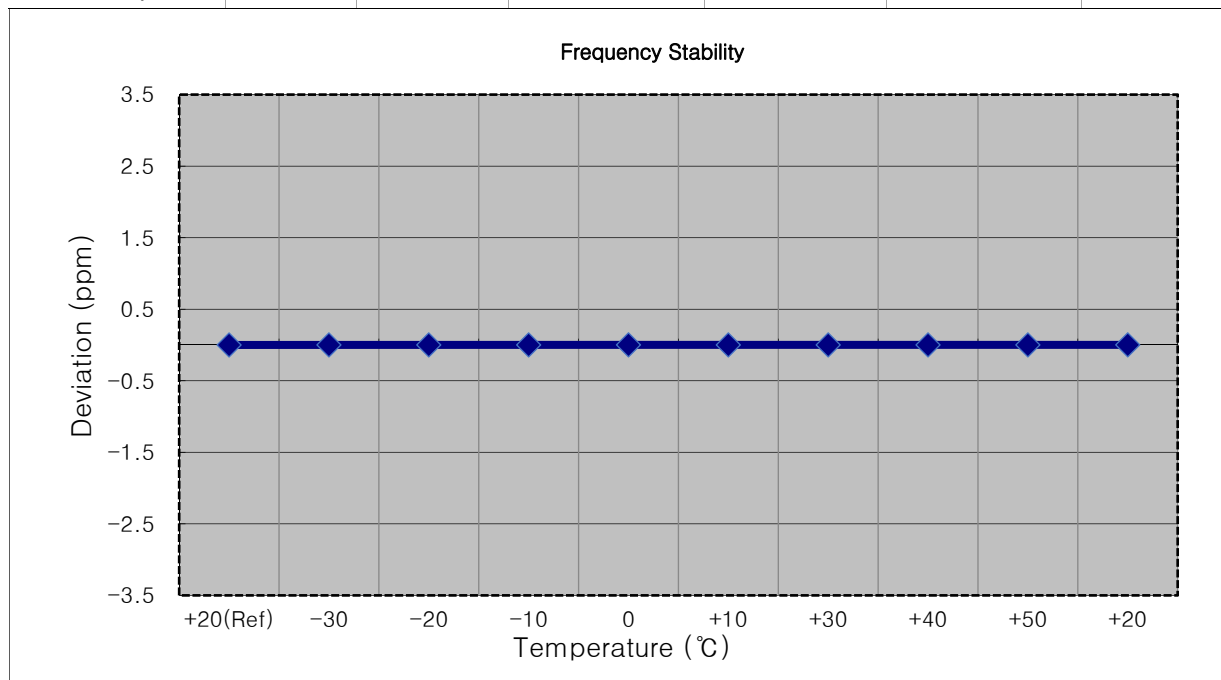
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1855,000,000 Hz
- ▣ CHANNEL: 26090 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1855 000 003	0.0	0.000 000	0.000
100 %		-30	1855 000 005	1.7	0.000 000	0.001
100 %		-20	1855 000 005	2.3	0.000 000	0.001
100 %		-10	1855 000 006	3.1	0.000 000	0.002
100 %		0	1855 000 006	3.3	0.000 000	0.002
100 %		+10	1855 000 006	3.3	0.000 000	0.002
100 %		+30	1855 000 005	1.6	0.000 000	0.001
100 %		+40	1855 000 006	2.5	0.000 000	0.001
100 %		+50	1855 000 007	3.6	0.000 000	0.002
Batt. Endpoint	3.300	+20	1855 000 005	2.2	0.000 000	0.001



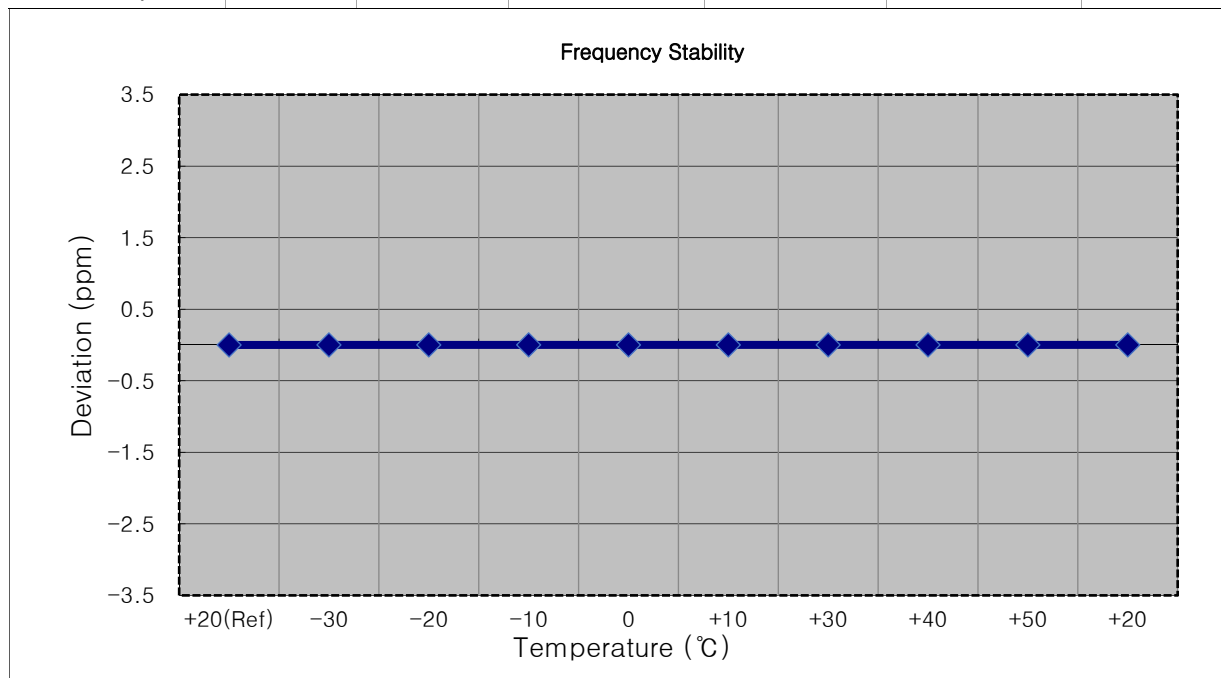
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1857,500,000 Hz
- ▣ CHANNEL: 26115 (15 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1857 500 002	0.0	0.000 000	0.000
100 %		-30	1857 500 004	1.9	0.000 000	0.001
100 %		-20	1857 500 005	2.3	0.000 000	0.001
100 %		-10	1857 500 005	2.3	0.000 000	0.001
100 %		0	1857 500 006	3.4	0.000 000	0.002
100 %		+10	1857 500 005	2.2	0.000 000	0.001
100 %		+30	1857 500 004	2.1	0.000 000	0.001
100 %		+40	1857 500 004	1.6	0.000 000	0.001
100 %		+50	1857 500 005	2.7	0.000 000	0.001
Batt. Endpoint	3.300	+20	1857 500 005	2.9	0.000 000	0.002



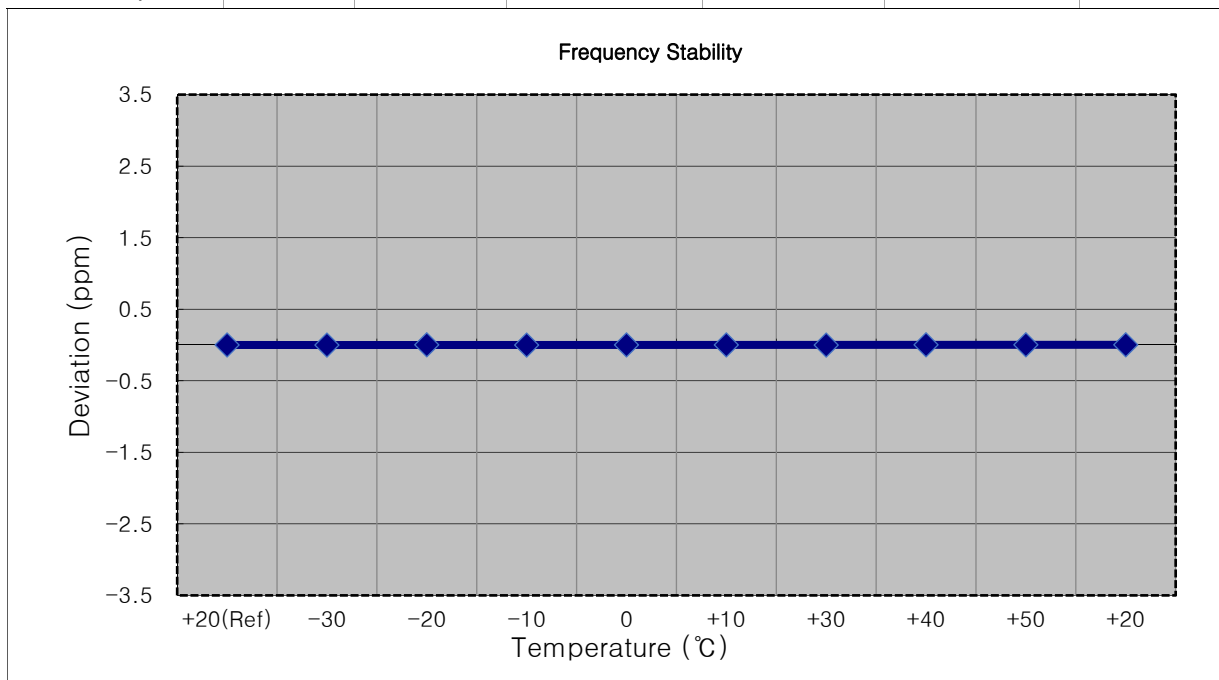
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1860,000,000 Hz
- ▣ CHANNEL: 26140 (20 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1860 000 002	0.0	0.000 000	0.000
100 %		-30	1860 000 004	1.7	0.000 000	0.001
100 %		-20	1860 000 004	1.7	0.000 000	0.001
100 %		-10	1860 000 006	3.3	0.000 000	0.002
100 %		0	1860 000 004	2.0	0.000 000	0.001
100 %		+10	1860 000 004	2.2	0.000 000	0.001
100 %		+30	1860 000 004	1.4	0.000 000	0.001
100 %		+40	1860 000 004	2.0	0.000 000	0.001
100 %		+50	1860 000 004	1.5	0.000 000	0.001
Batt. Endpoint	3.300	+20	1860 000 005	2.5	0.000 000	0.001



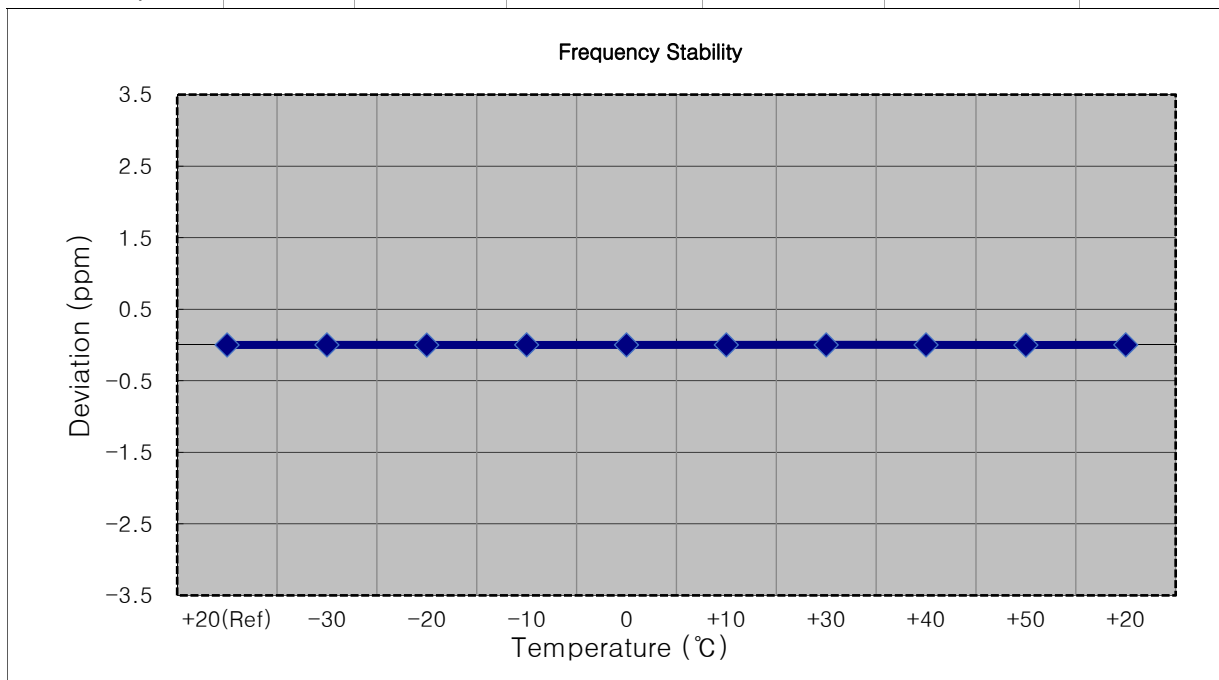
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 003	0.0	0.000 000	0.000
100 %		-30	1882 500 001	-2.1	0.000 000	-0.001
100 %		-20	1882 500 008	4.9	0.000 000	0.003
100 %		-10	1882 500 001	-2.3	0.000 000	-0.001
100 %		0	1882 500 005	2.1	0.000 000	0.001
100 %		+10	1882 500 005	1.9	0.000 000	0.001
100 %		+30	1882 500 002	-1.5	0.000 000	-0.001
100 %		+40	1882 500 008	4.3	0.000 000	0.002
100 %		+50	1882 500 008	4.2	0.000 000	0.002
Batt. Endpoint	3.300	+20	1882 500 008	4.4	0.000 000	0.002



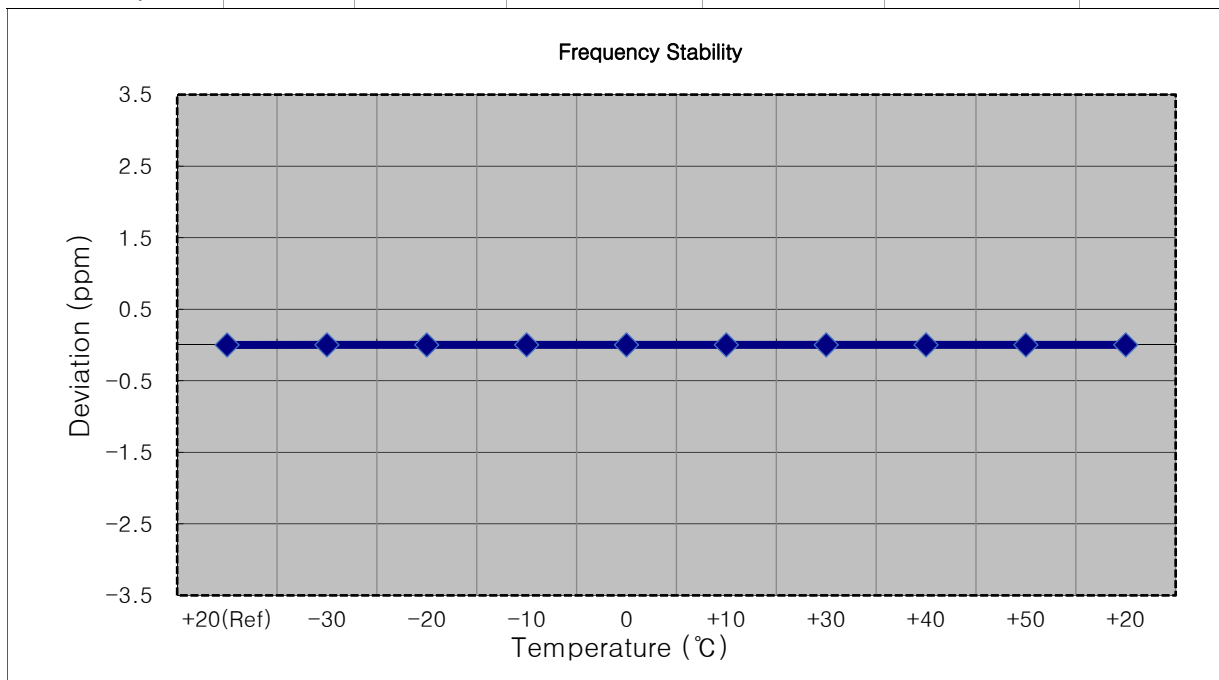
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 003	0.0	0.000 000	0.000
100 %		-30	1882 500 005	2.1	0.000 000	0.001
100 %		-20	1882 500 000	-2.6	0.000 000	-0.001
100 %		-10	1882 500 006	2.9	0.000 000	0.002
100 %		0	1882 500 004	1.5	0.000 000	0.001
100 %		+10	1882 500 005	2.4	0.000 000	0.001
100 %		+30	1882 500 005	2.3	0.000 000	0.001
100 %		+40	1882 500 005	2.6	0.000 000	0.001
100 %		+50	1882 500 001	-1.6	0.000 000	-0.001
Batt. Endpoint	3.300	+20	1882 500 006	3.3	0.000 000	0.002



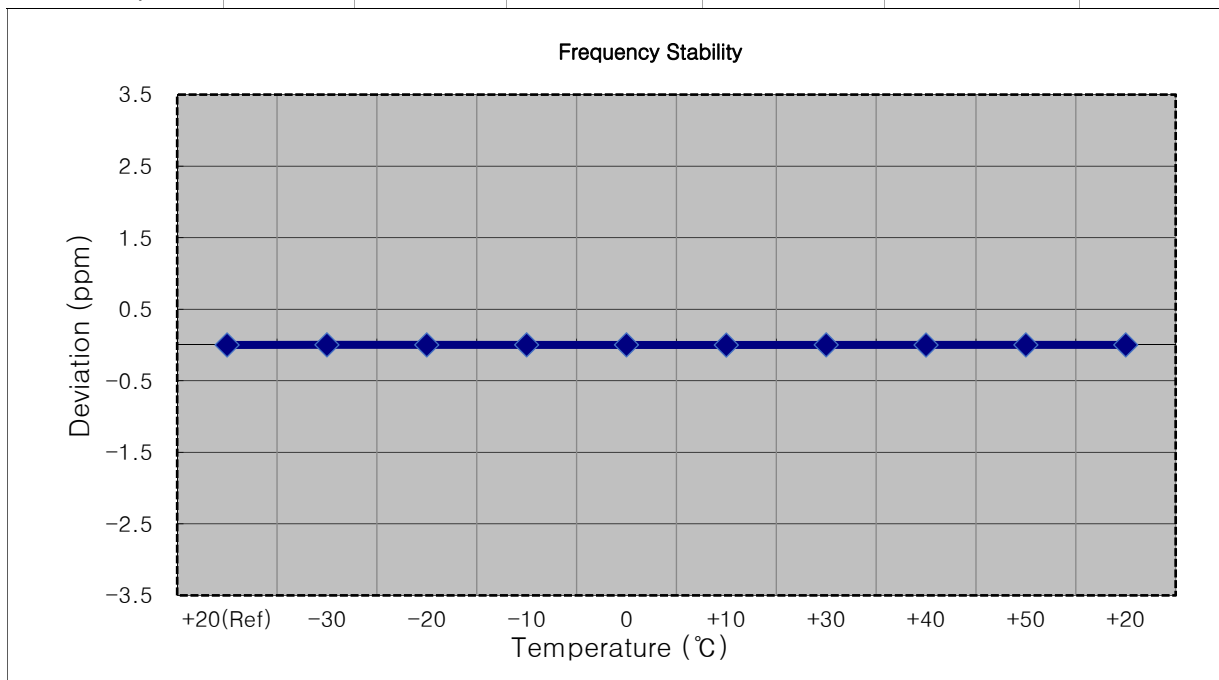
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 003	0.0	0.000 000	0.000
100 %		-30	1882 500 006	3.3	0.000 000	0.002
100 %		-20	1882 500 005	2.4	0.000 000	0.001
100 %		-10	1882 500 006	3.0	0.000 000	0.002
100 %		0	1882 500 006	3.3	0.000 000	0.002
100 %		+10	1882 500 006	3.3	0.000 000	0.002
100 %		+30	1882 500 006	3.2	0.000 000	0.002
100 %		+40	1882 500 006	2.8	0.000 000	0.001
100 %		+50	1882 500 006	3.2	0.000 000	0.002
Batt. Endpoint	3.300	+20	1882 500 007	4.0	0.000 000	0.002



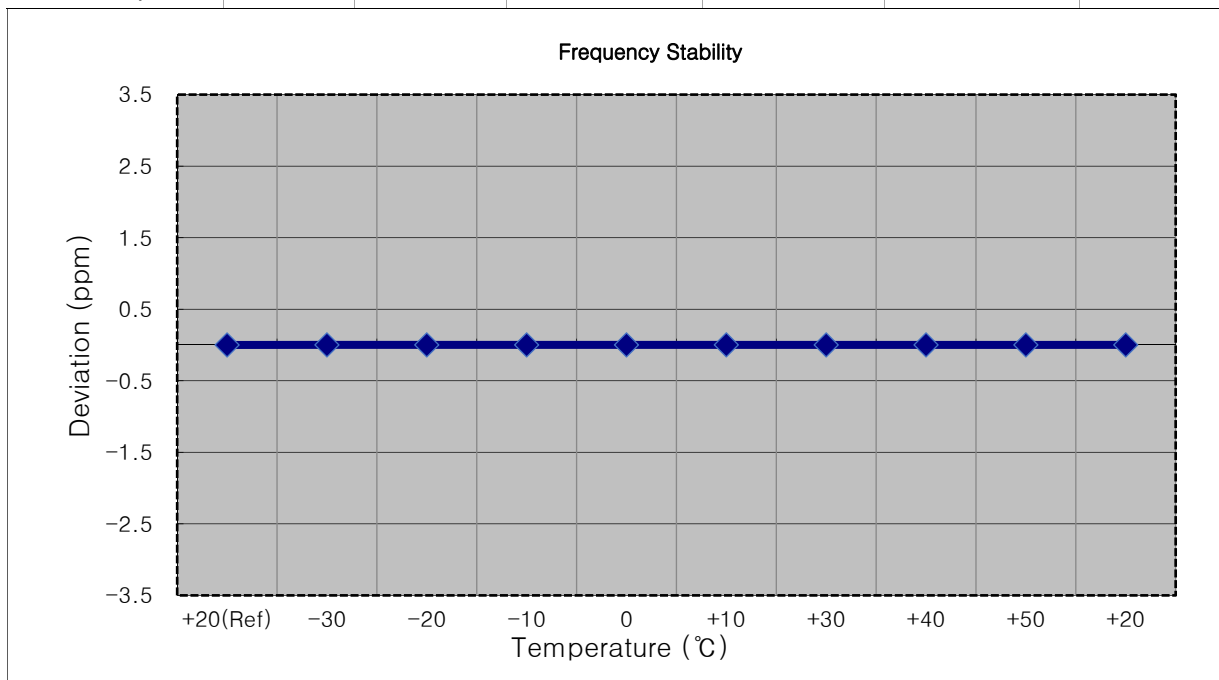
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 002	0.0	0.000 000	0.000
100 %		-30	1882 500 006	3.8	0.000 000	0.002
100 %		-20	1882 500 004	2.3	0.000 000	0.001
100 %		-10	1882 500 005	3.0	0.000 000	0.002
100 %		0	1882 500 005	3.4	0.000 000	0.002
100 %		+10	1882 500 000	-2.2	0.000 000	-0.001
100 %		+30	1882 500 006	4.0	0.000 000	0.002
100 %		+40	1882 500 001	-1.4	0.000 000	-0.001
100 %		+50	1882 500 004	2.4	0.000 000	0.001
Batt. Endpoint	3.300	+20	1882 500 005	2.6	0.000 000	0.001



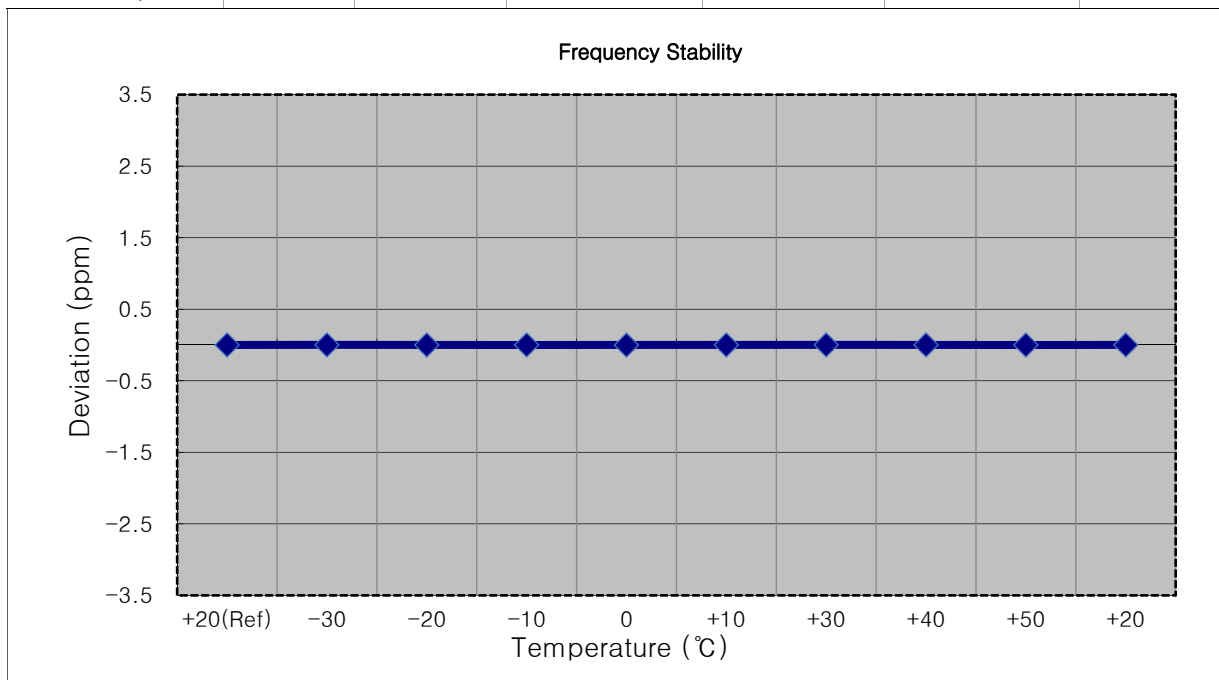
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (15 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 002	0.0	0.000 000	0.000
100 %		-30	1882 500 005	2.7	0.000 000	0.001
100 %		-20	1882 500 004	2.4	0.000 000	0.001
100 %		-10	1882 500 005	2.7	0.000 000	0.001
100 %		0	1882 500 004	1.6	0.000 000	0.001
100 %		+10	1882 500 005	2.8	0.000 000	0.001
100 %		+30	1882 500 004	1.5	0.000 000	0.001
100 %		+40	1882 500 004	2.2	0.000 000	0.001
100 %		+50	1882 500 003	1.4	0.000 000	0.001
Batt. Endpoint	3.300	+20	1882 500 005	2.7	0.000 000	0.001



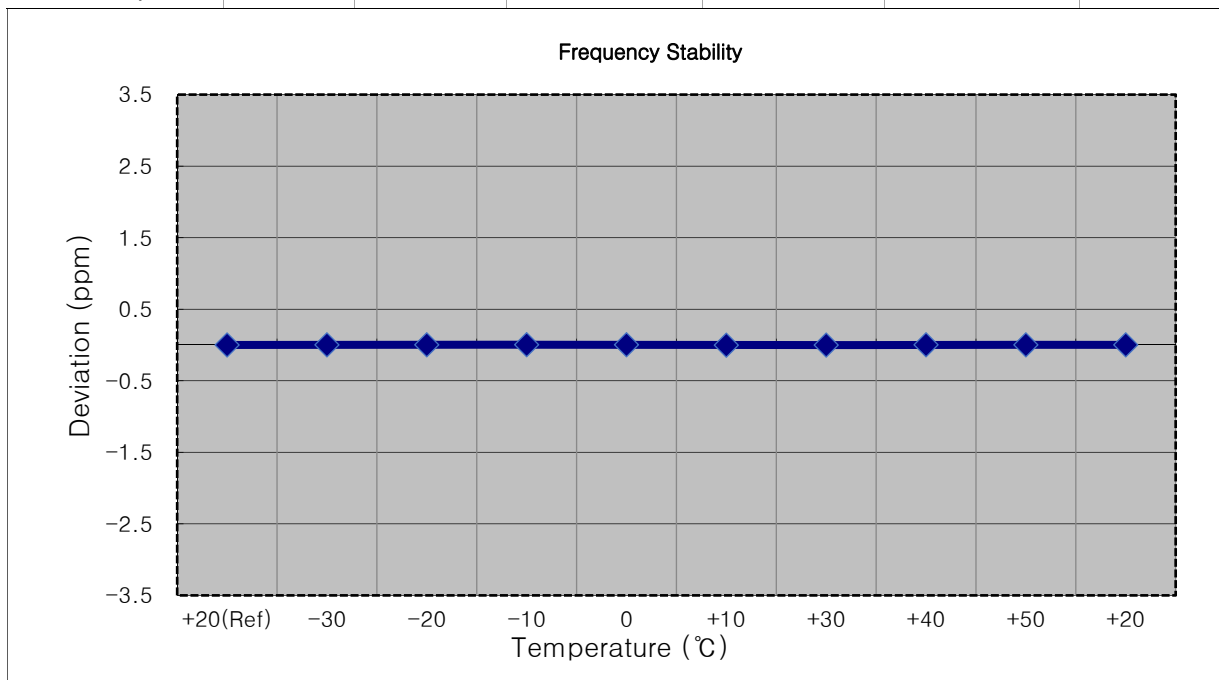
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1882,500,000 Hz
- ▣ CHANNEL: 26365 (20 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1882 500 001	0.0	0.000 000	0.000
100 %		-30	1882 500 003	2.1	0.000 000	0.001
100 %		-20	1882 500 003	1.2	0.000 000	0.001
100 %		-10	1882 500 004	2.2	0.000 000	0.001
100 %		0	1882 499 999	-2.3	0.000 000	-0.001
100 %		+10	1882 500 003	1.5	0.000 000	0.001
100 %		+30	1882 500 004	2.8	0.000 000	0.001
100 %		+40	1882 500 004	2.2	0.000 000	0.001
100 %		+50	1882 500 000	-1.1	0.000 000	-0.001
Batt. Endpoint	3.300	+20	1882 500 003	1.7	0.000 000	0.001



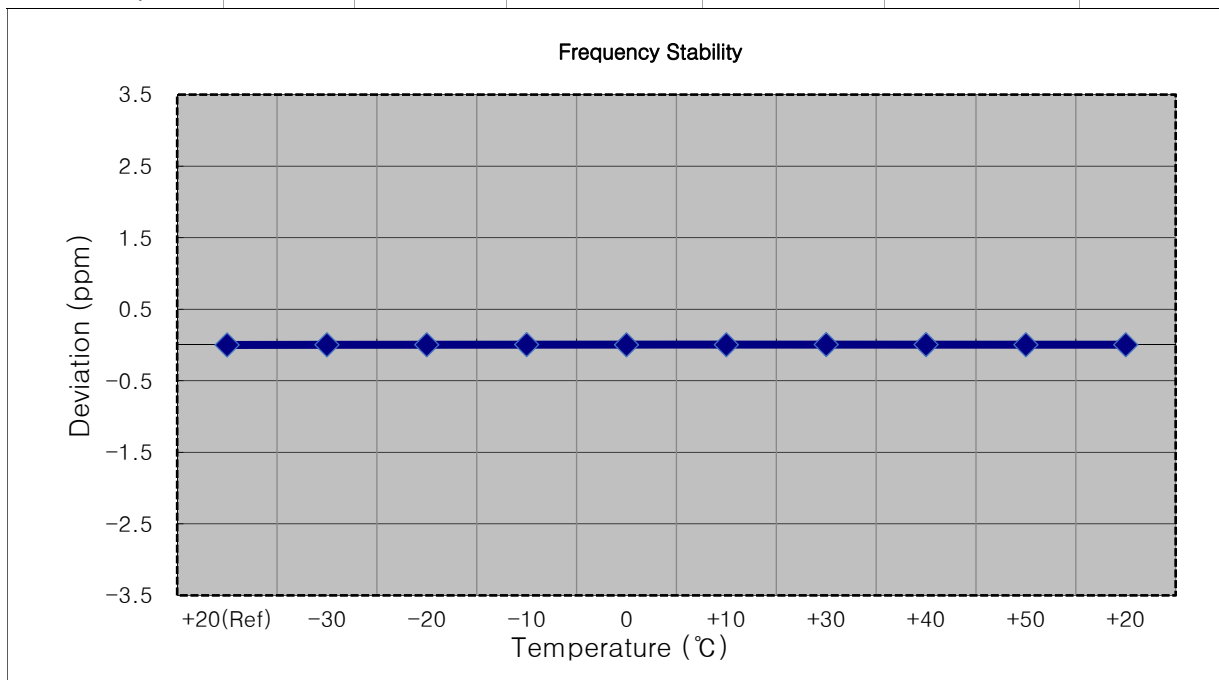
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1914,300,000 Hz
- ▣ CHANNEL: 26683 (1.4 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1914 300 006	0.0	0.000 000	0.000
100 %		-30	1914 300 009	3.2	0.000 000	0.002
100 %		-20	1914 300 011	4.6	0.000 000	0.002
100 %		-10	1914 300 014	8.1	0.000 000	0.004
100 %		0	1914 300 013	6.7	0.000 000	0.003
100 %		+10	1914 300 001	-5.1	0.000 000	-0.003
100 %		+30	1914 300 004	-2.3	0.000 000	-0.001
100 %		+40	1914 300 011	4.7	0.000 000	0.002
100 %		+50	1914 300 010	3.9	0.000 000	0.002
Batt. Endpoint	3.300	+20	1914 300 009	3.3	0.000 000	0.002



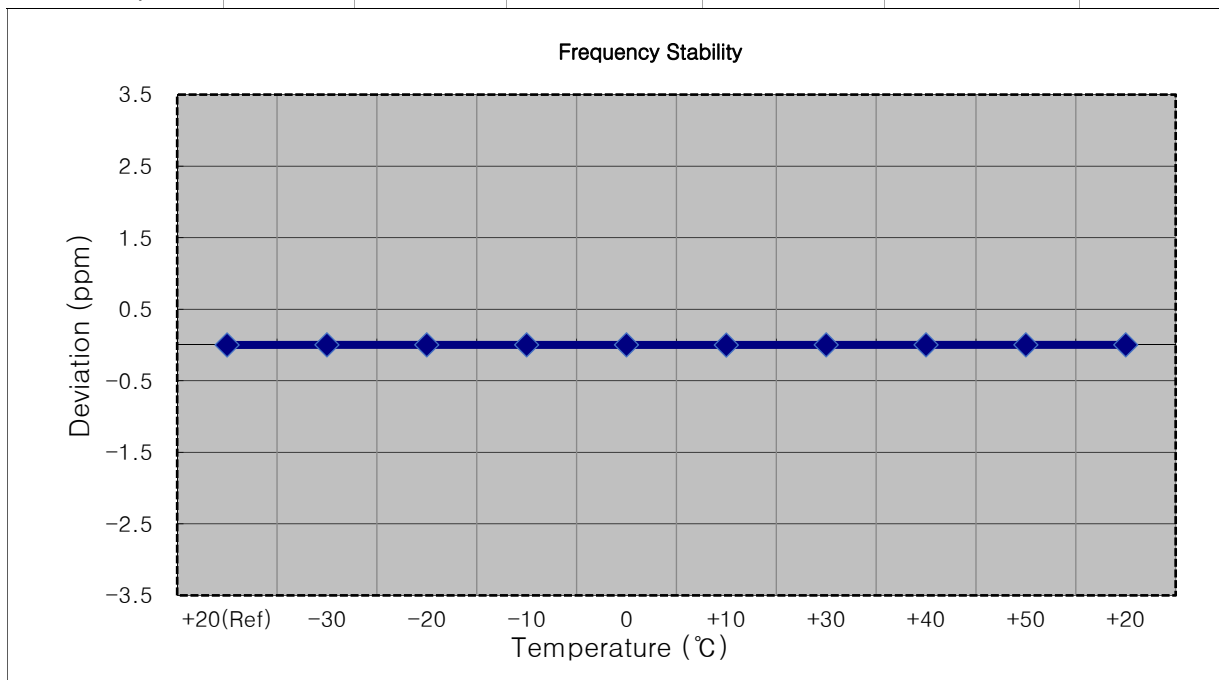
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1913,500,000 Hz
- ▣ CHANNEL: 26675 (3 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1913 500 004	0.0	0.000 000	0.000
100 %		-30	1913 500 009	4.9	0.000 000	0.003
100 %		-20	1913 500 010	6.0	0.000 000	0.003
100 %		-10	1913 500 015	11.3	0.000 001	0.006
100 %		0	1913 500 009	5.3	0.000 000	0.003
100 %		+10	1913 500 010	6.4	0.000 000	0.003
100 %		+30	1913 500 015	11.4	0.000 001	0.006
100 %		+40	1913 500 014	10.2	0.000 001	0.005
100 %		+50	1913 500 010	6.7	0.000 000	0.004
Batt. Endpoint	3.300	+20	1913 500 010	6.8	0.000 000	0.004



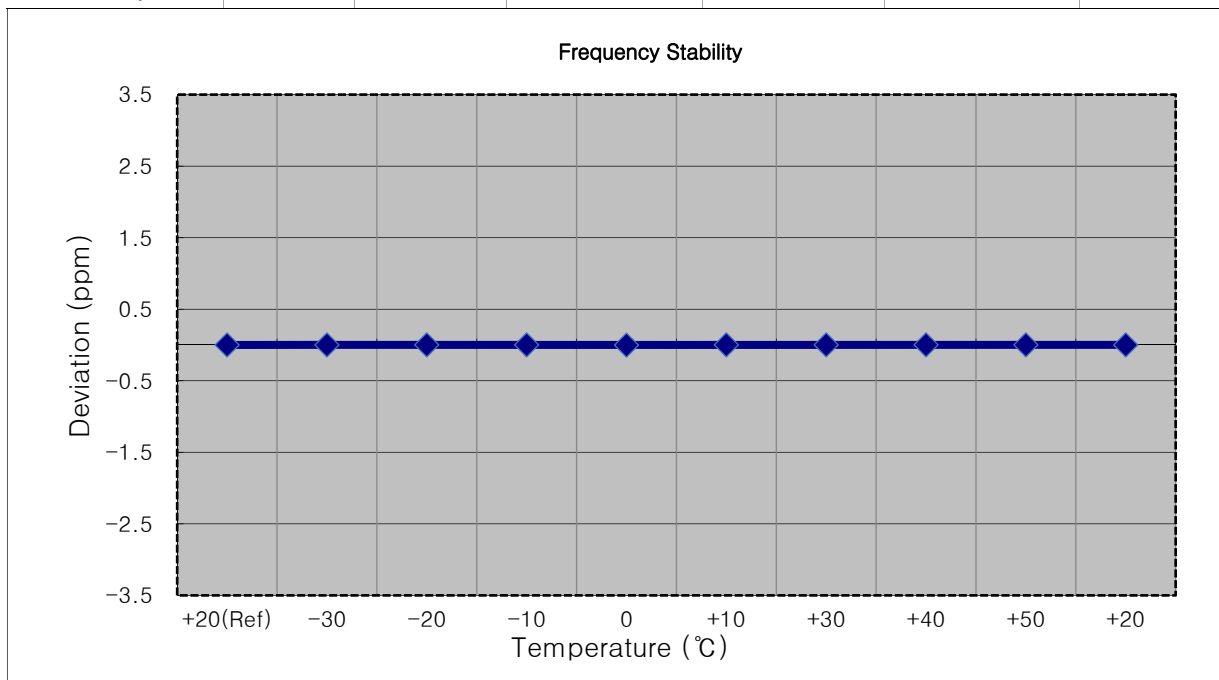
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1912,500,000 Hz
- ▣ CHANNEL: 26665 (5 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1912 500 004	0.0	0.000 000	0.000
100 %		-30	1912 500 008	3.3	0.000 000	0.002
100 %		-20	1912 500 008	3.5	0.000 000	0.002
100 %		-10	1912 500 008	4.0	0.000 000	0.002
100 %		0	1912 500 008	3.5	0.000 000	0.002
100 %		+10	1912 500 002	-2.7	0.000 000	-0.001
100 %		+30	1912 500 007	2.9	0.000 000	0.002
100 %		+40	1912 500 008	3.2	0.000 000	0.002
100 %		+50	1912 500 008	3.5	0.000 000	0.002
Batt. Endpoint	3.300	+20	1912 500 008	3.4	0.000 000	0.002



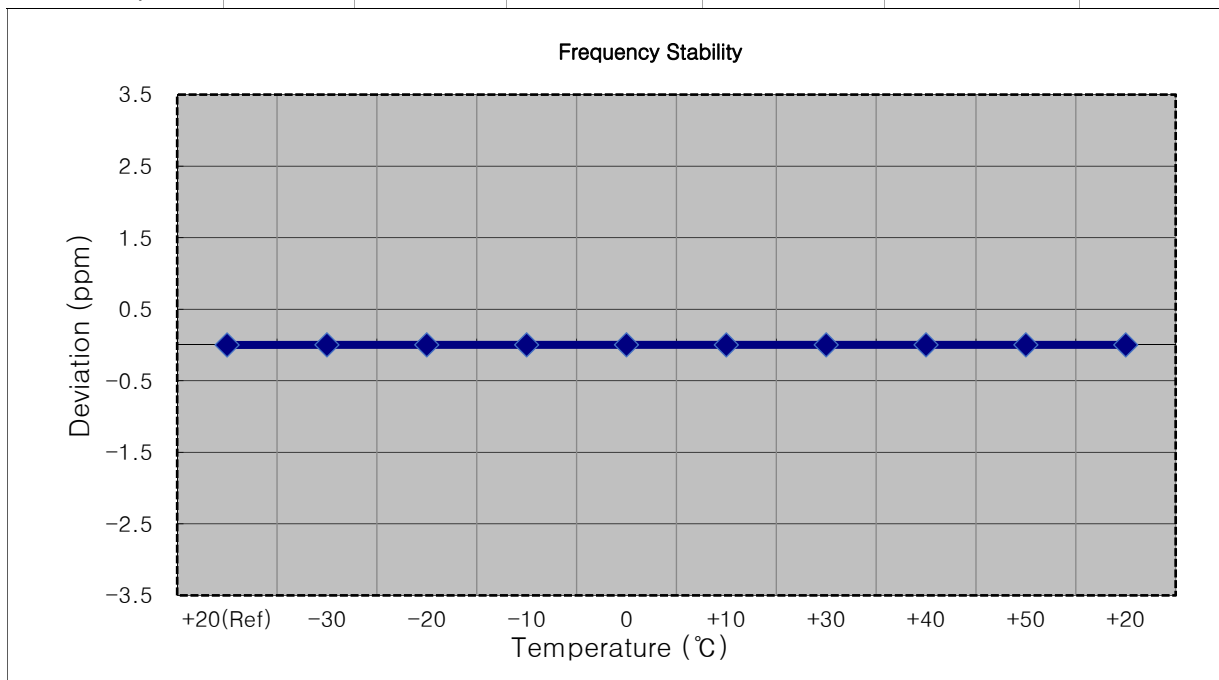
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1910,000,000 Hz
- ▣ CHANNEL: 26640 (10 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1910 000 003	0.0	0.000 000	0.000
100 %		-30	1910 000 006	2.5	0.000 000	0.001
100 %		-20	1910 000 006	3.0	0.000 000	0.002
100 %		-10	1910 000 007	3.5	0.000 000	0.002
100 %		0	1910 000 001	-2.9	0.000 000	-0.002
100 %		+10	1910 000 007	3.2	0.000 000	0.002
100 %		+30	1910 000 006	2.9	0.000 000	0.002
100 %		+40	1910 000 007	3.8	0.000 000	0.002
100 %		+50	1910 000 007	3.5	0.000 000	0.002
Batt. Endpoint	3.300	+20	1910 000 006	2.7	0.000 000	0.001



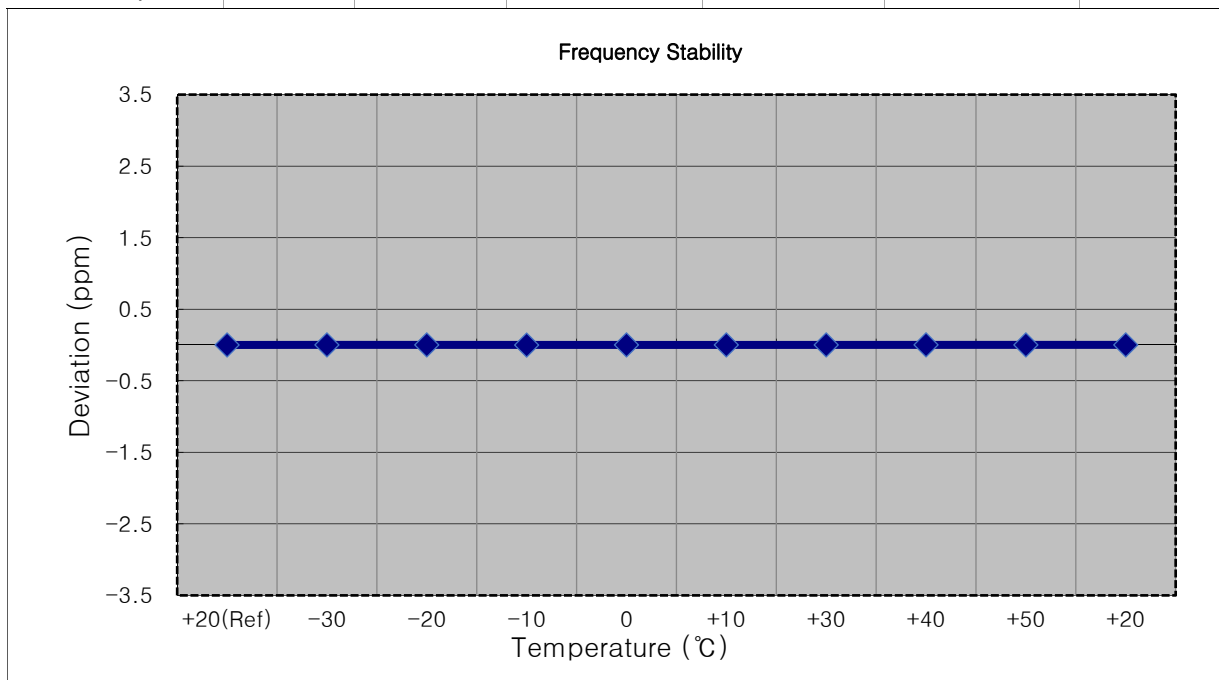
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1907,500,000 Hz
- ▣ CHANNEL: 26615 (15 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1907 500 003	0.0	0.000 000	0.000
100 %		-30	1907 500 006	3.0	0.000 000	0.002
100 %		-20	1907 500 007	3.5	0.000 000	0.002
100 %		-10	1907 500 007	3.3	0.000 000	0.002
100 %		0	1907 500 008	4.4	0.000 000	0.002
100 %		+10	1907 500 006	2.5	0.000 000	0.001
100 %		+30	1907 500 007	3.3	0.000 000	0.002
100 %		+40	1907 500 006	3.2	0.000 000	0.002
100 %		+50	1907 500 006	3.2	0.000 000	0.002
Batt. Endpoint	3.300	+20	1907 500 005	2.1	0.000 000	0.001



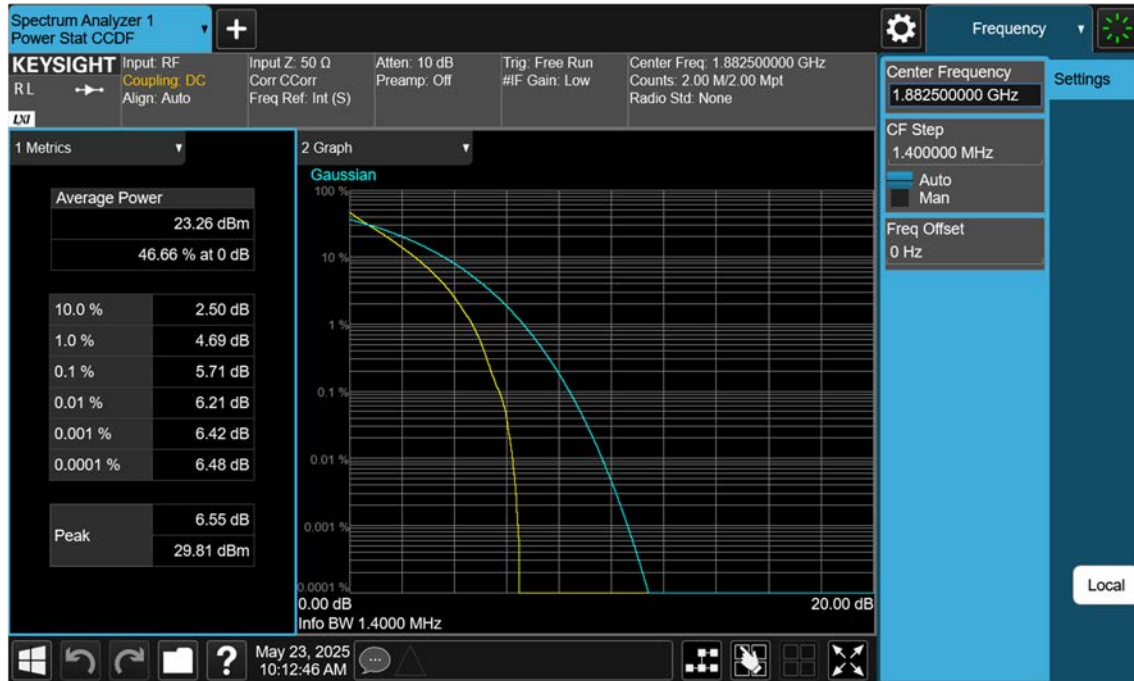
- ▣ MODE: LTE B25/B2
- ▣ OPERATING FREQUENCY: 1905,000,000 Hz
- ▣ CHANNEL: 26590 (20 MHz)
- ▣ REFERENCE VOLTAGE: 3.880 VDC
- ▣ DEVIATION LIMIT: Emission must remain in band

Voltage (%)	Power (VDC)	Temp. (°C)	Frequency (Hz)	Frequency Error (Hz)	Deviation (%)	ppm
100 %	3.880	+20(Ref)	1904 999 998	0.0	0.000 000	0.000
100 %		-30	1905 000 000	2.1	0.000 000	0.001
100 %		-20	1905 000 000	2.1	0.000 000	0.001
100 %		-10	1904 999 996	-2.1	0.000 000	-0.001
100 %		0	1905 000 000	2.2	0.000 000	0.001
100 %		+10	1905 000 001	2.5	0.000 000	0.001
100 %		+30	1905 000 000	1.7	0.000 000	0.001
100 %		+40	1905 000 001	3.0	0.000 000	0.002
100 %		+50	1905 000 000	2.1	0.000 000	0.001
Batt. Endpoint	3.300	+20	1905 000 001	2.5	0.000 000	0.001



10. TEST PLOTS(Main 1 ANT)

LTE B25_1.4M_PAR_Mid_QPSK_FullRB



LTE B25_1.4M_PAR_Mid_16QAM_FullRB



LTE B25_1.4M_PAR_Mid_64QAM_FullRB



LTE B25_1.4M_PAR_Mid_256QAM_FullRB



LTE B25_3 M_PAR_Mid_QPSK_FullRB



LTE B25_3 M_PAR_Mid_16QAM_FullRB



LTE B25_3 M_PAR_Mid_64QAM_FullRB



LTE B25_3 M_PAR_Mid_256QAM_FullRB



LTE B25_5 M_PAR_Mid_QPSK_FullRB



LTE B25_5 M_PAR_Mid_16QAM_FullRB



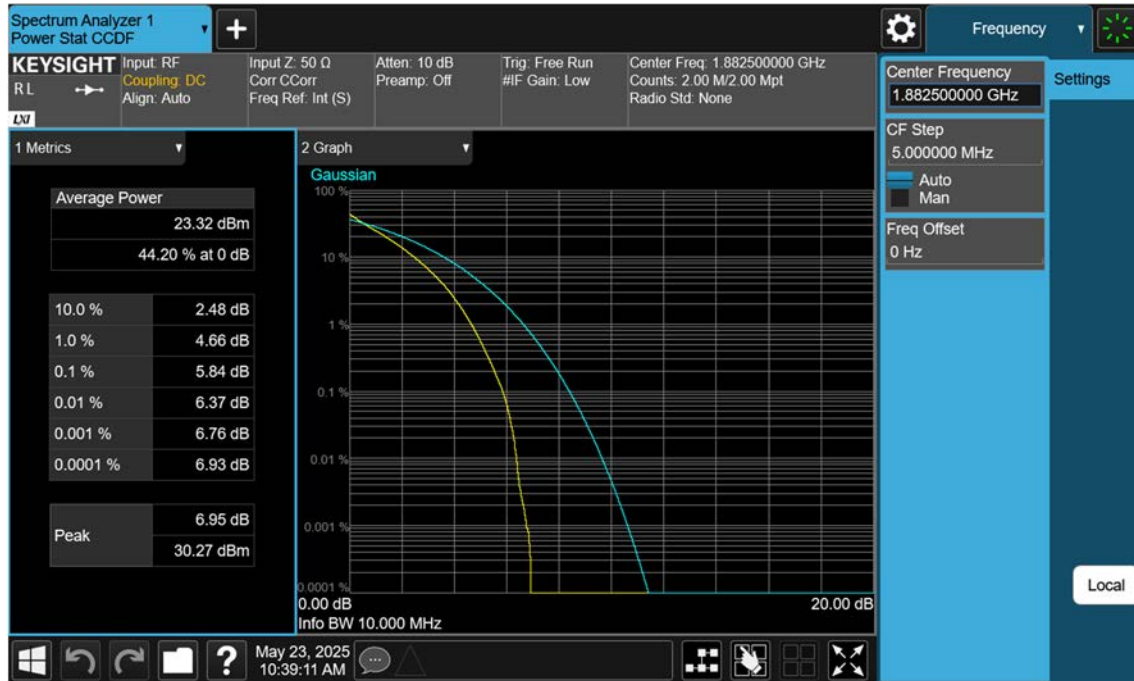
LTE B25_5 M_PAR_Mid_64QAM_FullRB



LTE B25_5 M_PAR_Mid_256QAM_FullRB



LTE B25_10 M_PAR_Mid_QPSK_FullRB



LTE B25_10 M_PAR_Mid_16QAM_FullRB



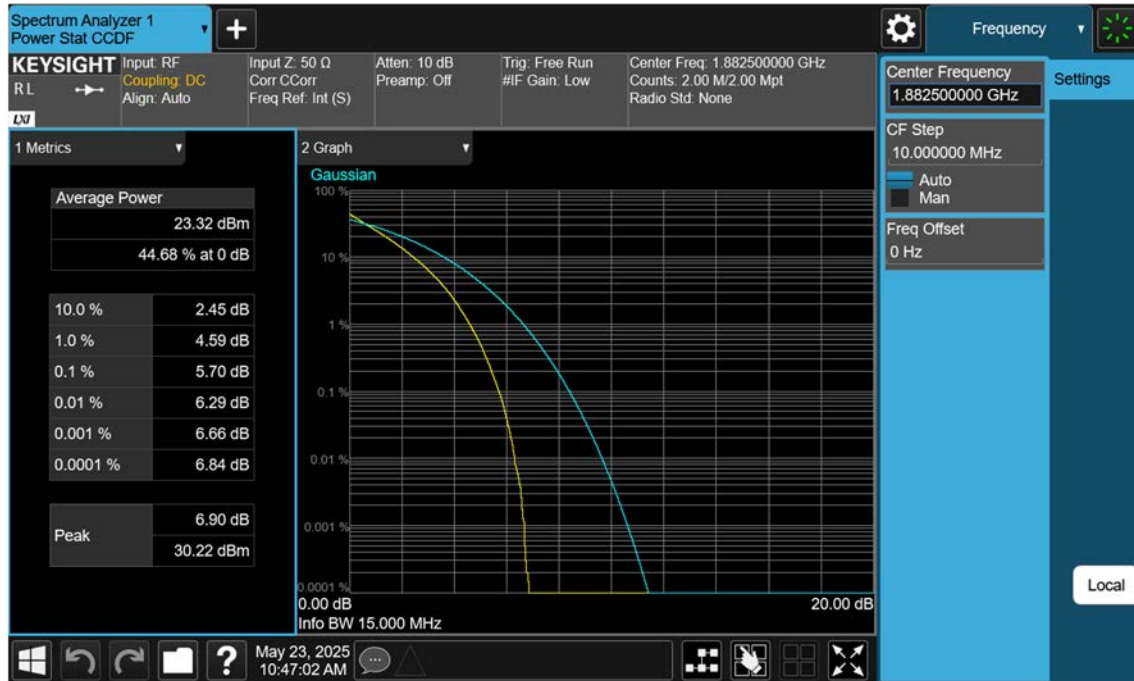
LTE B25_10 M_PAR_Mid_64QAM_FullRB



LTE B25_10 M_PAR_Mid_256QAM_FullRB



LTE B25_15 M_PAR_Mid_QPSK_FullRB



LTE B25_15 M_PAR_Mid_16QAM_FullRB



LTE B25_15 M_PAR_Mid_64QAM_FullRB



LTE B25_15 M_PAR_Mid_256QAM_FullRB



LTE B25_20 M_PAR_Mid_QPSK_FullRB



LTE B25_20 M_PAR_Mid_16QAM_FullRB



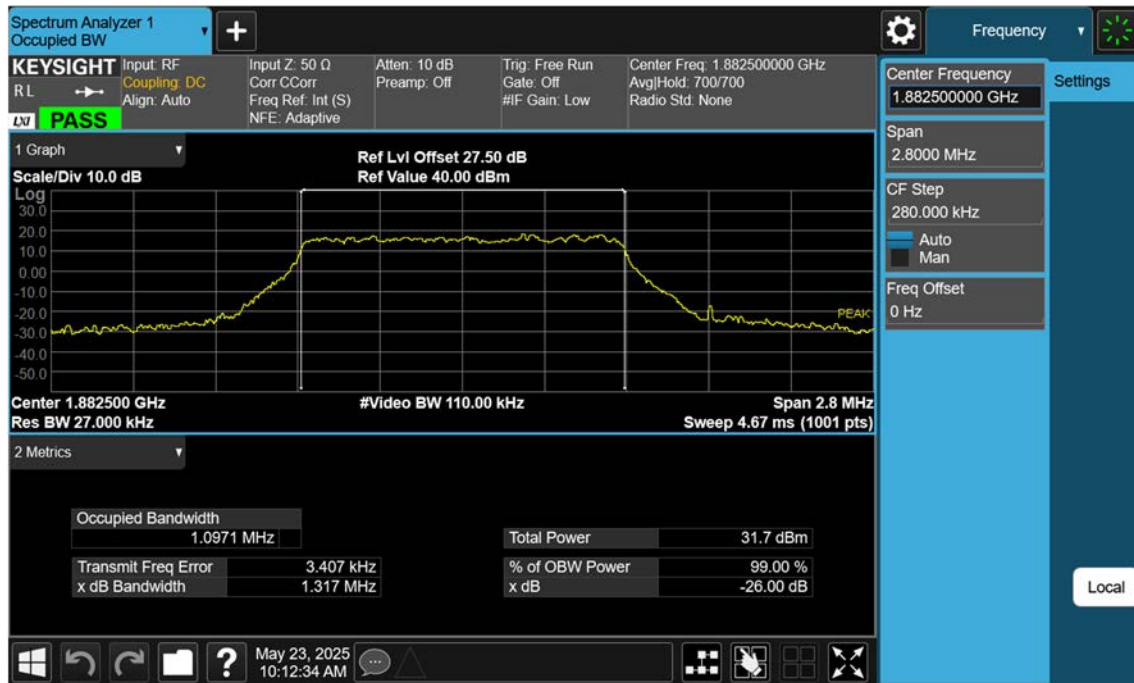
LTE B25_20 M_PAR_Mid_64QAM_FullRB



LTE B25_20 M_PAR_Mid_256QAM_FullRB



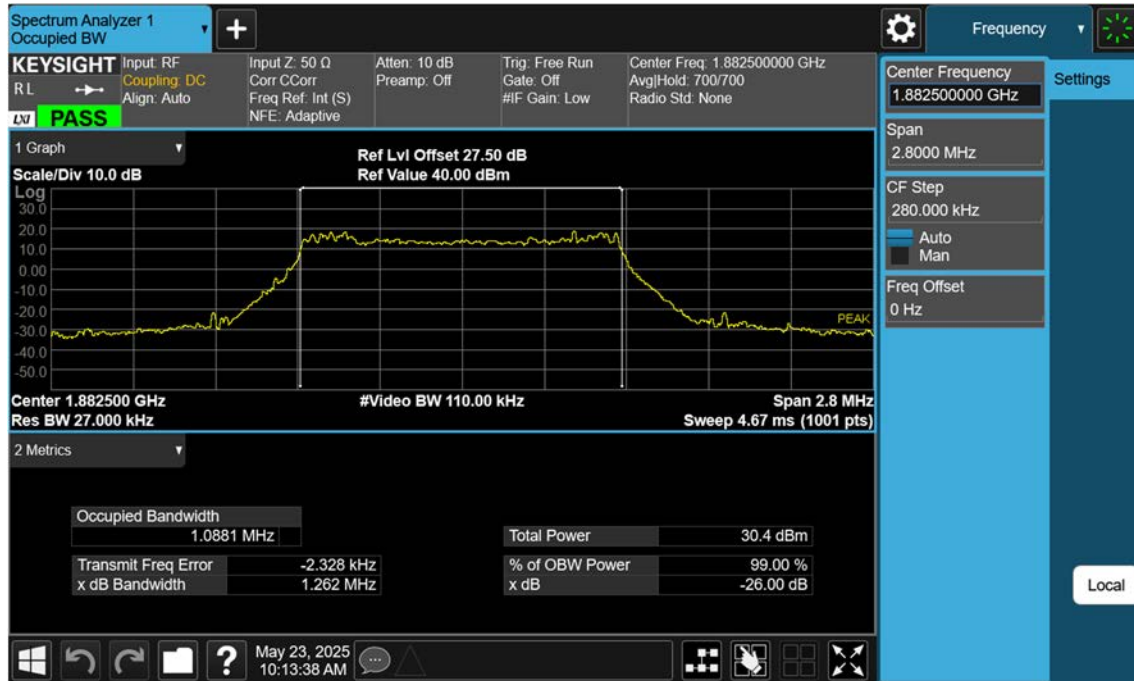
LTE B25_1.4M_OBW_Mid_QPSK_FullRB



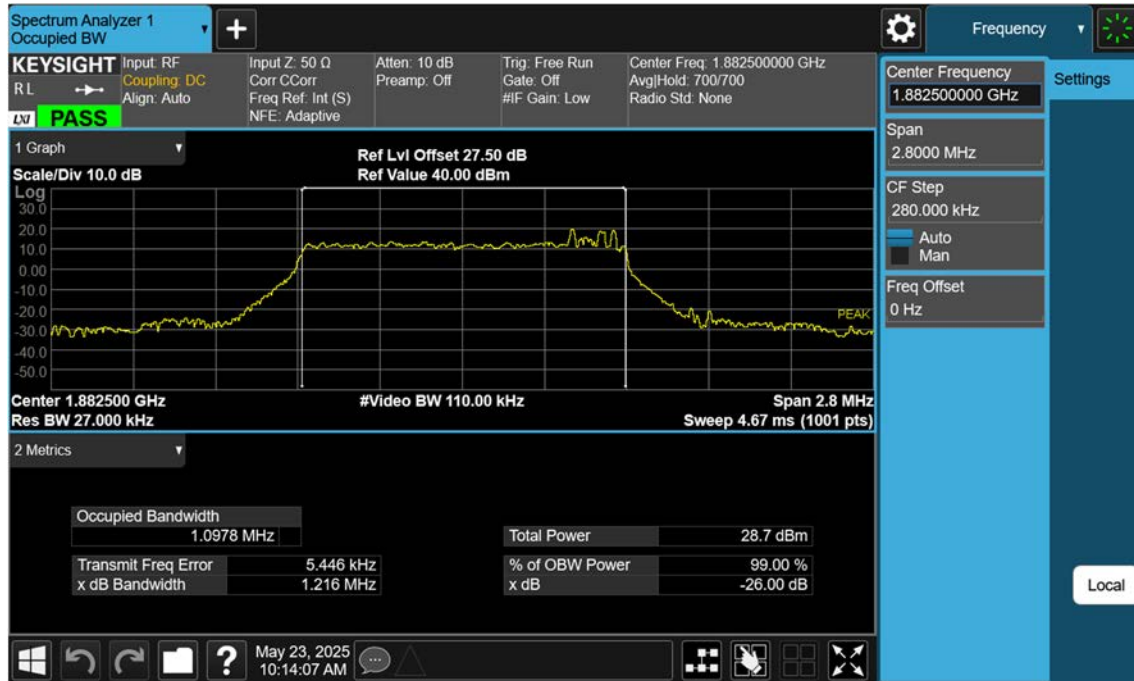
LTE B25_1.4M_OBW_Mid_16QAM_FullRB



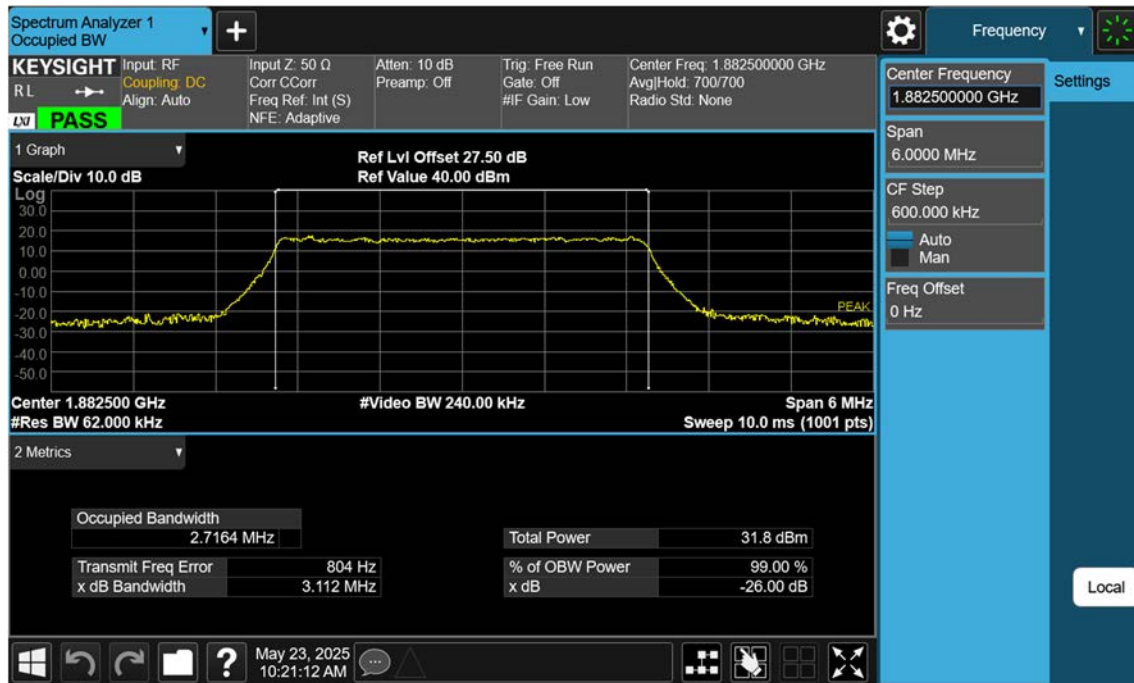
LTE B25_1.4M_OBW_Mid_64QAM_FullRB



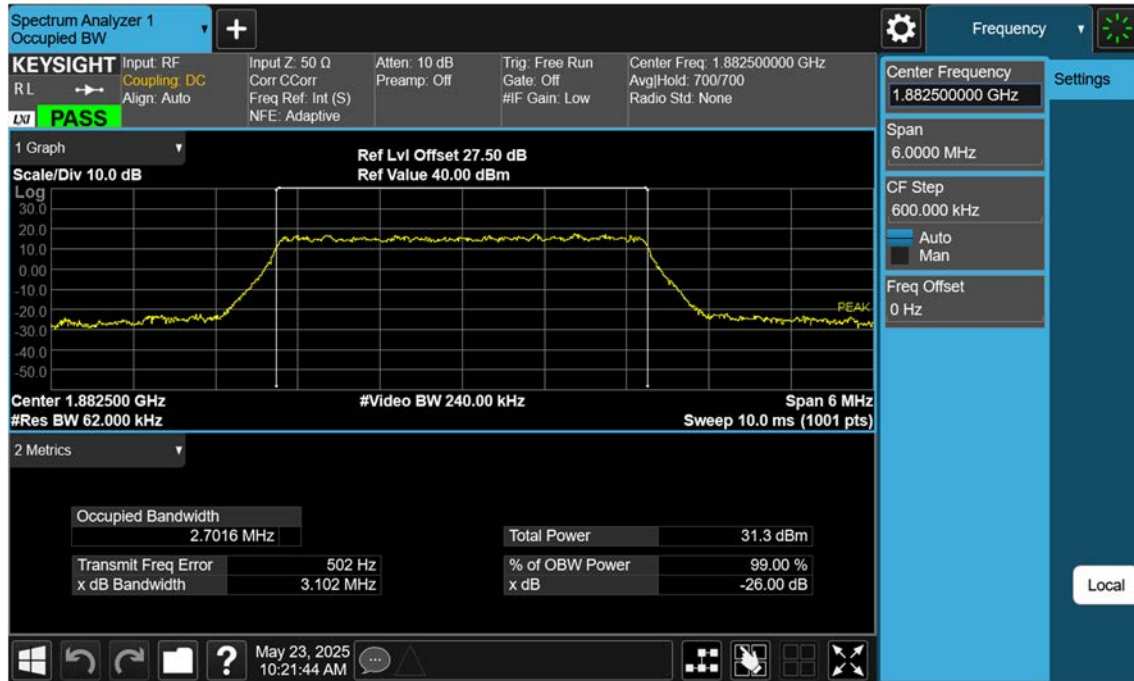
LTE B25_1.4M_OBW_Mid_256QAM_FullRB



LTE B25_3 M_OBW_Mid_QPSK_FullRB



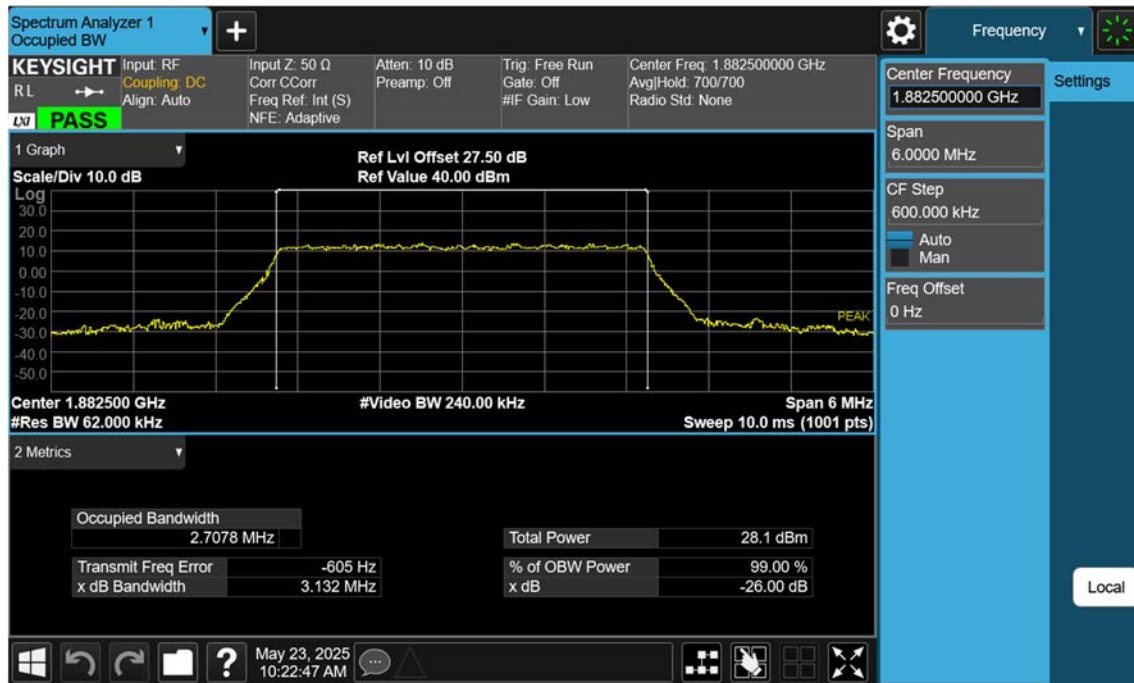
LTE B25_3 M_OBW_Mid_16QAM_FullRB



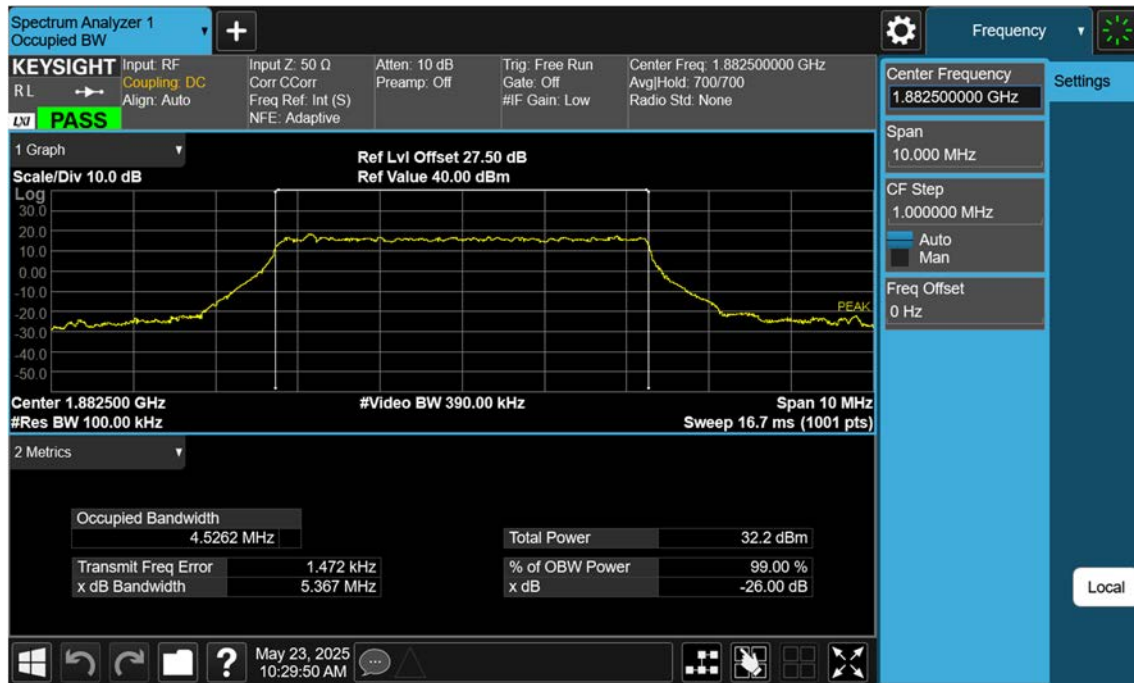
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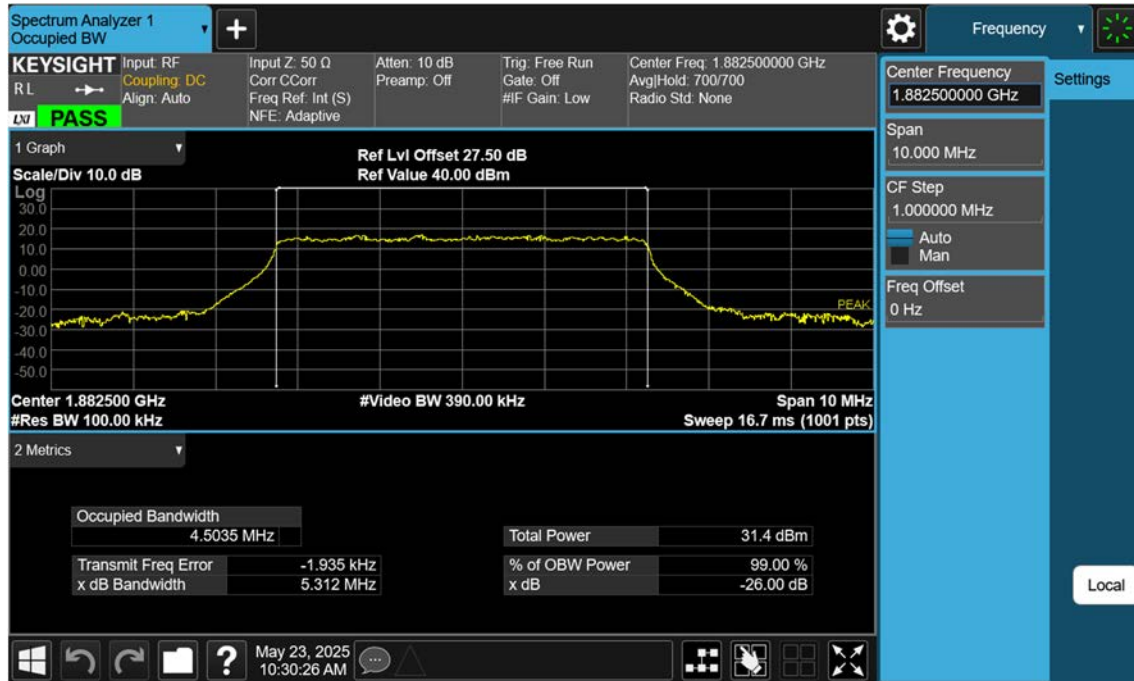
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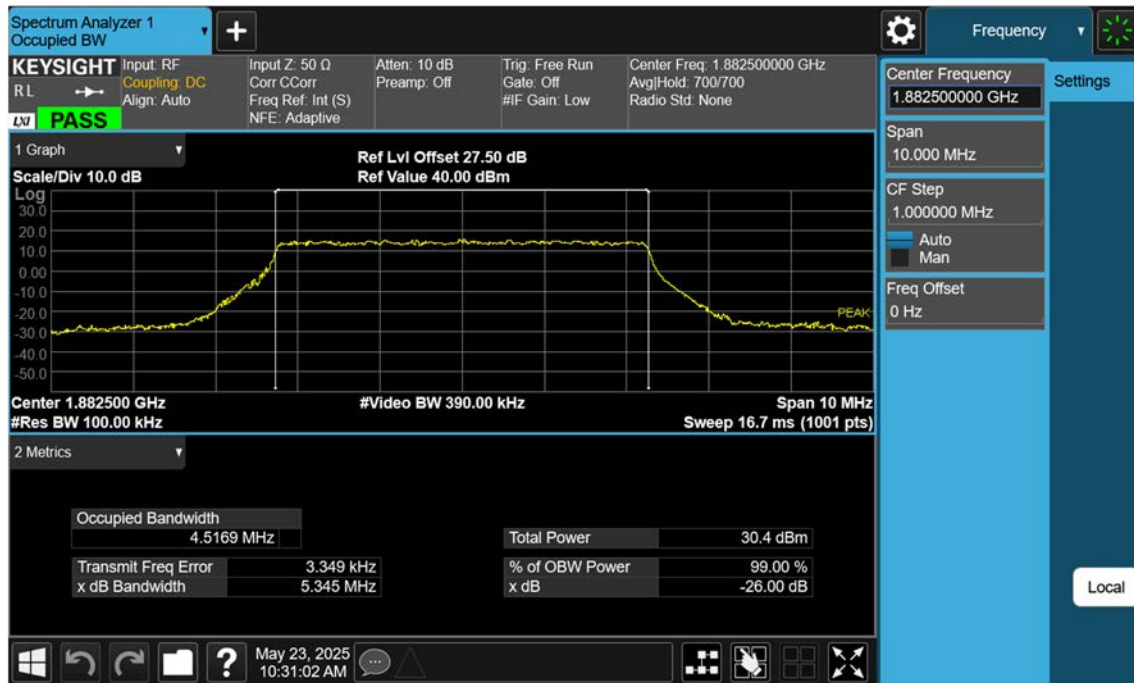
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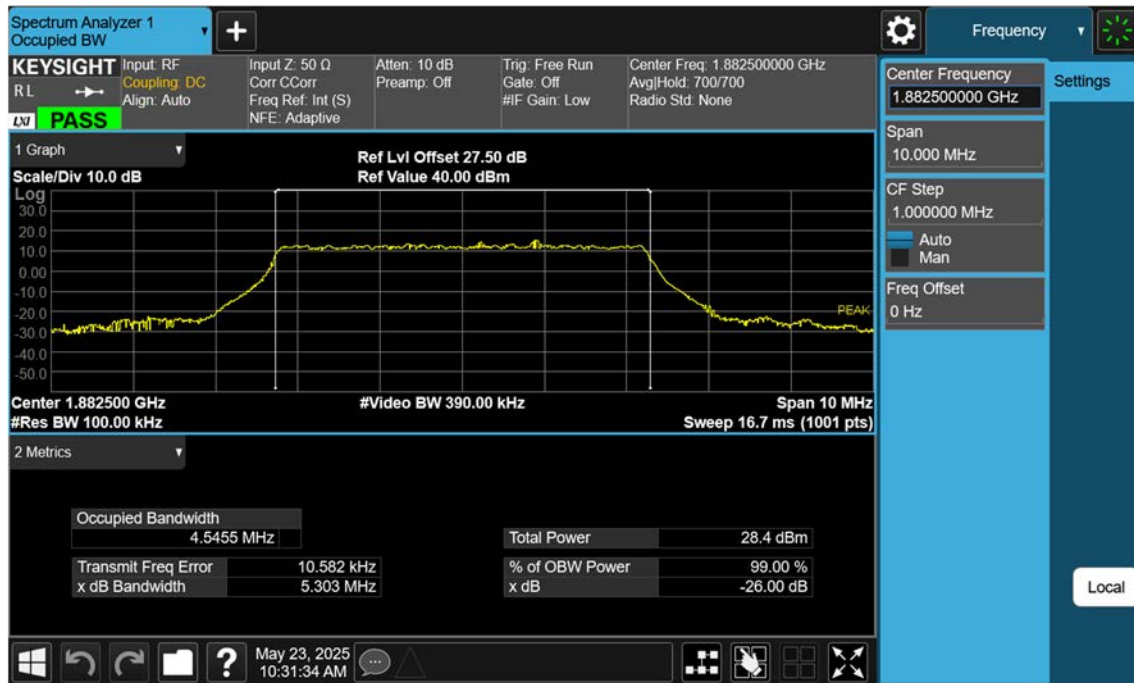
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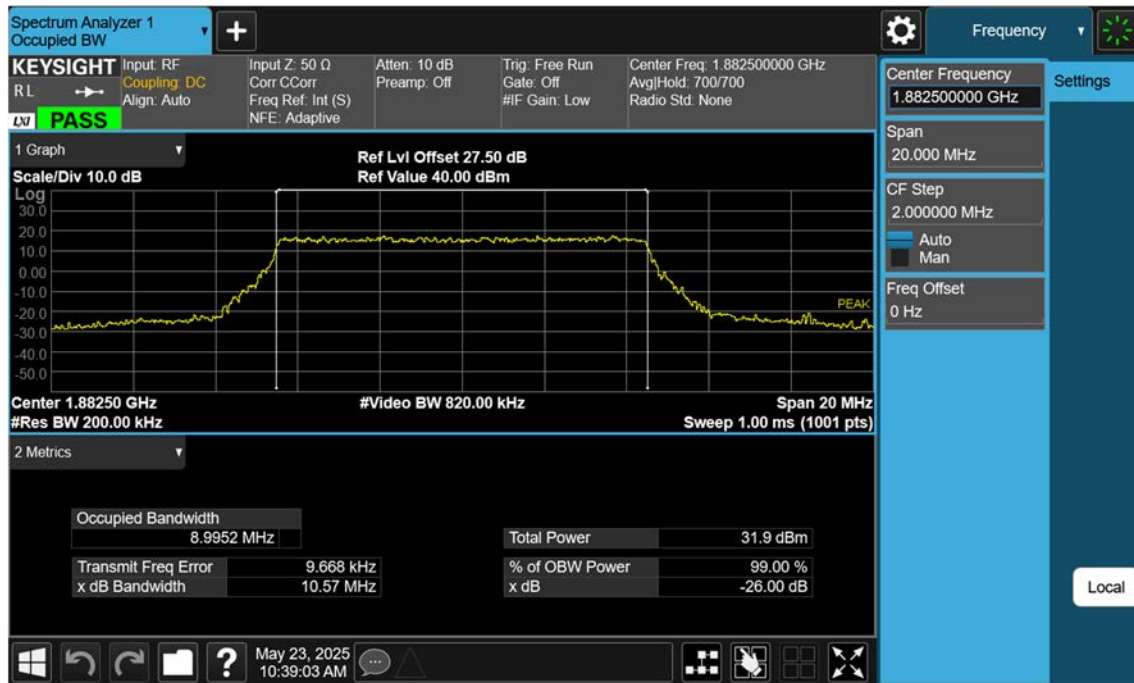
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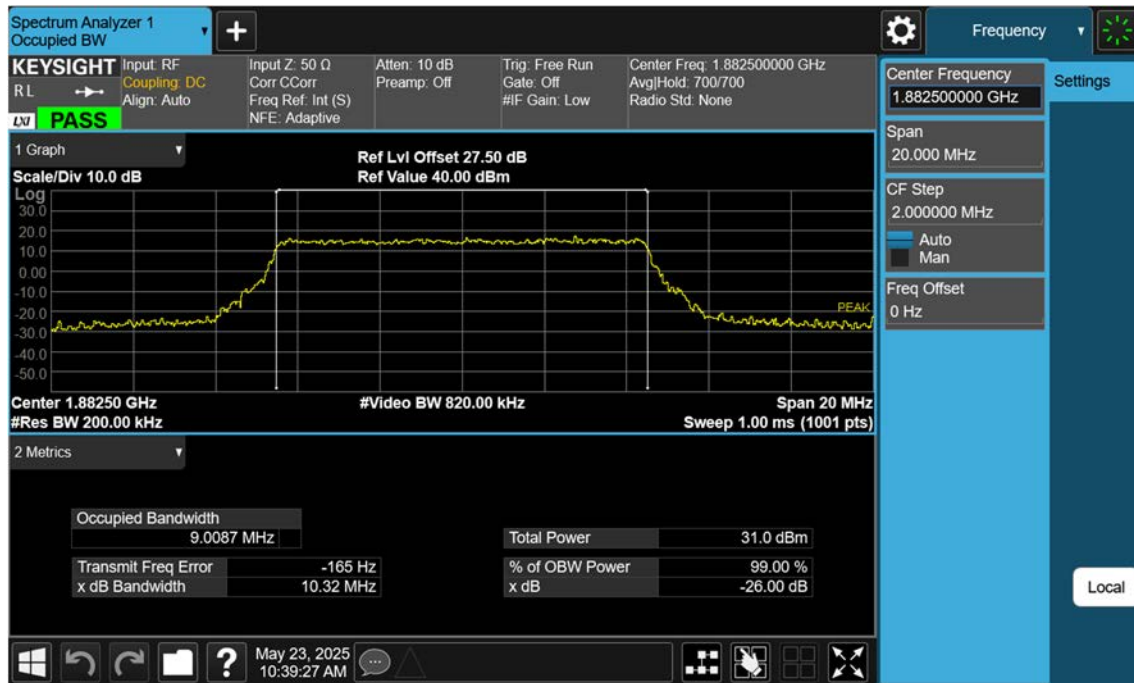
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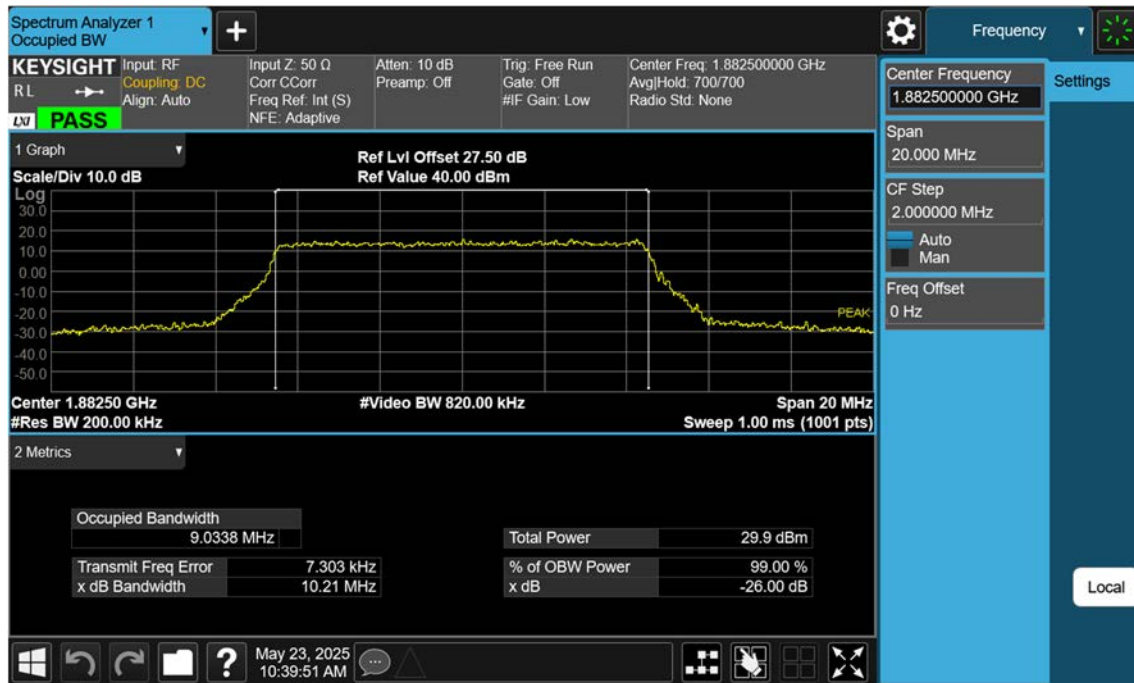
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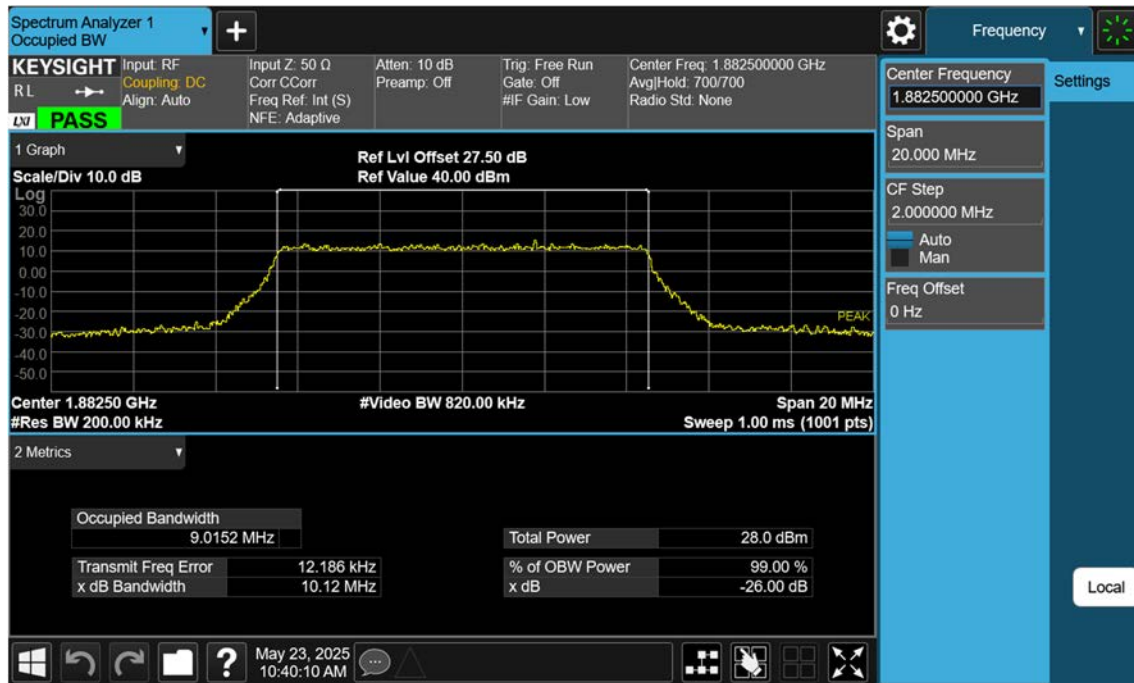
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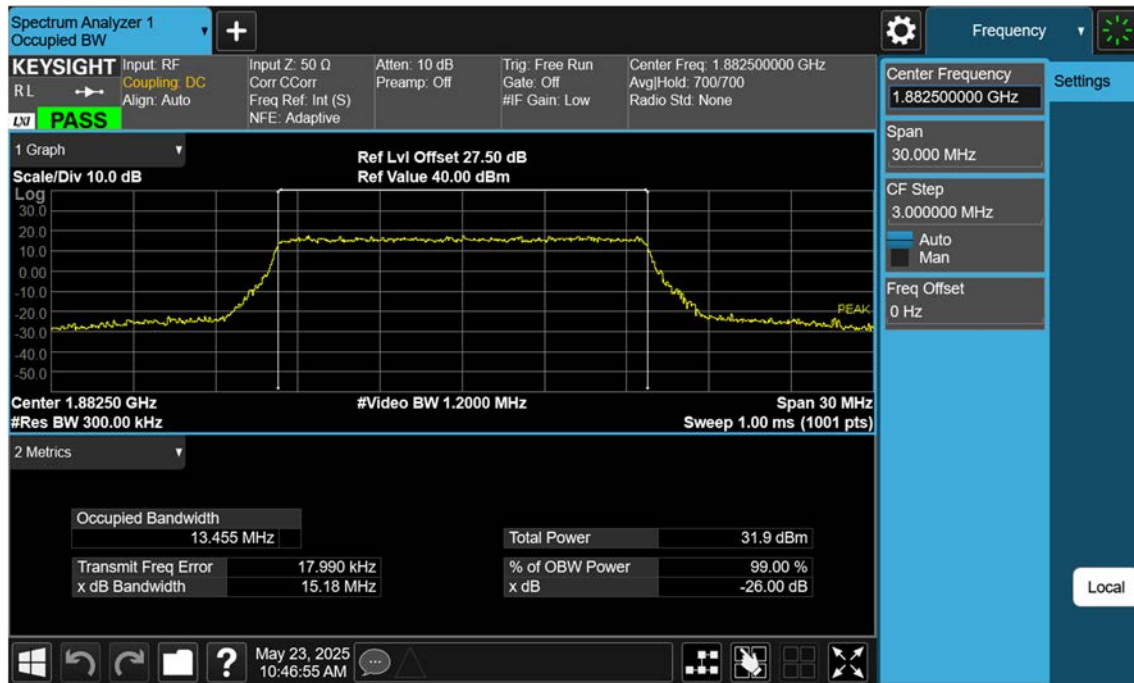
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LTE B25_10 M_OBW_Mid_256QAM_FullRB



LTE B25_15 M_OBW_Mid_QPSK_FullRB



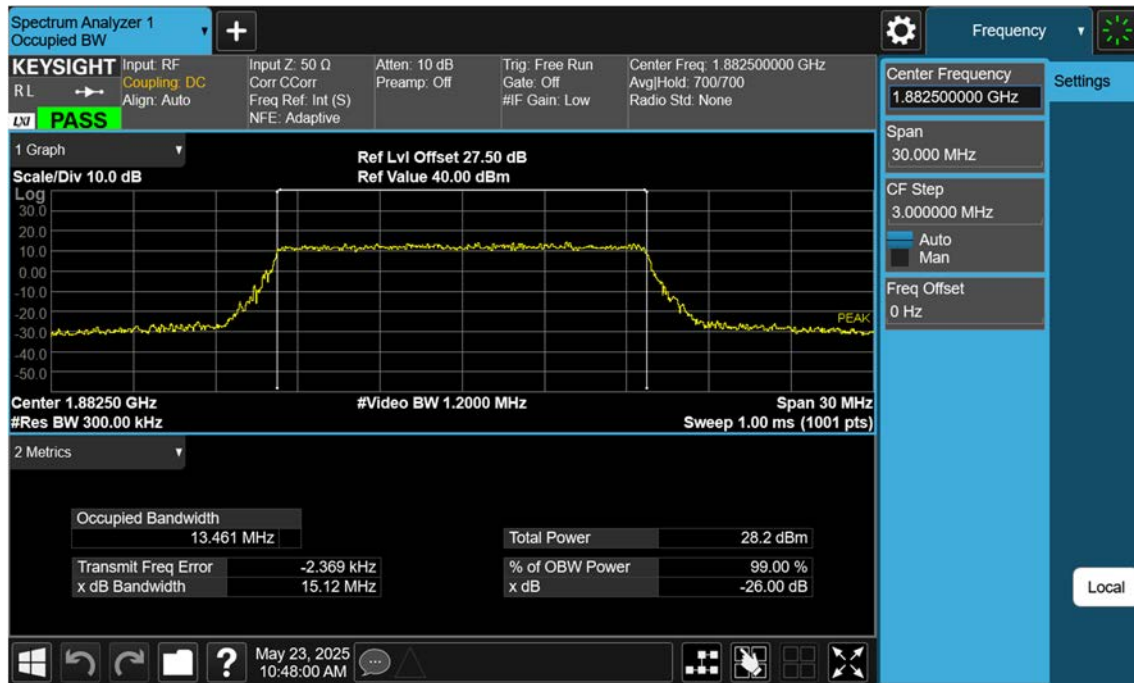
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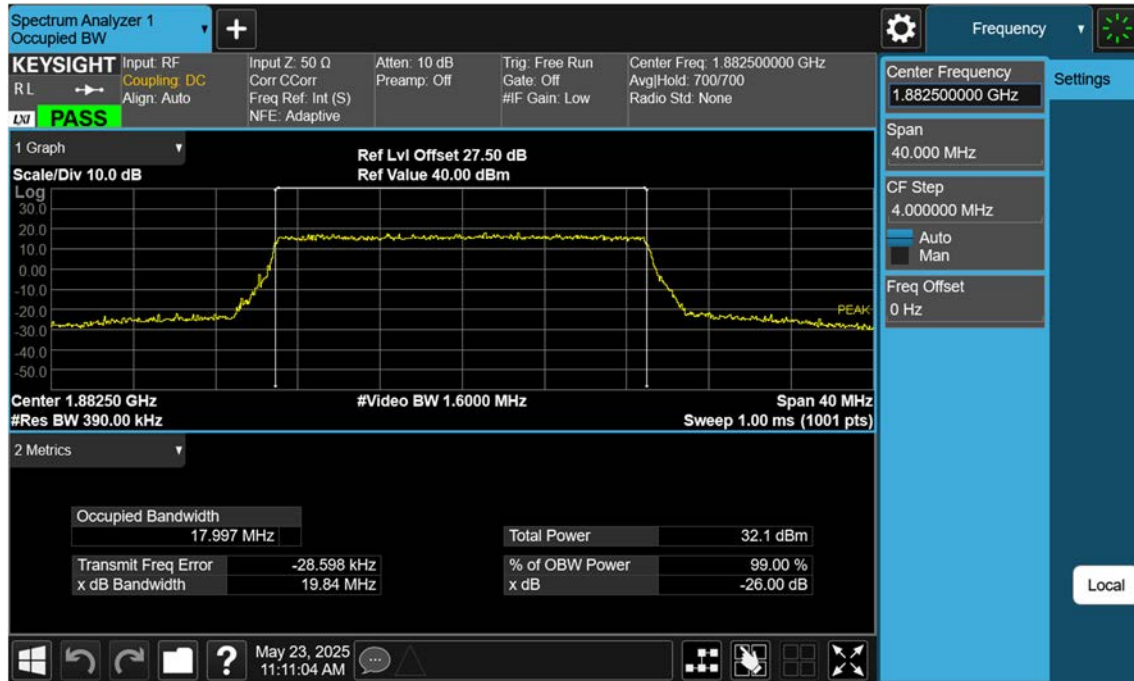
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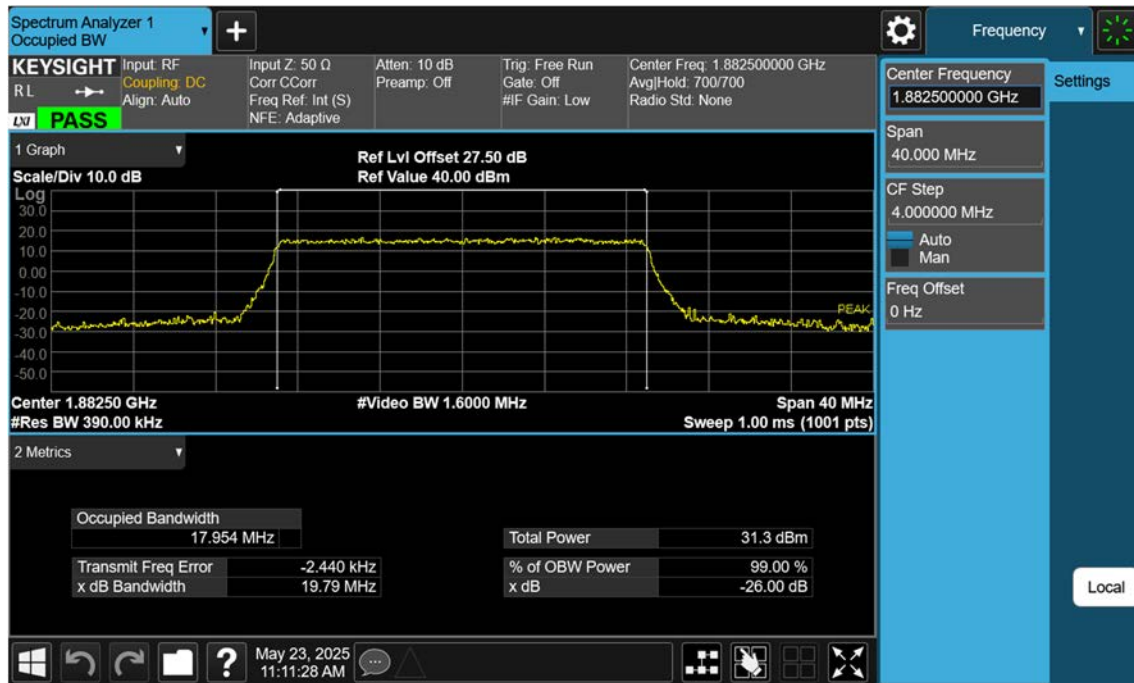
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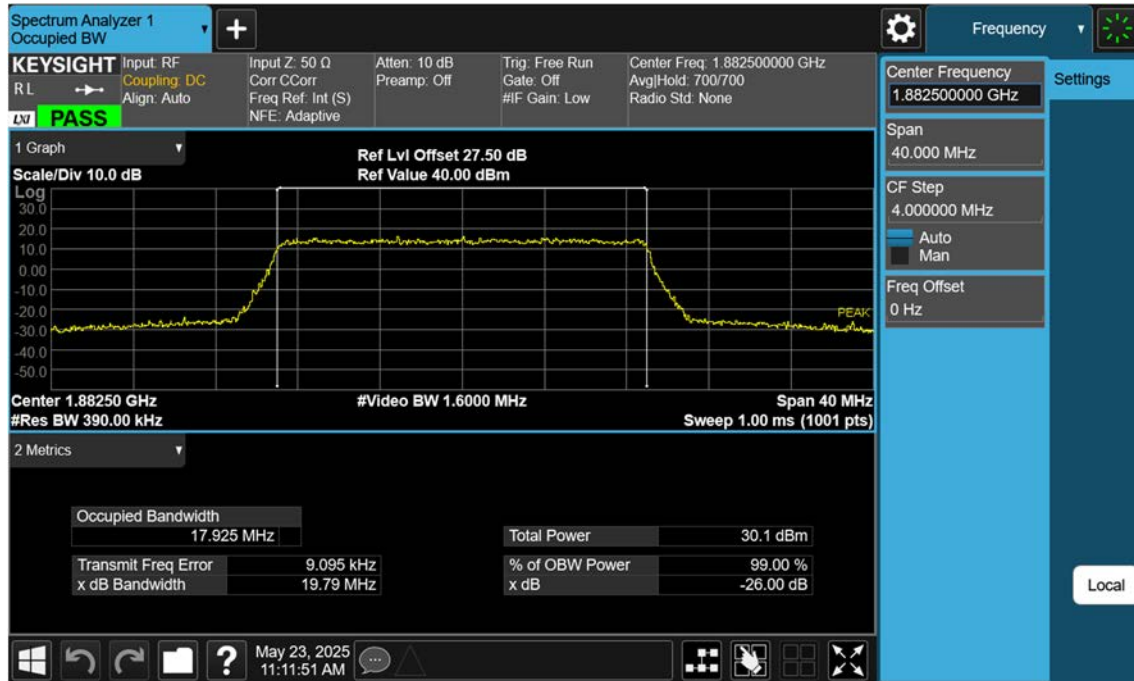
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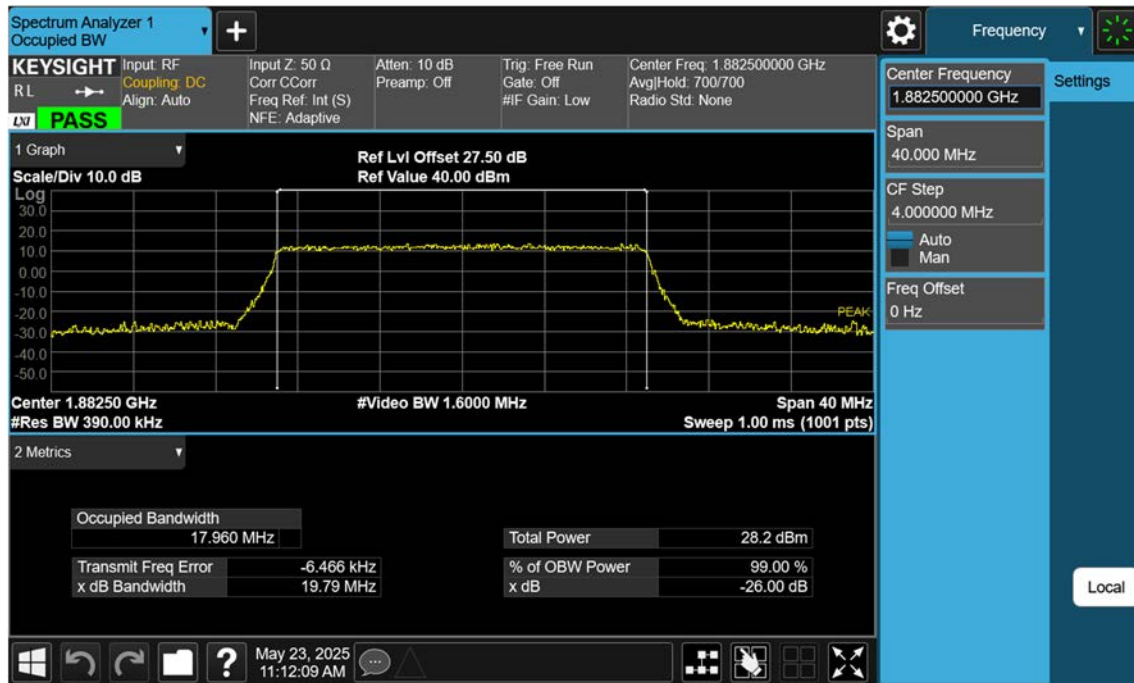
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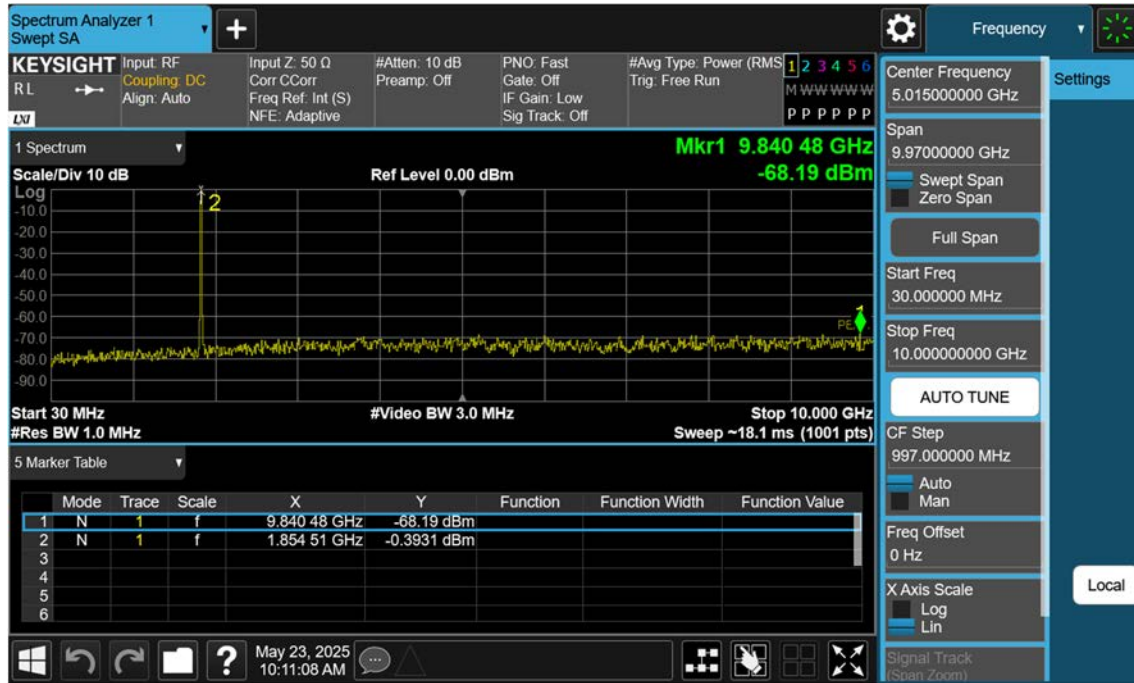
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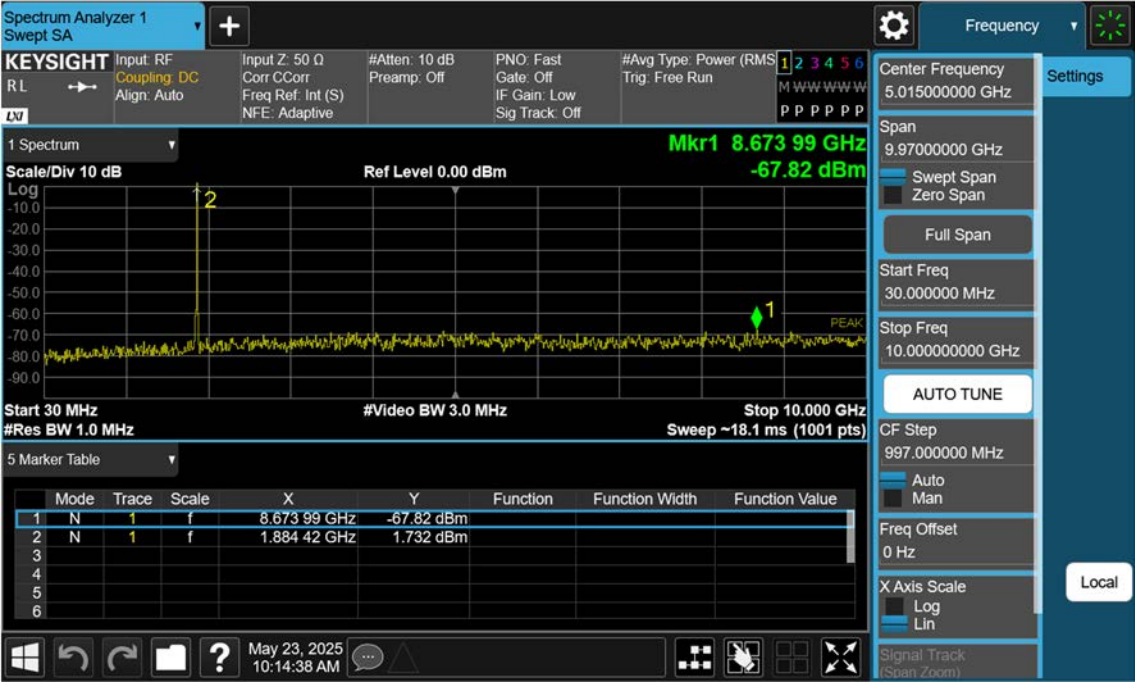
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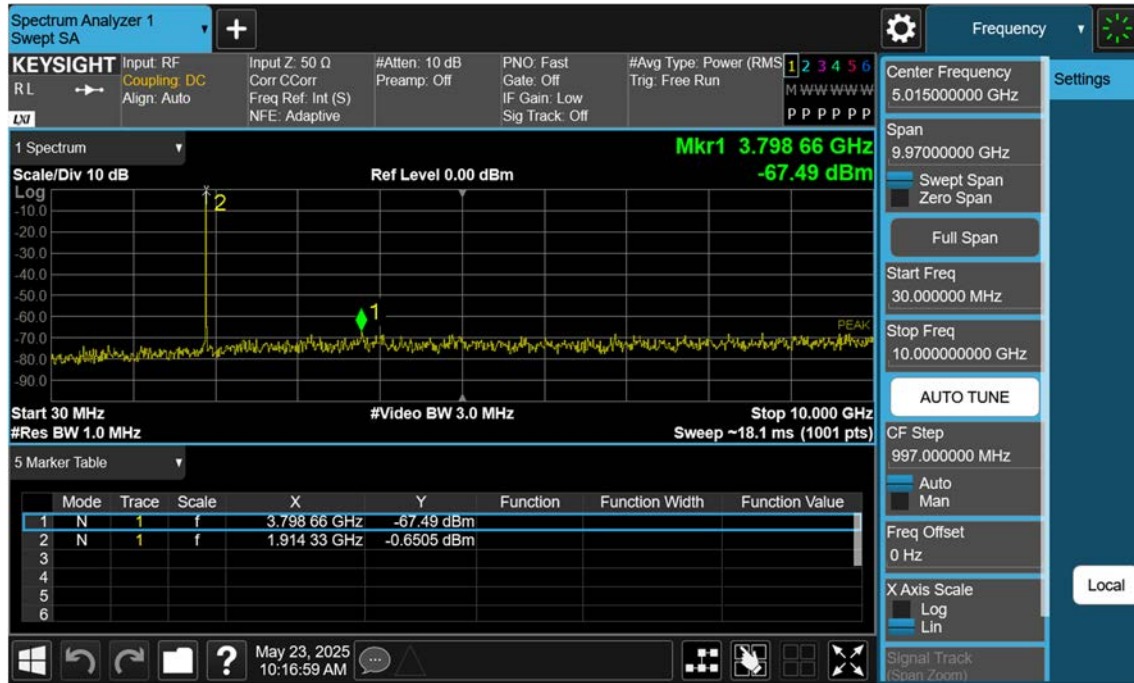
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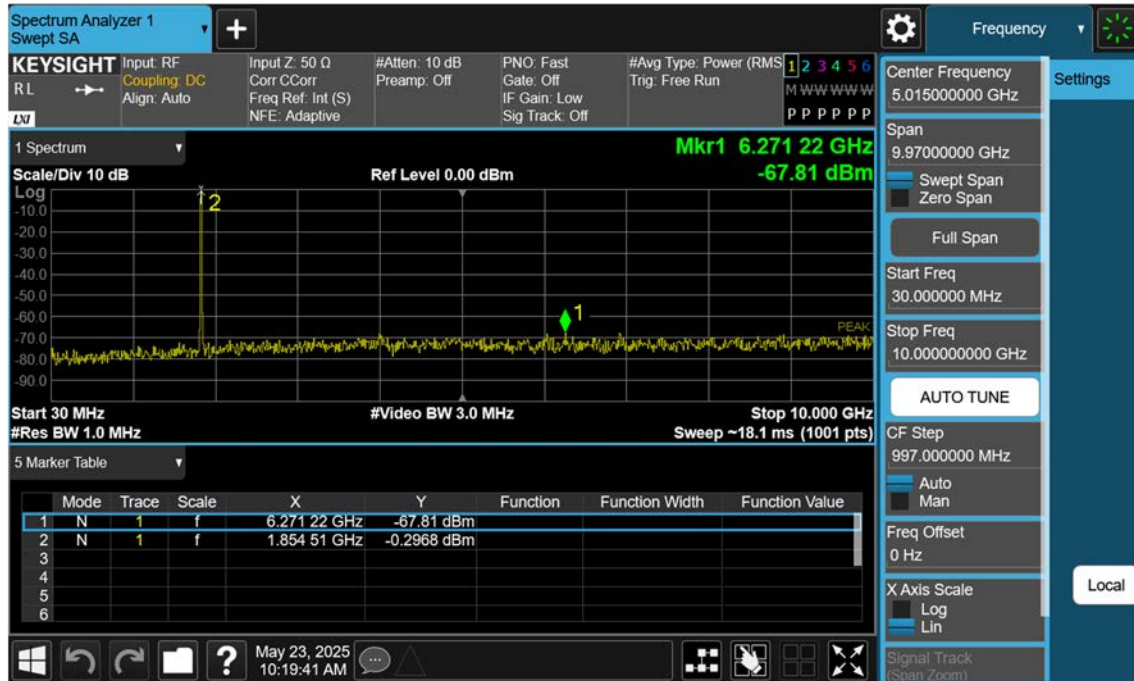
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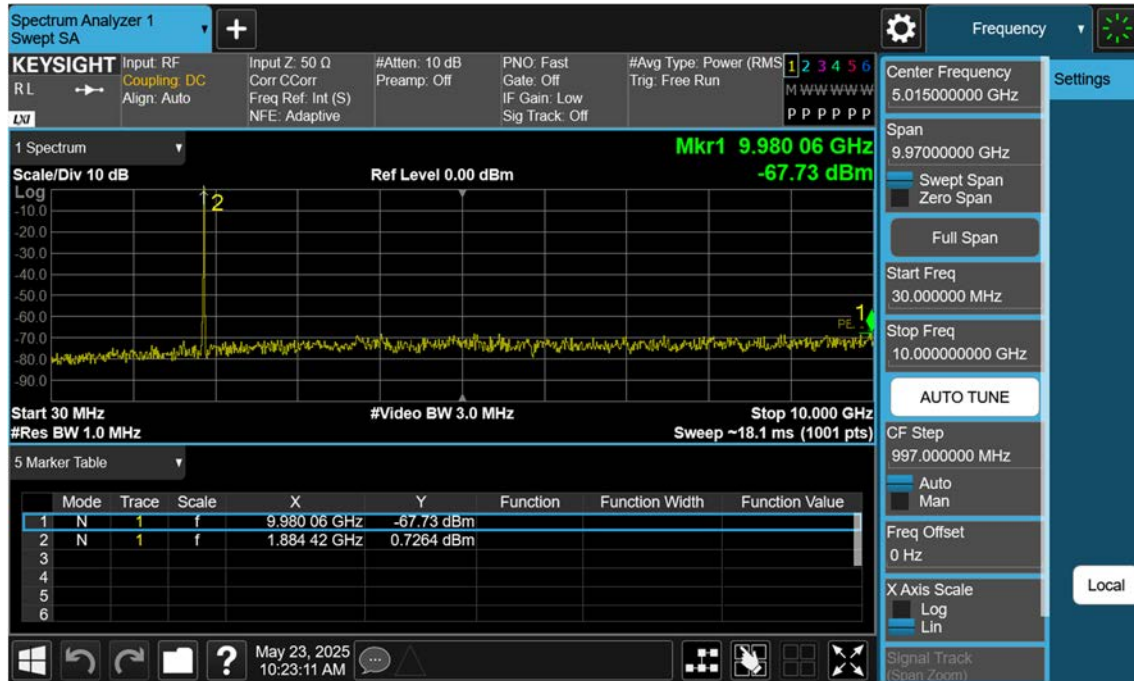
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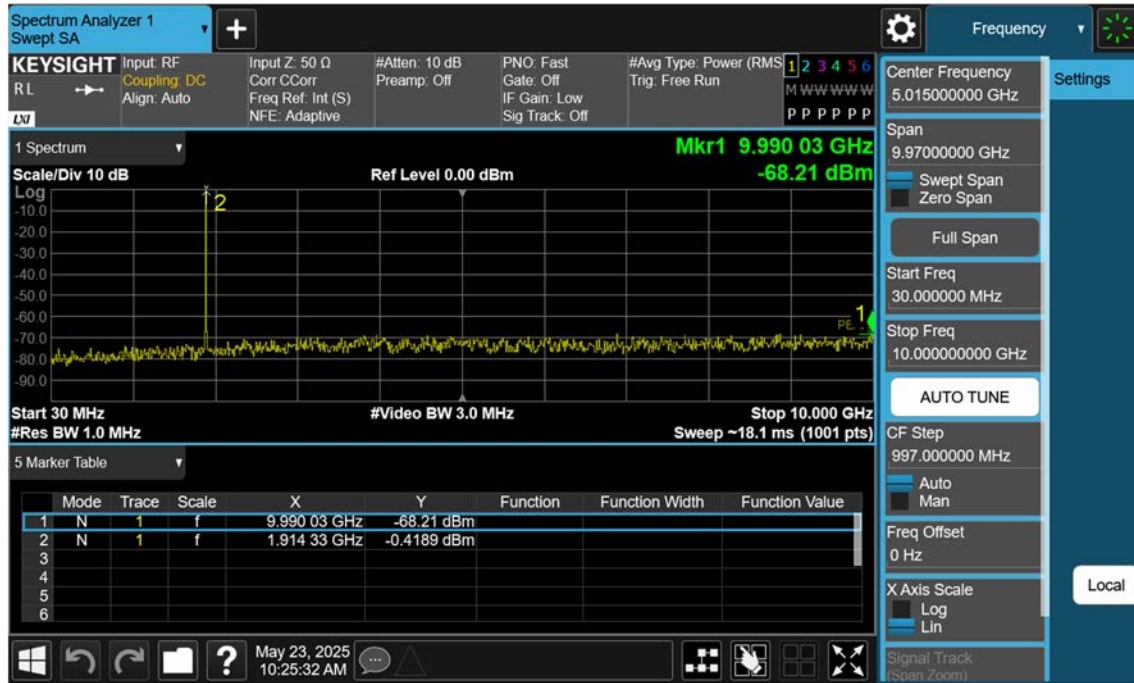
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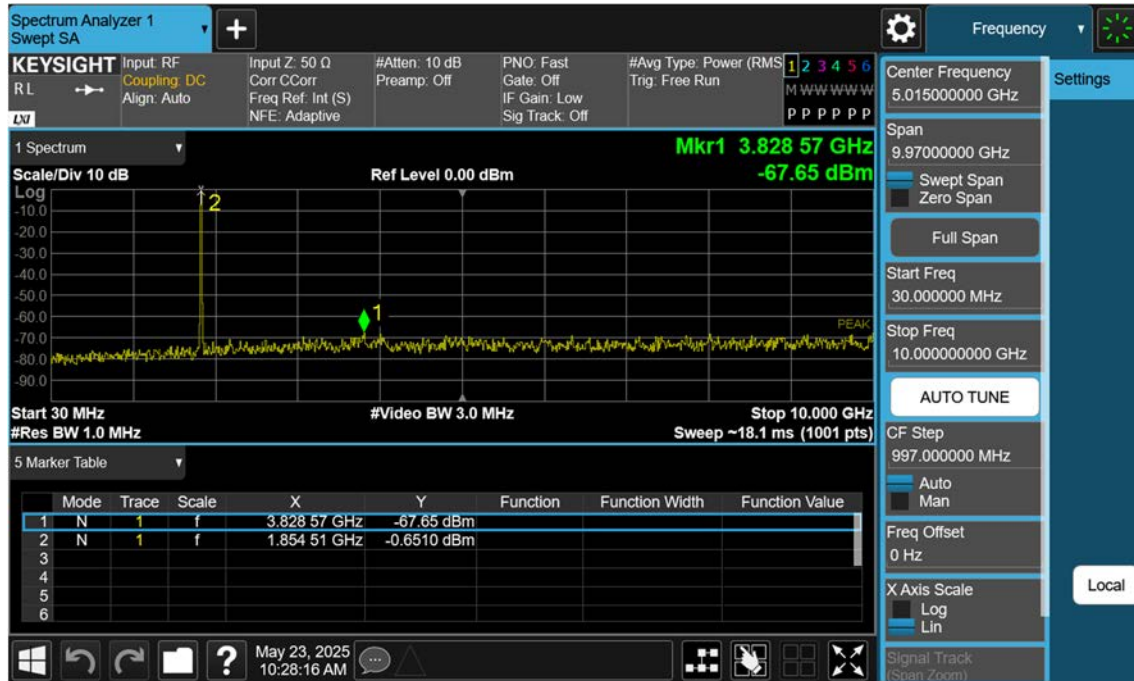
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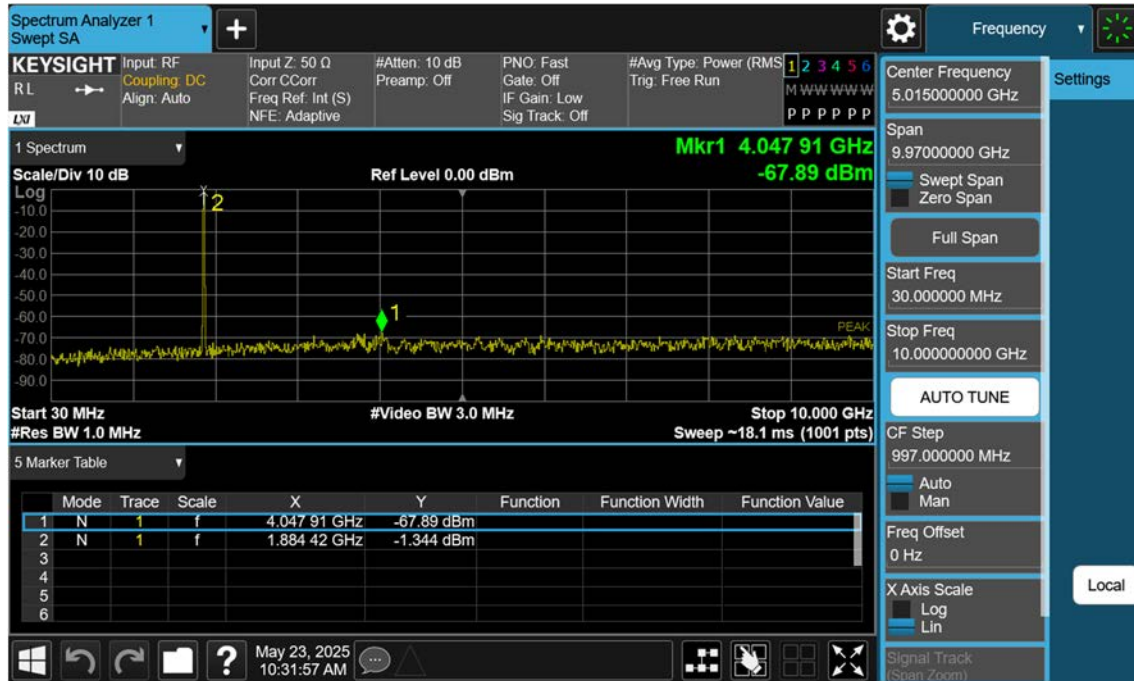
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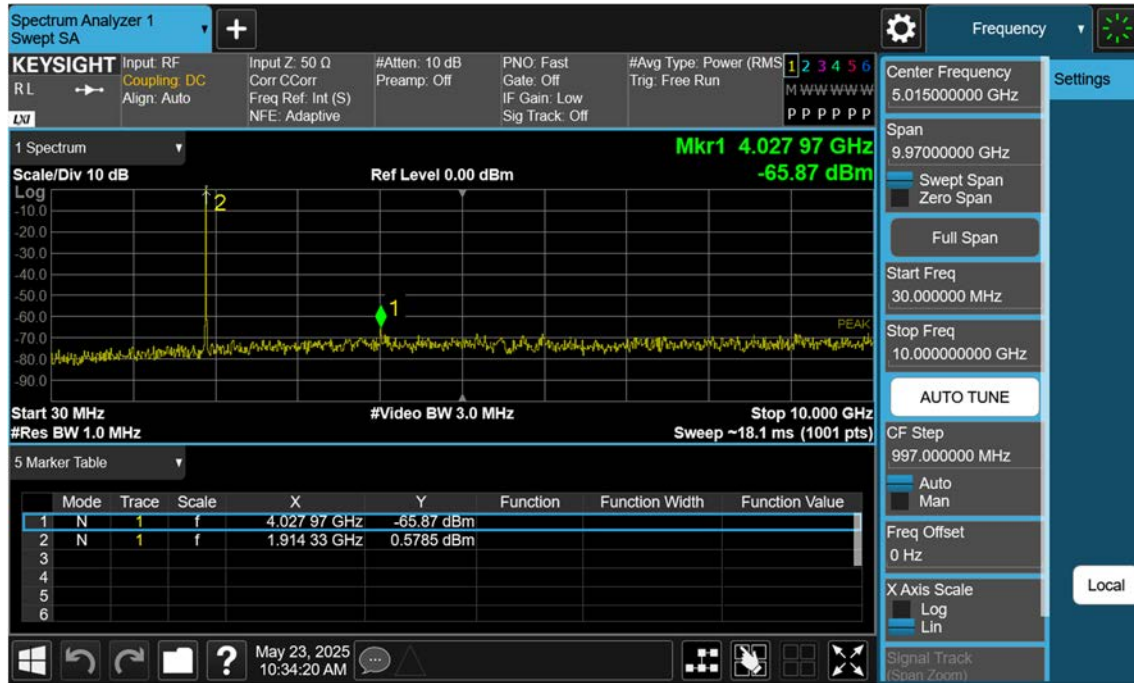
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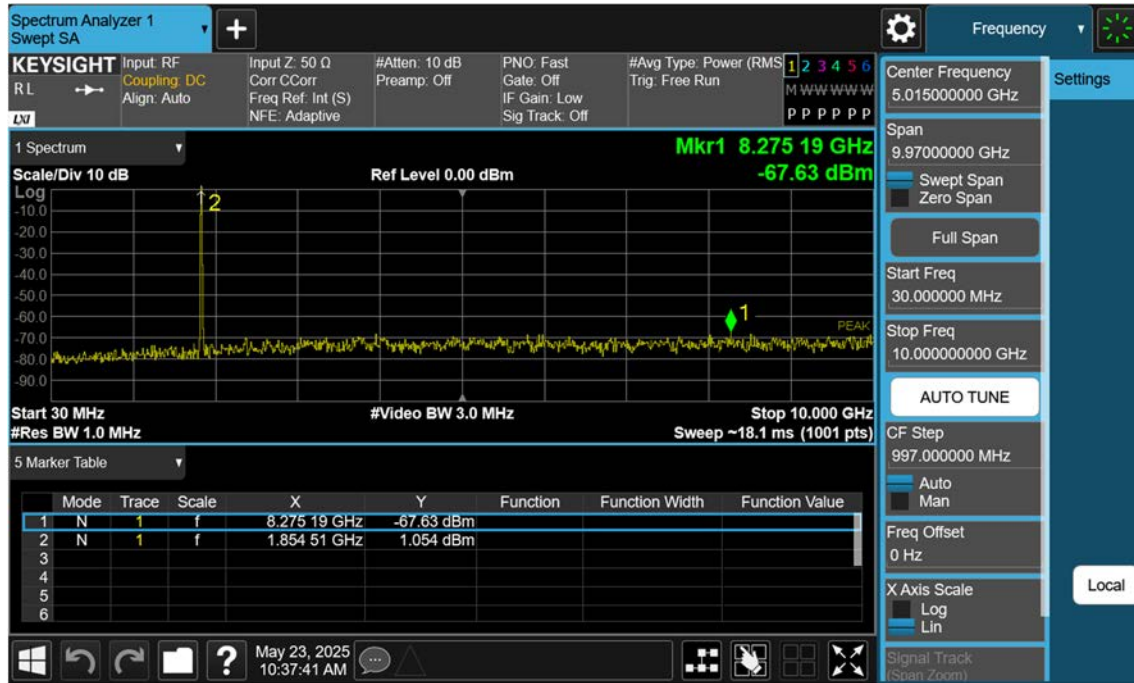
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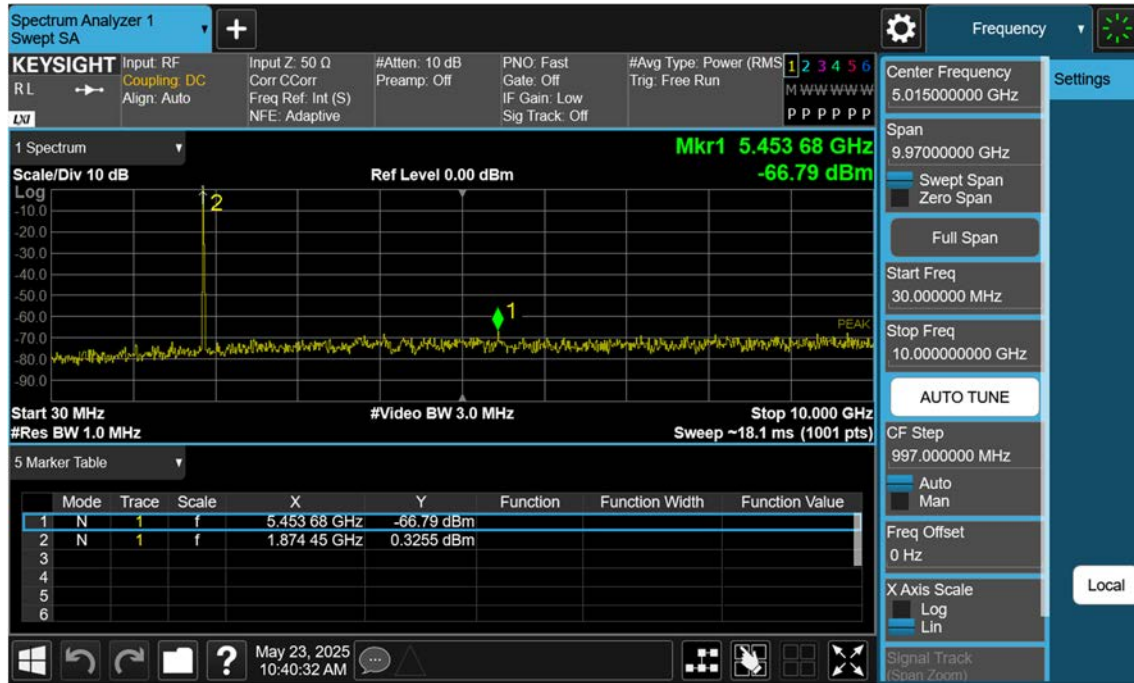
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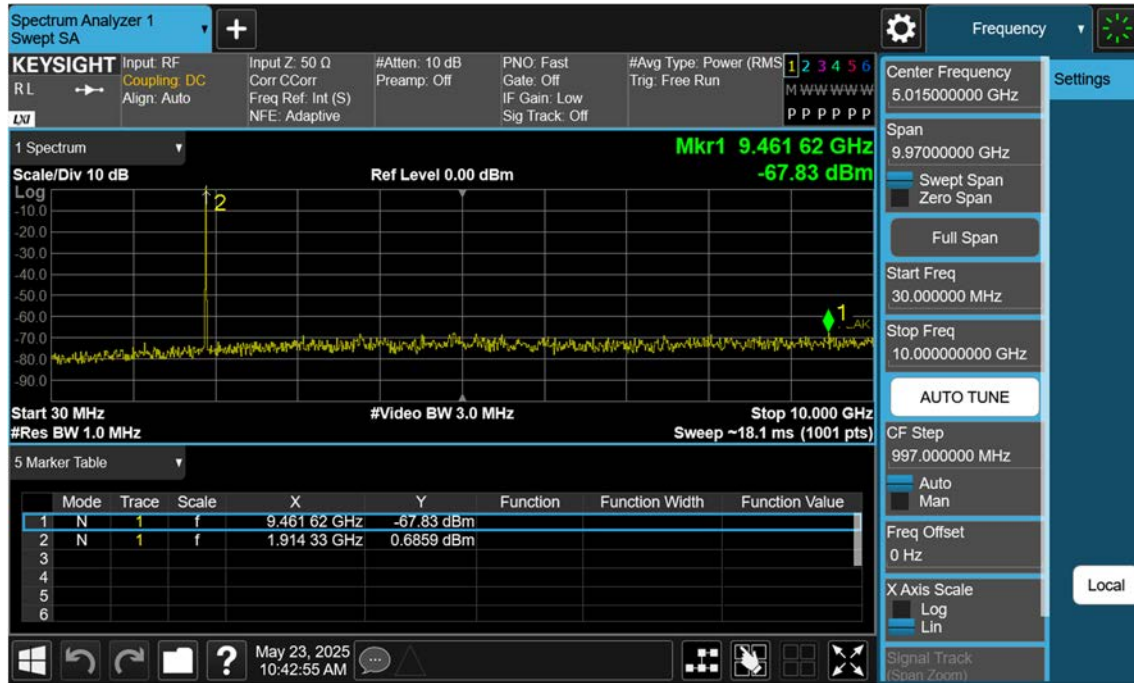
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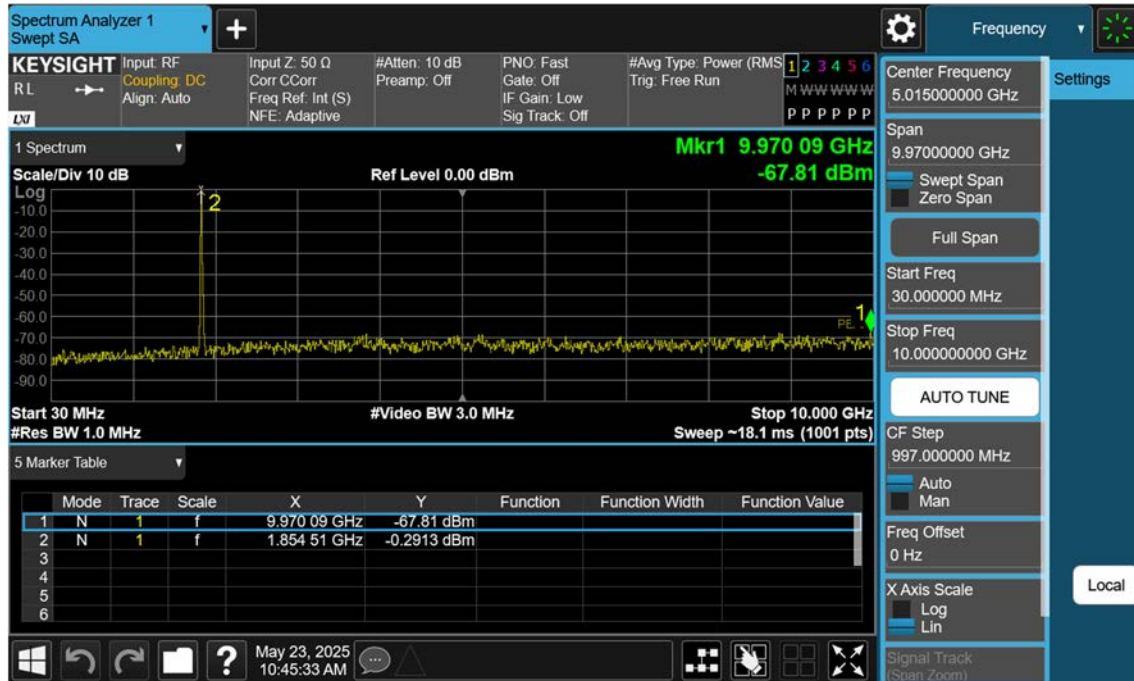
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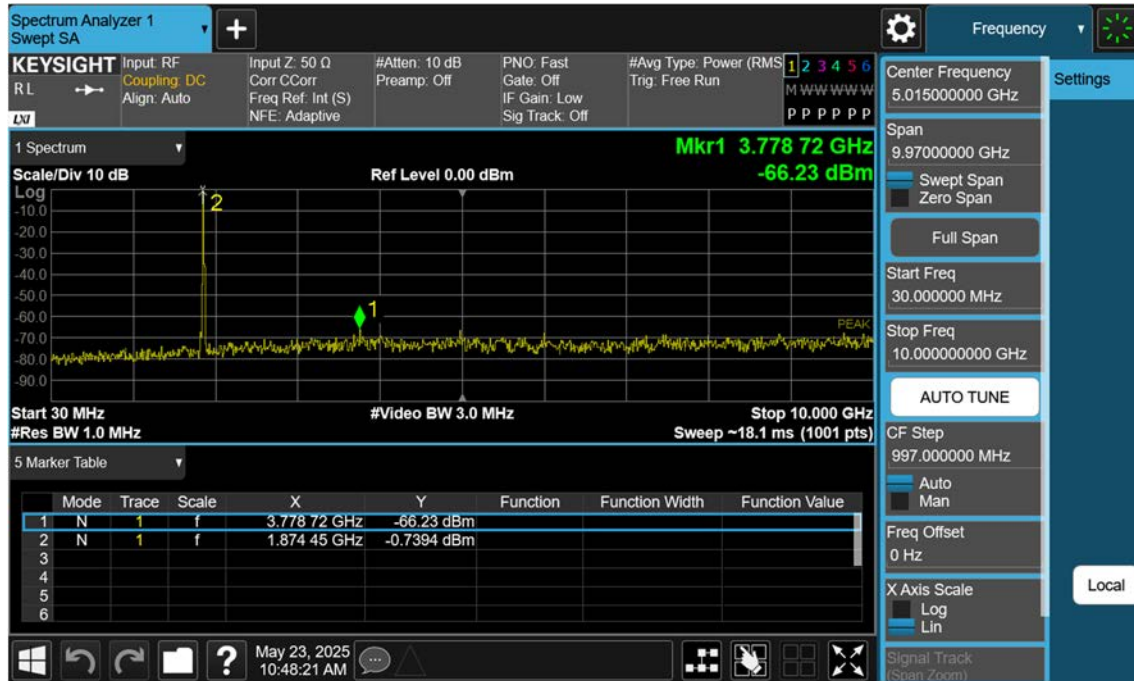
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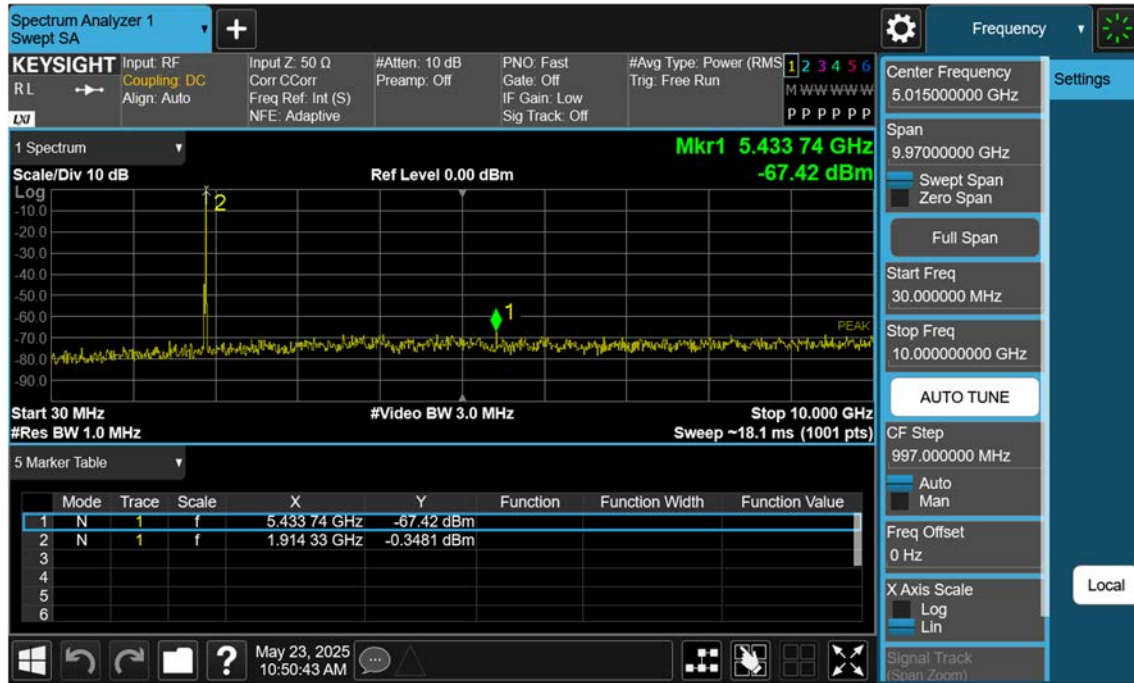
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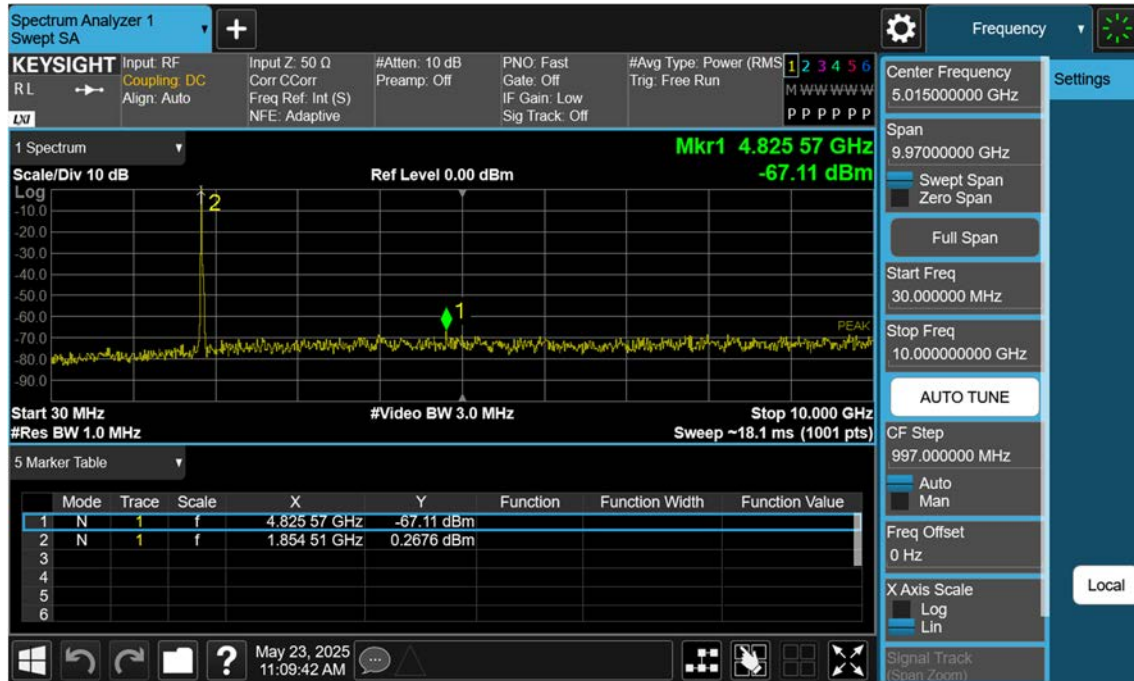
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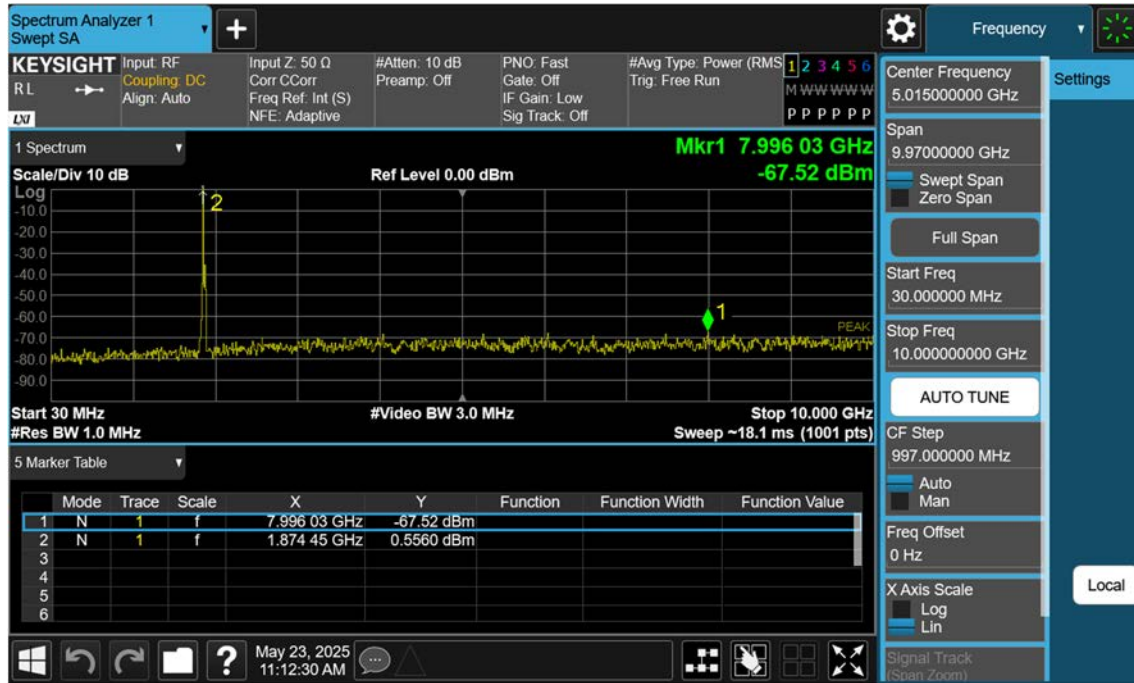
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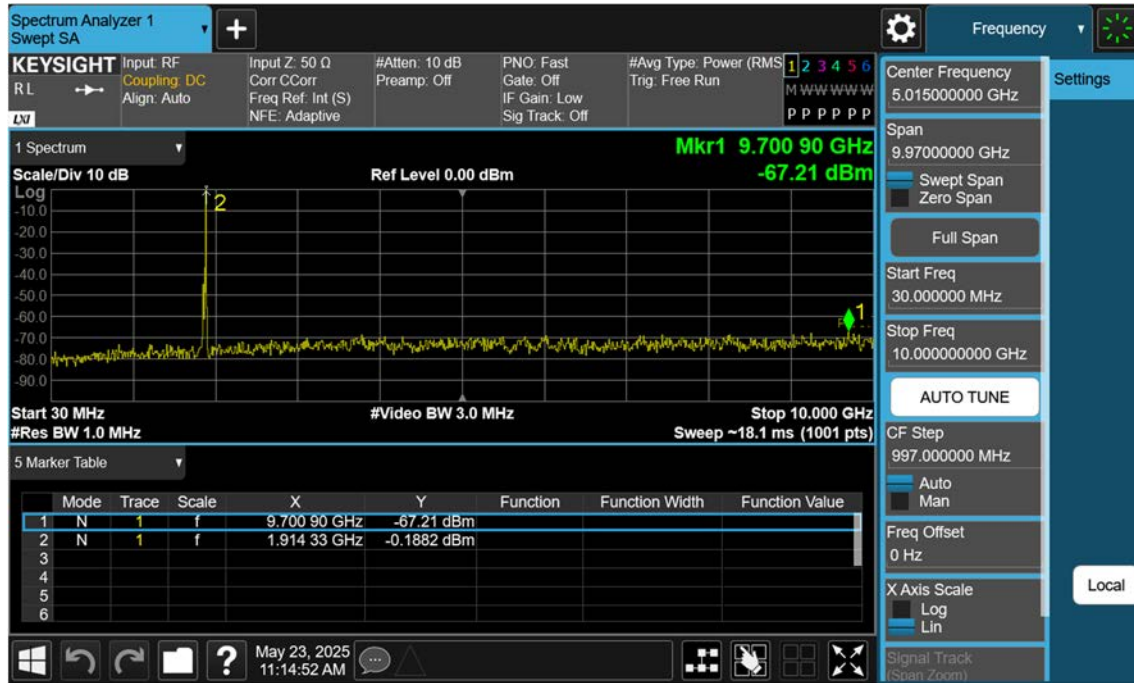
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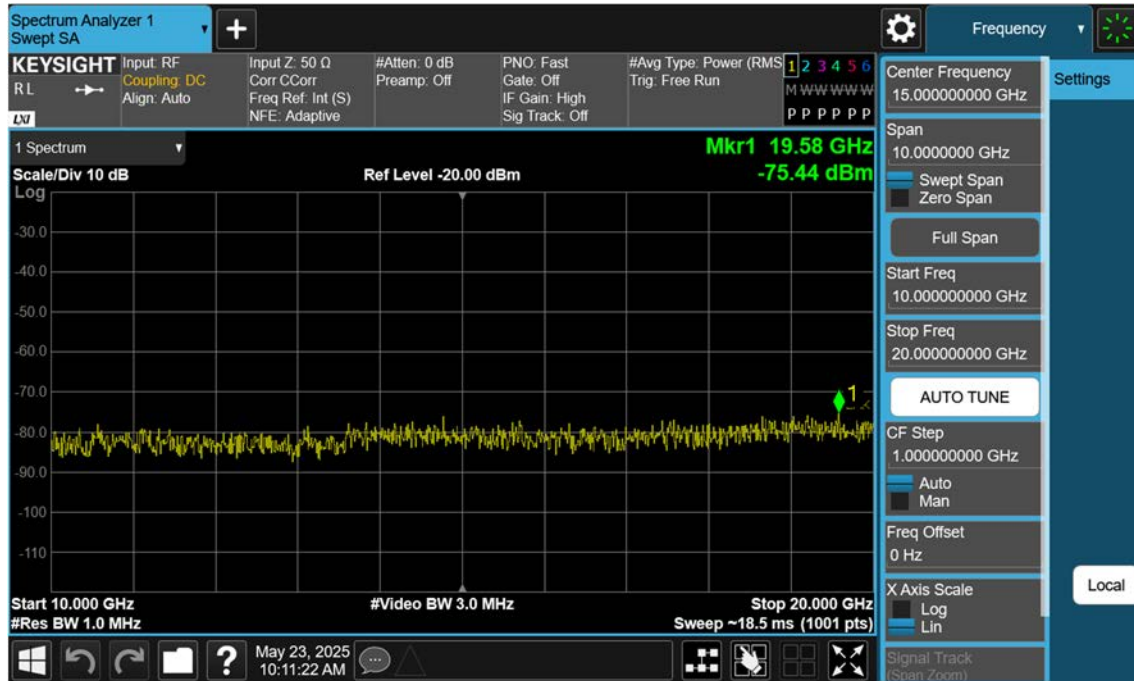
LTE B25_20 M_Conducted Spurious(30 M-10 G)_Mid_QPSK_1RB



LTE B25_20 M_Conducted Spurious(30 M-10 G)_High_QPSK_1RB



LTE B25_1.4M_Conducted Spurious(Above10 G)_Low_QPSK_1RB



LTE B25_1.4M_Conducted Spurious(Above10 G)_Mid_QPSK_1RB

